2020

Panasonic INDUSTRY

Fixed Resistors

Products Catalog



Guidelines and precautions regarding the technical information and use of our products described in this online catalog.

- If you want to use our products described in this online catalog for applications requiring special qualities or reliability, or for applications where the failure or malfunction of the products may directly jeopardize human life or potentially cause personal injury (e.g. aircraft and aerospace equipment, traffic and transportation equipment, combustion equipment, medical equipment, accident prevention, anti-crime equipment, and/or safety equipment), it is necessary to verify whether the specifications of our products fit to such applications. Please ensure that you will ask and check with our inquiry desk as to whether the specifications of our products fit to such applications use before you use our products.
- The quality and performance of our products as described in this online catalog only apply to our products when used in isolation. Therefore, please ensure you evaluate and verify our products under the specific circumstances in which our products are assembled in your own products and in which our products will actually be used.
- If you use our products in equipment that requires a high degree of reliability, regardless of the application, it is recommended that you set up protection circuits and redundancy circuits in order to ensure safety of your equipment.
- The products and product specifications described in this online catalog are subject to change for improvement without prior notice. Therefore, please be sure to request and confirm the latest product specifications which explain the specifications of our products in detail, before you finalize the design of your applications, purchase, or use our products.
- The technical information in this online catalog provides examples of our products' typical operations and application circuits. We do not guarantee the non-infringement of third party's intellectual property rights and we do not grant any license, right, or interest in our intellectual property.
- If any of our products, product specifications and/or technical information in this online catalog is to be exported or provided to non-residents, the laws and regulations of the exporting country, especially with regard to security and export control, shall be observed.

<Regarding the Certificate of Compliance with the EU RoHS Directive/REACH Regulations>

- The switchover date for compliance with the RoHS Directive/REACH Regulations varies depending on the part number or series of our products.
- When you use the inventory of our products for which it is unclear whether those products are compliant with the RoHS Directive/REACH Regulation, please select "Sales Inquiry" in the website inquiry form and contact us.

We do not take any responsibility for the use of our products outside the scope of the specifications, descriptions, guidelines and precautions described in this online catalog.



Fixed Resistors (Surface Mount Resistors) CONTENTS

Classification	Product Item	Part No.	Page	
Safety Precauti	ions (Common precautions for Fixed Resistors / Common precaut	ions for Surface Mount Resistors)	1	
C	Thick Film Chip Resistors	ERJ XG, 1G, 2G, 3G, 6G, 8G, 14, 12, 12Z, 1T	4	
General Purpose Chip Resistors	Precision Thick Film Chip Resistors	ERJ XG, 1G, 1R, 2R, 3R, 6R, 3E, 6E, 8E, ERJ 14, 12, 1T		
	Thin Film Chip Resistors, High Stability and Reliability Type	ERA 2V, 3V, 3K, 6V, 6K	11	
High Precision	Metal Film (Thin Film) Chip Resistors, High Reliability Type	ERA 1A, 2A, 3A, 6A, 8A		
	High Precision Thick Film Chip Resistors	ERJ PB3, PB6	17	
	Thick Film Chip Resistors / Low Resistance Type	ERJ 2LW, 3LW, 6LW, ERJ 2BW,3BW,6BW,8BW,6CW,8CW ERJ 2B, 3B, 6D, 6B, 8B, 14B, 3R, 6R, 8R, 14R, ERJ 12R, 12Z, ERJ 1TR, LO3, LO6, LO8, L14, L12, L1D, L1W		
	Current Sensing Resistors, Metal Plate Type	ERJ MS4S, MS4H, MB1S	25	
Current Sensing	Current Sensing Resistors, Metal Plate Type	ERJ MS6S NRFND	29	
carrent serioling	Current Sensing Resistors, Metal Plate Type	ERJ MP2, MP3, MP4 NRFND	33	
	Current Sensing Resistors, Metal Plate Type	ERJ M1W NRFND	37	
	High Power Chip Resistors / Wide Terminal Type	ERJ A1, B1, B2, B3	39	
	Low TCR High Power Chip Resistors / Wide Terminal Type	ERJ D1, D2	43	
	Current Sensing Resistors, Metal Foil Type	ERJ MFBA NRFND	46	
Small&High	Anti-Surge Thick Film Chip Resistors	ERJ PA2, P03, PA3, P06, P08, P14	48	
Power	Anti-Pulse Thick Film Chip Resistors	ERJ T06, T08, T14		
	Anti-Sulfurated Thick Film Chip Resistors	ERJ S02, S03, S06, S08, S14, S12, S1D, S1T, ERJ U0X, U01, U02, U03, U06, U08, U14, U12, ERJ U1D, ERJ U1T, ERJ U6S, U6Q		
Anti-Sulfurated	Anti-Sulfurated Thick Film Chip Resistors / Precision Type	ERJ U2R, U3R, U6R	59	
	Anti-Sulfurated Thick Film Chip Resistors / Anti-Surge Type	ERJ UP3, UP6, UP8	61	
	Anti-Sulfurated Thick Film Chip Resistors / Wide Terminal Type	ERJ C1	64	
High Temperature	High Temperature Thick Film Chip Resistor	ERJ H2G, H2C, H2R, H3G, H3E, H3Q, H6G, HP6	67	
	Chip Resistor Array	EXB 14V, 18V, 24V, 28V, N8V, 2HV, 34V, V4V, 38V, V8V, S8V	70	
Resistor	Anti-Sulfurated Chip Resistor Array	EXB U14, U18, U24, U28, U2H, U34, U38	74	
Network/Array	Chip Resistor Networks	EXB D, E, A, Q	77	
	Chip Attenuator	EXB 14AT, 24AT	81	
	Packaging Methods (Taping)		83	
Common	Recommended Land Pattern		88	
specifications	Recommended Soldering Conditions		91	
	Standard for Resistance Value and Resistance Tolerance		92	





Safety Precautions (Common precautions for Fixed Resistors)

- When using our products, no matter what sort of equipment they might be used for, be sure to make a written agreement on the specifications with us in advance. The design and specifications in this catalog are subject to change without prior notice.
- Do not use the products beyond the specifications described in this catalog.
- This catalog explains the quality and performance of the products as individual components. Before use, check and evaluate their operations when installed in your products under the actual conditions for use.
- Install the following systems for a failsafe design to ensure safety if these products are to be used in equipment where a defect in these products may cause the loss of human life or other significant damage, such as damage to vehicles (automobile, train, vessel), traffic lights, medical equipment, aerospace equipment, electric heating appliances, combustion/gas equipment, rotating equipment, and disaster/crime prevention
- * Systems equipped with a protection circuit and a protection device.
- * Systems equipped with a redundant circuit or other system to prevent an unsafe status in the event of a single
- * Systems equipped with an arresting the spread of fire or preventing glitch.

(1) Precautions for use

- These products are designed and manufactured for general and standard use in general elec tron ic equipment. (e.g. AV equipment, home electric appliances, office equipment, information and communication equipment) For applications in which special quality and reliability are required, or if the failure or malfunction of the products may directly jeopardize life or cause threat of personal injury (such as for aircraft and aerospace equipment, traffic and transport equipment, combustion equipment, medical equipment, accident prevention and anti-theft devices, and safety equipment), please be sure to consult with our sales representative in advance and to exchange product specifications which conform to such applications.
- These products are not intended for use in the following special conditions. Before using the products, carefully check the effects on their quality and performance, and determine whether or not they can be used.
 - 1. In liquid, such as water, oil, chemicals, or organic solvent.
 - 2. In direct sunlight, outdoors, or in dust.
 - 3. In salty air or air with a high concentration of corrosive gas, such as Cl₂, H₂S, NH₃, SO₂, or NO_X.
 - 4. Electric Static Discharge (ESD) Environment.
 - These components are sensitive to static electricity and can be damaged under static shock (ESD). Please take measures to avoid any of these environments.
 - Smaller components are more sensitive to ESD environment.
 - 5. Electromagnetic and Radioactive Environment.
 - Avoid any environment where strong electromagnetic waves and radiation exist.
 - 6. In an environment where these products cause dew condensation.
 - 7. Sealing or coating of these products or a printed circuit board on which these products are mounted, with resin or other materials.
- These products generate Joule heat when energized. Carefully position these products so that their heat will not affect the other components.
- · Carefully position these products so that their temperatures will not exceed the category temperature range due to the effects of neighboring heat-generating components. Do not mount or place heat-generating components or inflammables, such as vinyl-coated wires, near these products.
- Note that non-cleaning solder, halogen-based highly active flux, or water-soluble flux may deteriorate the performance or reliability of the products.
- Carefully select a flux cleaning agent for use after soldering. An unsuitable agent may deteriorate the performance or reliability. In particular, when using water or a water-soluble cleaning agent, be careful not to leave water residues. Otherwise, the insulation performance may be deteriorated.
- Do not apply flux to these products after soldering. The activity of flux may be a cause of failures in these products.
- Refer to the recommended soldering conditions and set the soldering condition. High peak temperature or long heating time may impair the performance or the reliability of these products.
- Recommended soldering condition is for the guideline for ensuring the basic characteristics of the products, not for the stable soldering conditions. Conditions for proper soldering should be set up according to individual conditions.



- Do not reuse any products after removal from mounting boards.
- Do not drop these products. If these products are dropped, do not use them. Such products may have received mechanical or electrical damage.
- If any doubt or concern to the safety on these products arise, make sure to inform us immediately and conduct technical examinations at your side.

(2) Precautions for storage

The performance of these products, including the solderability, is guaranteed for a year from the date of arrival at your company, provided that they remain packed as they were when delivered and stored at a temperature of 5 °C to 35 °C and a relative humidity of 45 % to 85 %.

Even within the above guarantee periods, do not store these products in the following conditions. Otherwise, their electrical performance and/or solderability may be deteriorated, and the packaging materials (e.g. taping materials) may be deformed or deteriorated, resulting in mounting failures.

- 1. In salty air or in air with a high concentration of corrosive gas, such as Cl₂, H₂S, NH₃, SO₂, or NO_X.
- 2. In direct sunlight.

(3) AEC-Q200 Compliant

The products are tested based on all or part of the test conditions and methods defined in AEC-Q200. Please consult with Panasonic for the details of the product specification and specific evaluation test results, etc., and please review and approve Panasonic's product specification before ordering.

<Package markings>

Package markings include the product number, quantity, and country of origin.

In principle, the country of origin should be indicated in English.





Safety Precautions (Common precautions for Surface Mount Resistors)

The following are precautions for individual products. Please also refer to the common precautions for Fixed Resistors in this catalog.

- Take measures against mechanical stress during and after mounting of Surface Mount Resistors (hereafter called the resistors) so as not to damage their electrodes and protective coatings. Be careful not to misplace the resistors on the land patterns. Otherwise, solder bridging may occur.
- Keep the rated power and ambient temperature within the specified derating curve. Some circuit boards, wiring patterns, temperatures of heat generated by adjacent components, or ambient temper a tures can become factors in the rise of the temperature of the resistors, regardless of the level of power applied. Therefore, check the conditions before use and op timize them so as not to damage the boards and peripheral components.
 - Make sure to contact us before using the resistors under special conditions.
- If a transient load (heavy load in a short time) like a pulse is expected to be applied, check and evaluate the operations of the resistors when installed in your products before use. Never exceed the rated power. Otherwise, the performance and/or reliability of the resistors may be impaired.
- Transient voltage If there is a possibility that the transient phenomenon (significantly high voltage applied in a short time) may occur or that a high voltage pulse may be applied, make sure to evaluate and check the characteristics of resistors mounted on your product rather than only depending on the calculated power limit or steady-state conditions.
- If the resistors are to be used in high frequency circuits, carefully check the operation before use. Such circuits change the electrical characteristics of the resistors.
- Before using halogen-based or other high-activity flux, check the possible effects of the flux residues on the 6. performance and reliability of the resistors.
- 7. When soldering with a soldering iron, never touch the resistors'bodies with the tip of the soldering iron. When using a soldering iron with a high temperature tip, finish soldering as quickly as possible (within three seconds at 350 °C max.).
- Mounting of the resistors with excessive or insufficient wetting amount of solder may affect the connection reliability or the performance of the resistors. Carefully check the effects and apply a proper amount of solder for use.
- When the resistors' protective coatings are chipped, flawed, or removed, the characteristics of the resistors may be impaired. Take special care not to apply mechanical shock during automatic mounting or cause damage during handling of the boards with the resistors mounted.
- 10. Do not apply shock to the resistors or pinch them with a hard tool (e.g. pliers and tweezers). Otherwise, the resistors' protective coatings and bodies may be chipped, affecting their performance.
- 11. Avoid excessive bending of printed circuit boards in order to protect the resistors from abnormal stress.
- 12. Do not immerse the resistors in solvent for a long time. Before using solvent, carefully check the effects of immersion.
- 13. Do not apply excessive tension to the terminals.



Thick Film Chip Resistors

Thick Film Chip Resistors

Series: ERJ XG, 1G, 2G, 3G, 6G, 8G, 14, 12, 12Z, 1T

102

102

102

102

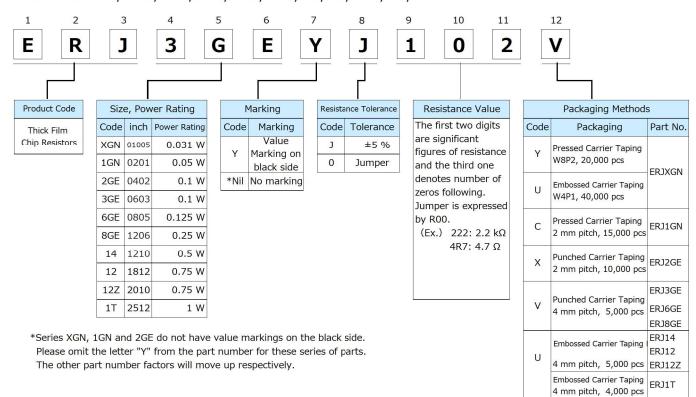
102

Features

- Small size and lightweight
- High reliability...Metal glaze thick film resistive element and three layers of electrodes
- Compatible with placement machines ··· Taping packaging available
- Suitable for both reflow and flow soldering
- Reference Standard ··· IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant (except ERJXG)
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers

• Series ERJXGN, 1GN, 2GE, 3GE, 6GE, 8GE, 14, 12, 12Z, 1T, ±5 %



Ratings

[For Resistor]

Part No. (inch size)	Power Rating at 70 °C ⁽¹⁾ (W)	Limiting Element Voltage ⁽²⁾ (V)	Maximum Overload Voltage ⁽³⁾ (V)	Resistance Tolerance (%)	Resista Rang (Ω)	ge	T.C.R. (×10 ⁻⁶ /K)	Catcgory Temperature Range (°C)	AEC- Q200 Grade
ERJXG (01005)	0.031	15	30	±5	1 to 1 M	(E24)	R<10 Ω : -100 to +600 10 Ω to 100 Ω : \pm 300 100 Ω≤R : \pm 200	-55 to +125	-
ERJ1G (0201)	0.05	25	50	±5	1 to 10 M	(E24)		-55 to +125	Grade 1
ERJ2G (0402)	0.1	50	100	±5	1 to 10 M	(E21)	R<10 Ω:	-55 to +155	Grade 0
ERJ3G (0603)	0.1	75	150	±5	1 to 10 M	(E24)	-100 to +600	-55 to +155	Grade 0
ERJ6G (0805)	0.125	150	200	±5	1 to 10 M	(E24)	10 Ω to 1 M Ω :	-55 to +155	Grade 0
ERJ8G (1206)	0.25	200	400	±5	1 to 10 M	(E24)	±200	-55 to +155	Grade 0
ERJ14 (1210)	0.5	200	400	±5	1 to 10 M	(E24)	1 MΩ <r :<="" td=""><td>-55 to +155</td><td>Grade 0</td></r>	-55 to +155	Grade 0
ERJ12 (1812)	0.75	200	500	±5	1 to 10 M	(E24)	-400 to +150	-55 to +155	Grade 0
ERJ12Z (2010)	0.75	200	500	±5	1 to 10 M	(E24)		-55 to +155	Grade 0
ERJ1T (2512)	1	200	500	±5	1 to 1 M	(E24)		-55 to +155	Grade 0

- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

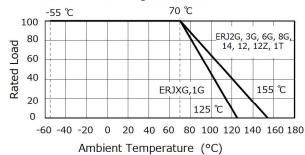
[For Jumper]

(1 of Samper)										
Part No.	Resistance(Ω)	Rated Current(A)	Maximum Overload Current (A) ⁽¹⁾							
ERJXG		0.5	1							
FR11G		0.5	1							
ERJ2G		1	2							
ERJ3G		_	2							
ERJ6G	50 mO or less		_							
ERJ8G	30 ms 01 less									
ERJ14		2	4							
ERJ12		2	7							
ERJ12Z										
ERJ1T										

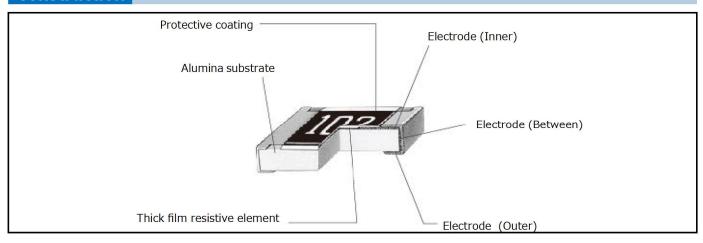
(1) Overload test current

Power Derating Curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure below.

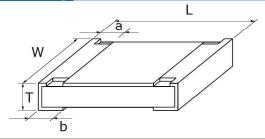


Construction





Dimensions in mm (not to scale)



Part No.	Dimensions (mm)									
Part No.	L	W	a	b	Т	(g/1000 pcs)				
ERJXG	0.40±0.02	0.20±0.02	0.10±0.03	0.10±0.03	0.13±0.02	0.04				
ERJ1G	0.60±0.03	0.30±0.03	0.10±0.05	0.15±0.05	0.23±0.03	0.15				
ERJ2G	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	0.8				
ERJ3G	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2				
ERJ6G	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4				
ERJ8G	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10				
ERJ14	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16				
ERJ12	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27				
ERJ12Z	5.00±0.20	2.50±0.20	0.60±0.20	0.60±0.20	0.60±0.10	27				
ERJ1T	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45				

Performance

Test Item	Performance Re	equirements ⊿R	Test Conditions		
rest Item	Resistor type	Jumper type	rest conditions		
Resistance	Within Specified Tolerance	50 mΩ or less	20 °C		
T. C. R.	Within Specified T. C. R.	$50 \text{ m}\Omega$ or less	+25 °C/+155 °C (ERJXG,1G : +25 °C/+125 °C)		
Overload	±2 %	50 m Ω or less	Rated Voltage× 2.5, 5 s Jumper type: Max. Overload Current, 5 s		
Resistance to Soldering Heat	±1 %	50 mΩ or less	270 °C, 10 s		
Rapid Change of Temperature	±1 %	50 m Ω or less	-55 °C (30 min.) / +155 °C (ERJXG,1G: +125 °C) (30 min.), 100 cycles		
High Temperature Exposure	±1 %	50 mΩ or less	+155 °C (ERJXG,1G: +125 °C), 1000 h		
Damp Heat, Steady State	±1 %	$50~\text{m}\Omega~\text{or less}$	60 °C, 90 % to 95 %RH, 1000 h		
Load Life in Humidity	±3 %	50 m Ω or less	60 °C, 90 % to 95 %RH, Rated Voltage (Jumper type : Rated Current), 1.5 h ON / 0.5 h OFF cycle, 1000 h		
Endurance at 70 °C	± 3 % 50 mΩ or less		70 °C, Rated Voltage (Jumper type :Rated Current), 1.5 h ON / 0.5 h OFF cycle, 1000 h		



Precision Thick Film Chip Resistors

Precision Thick Film Chip Resistors

Series: ERJ XG, 1G

ERJ 1R, 2R, 3R, 6R

ERJ 3E, 6E, 8E, 14, 12, 1T







1001

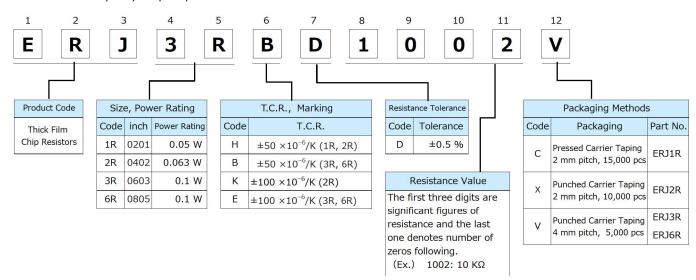
1001

Features

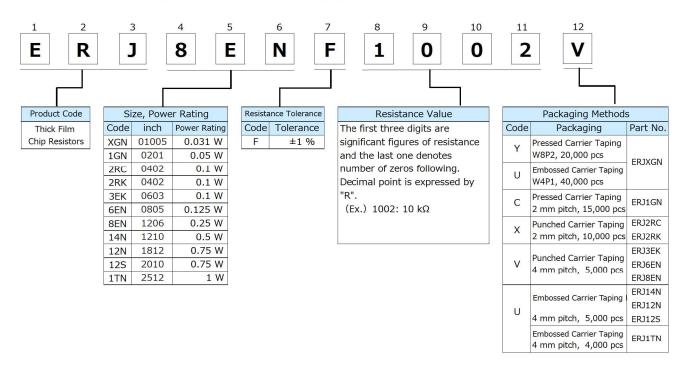
- Small size and lightweight
- High reliability...Metal glaze thick film resistive element and three layers of electrodes
- Compatible with placement machines ··· Taping packaging available
- Suitable for both reflow and flow soldering
- Low Resistance Tolerance : ERJXG, 1G, 2R, 3E, 6E, 8E, 14, 12, 1T : ±1 % ERJ1R, 2R, 3R, 6R : ±0.5 %
- Reference Standard ··· IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant (except ERJXG, ERJ1R)
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers

Series ERJ1R, 2R, 3R, 6R, ±0.5 %



• Series ERJXGN, 1GN, 2RC, 2RK, 3EK, 6EN, 8EN, 14N, 12N, 12S, 1TN, ±1 %



Ratings

<±0.5 %>

Part No. (inch size)	Power Rating at 70 °C (1) (W)	Limiting Element Voltage ⁽²⁾ (V)	Maximum Overload Voltage ⁽³⁾ (V)	Resistance Tolerance (%)	Resista Rang (Ω	ge	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (°C)	AEC- Q200 Grade
ERJ1RH (0201)	0.05	15	30	±0.5	1 k to 1 M	(E24,E96)	±50	-55 to +125	-
ERJ2RH (0402)	0.063	50	100	±0.5	100 to 100 k	(E24,E96)	±50	-55 to +155	Grade 0
ERJ2RK (0402)	0.063	50	100	±0.5	10 to 97.6 102 k to 1 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ3RB (0603)	0.1	50	100	±0.5	100 to 100 k	(E24,E96)	±50	-55 to +155	Grade 0
ERJ3RE (0603)	0.1	50	100	±0.5	10 to 97.6 102 k to 1 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ6RB (0805)	0.1	150	200	±0.5	100 to 100 k	(E24,E96)	±50	-55 to +155	Grade 0
ERJ6RE (0805)	0.1	150	200	±0.5	10 to 97.6 102 k to 1 M	(E24,E96)	±100	-55 to +155	Grade 0

- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Ratings

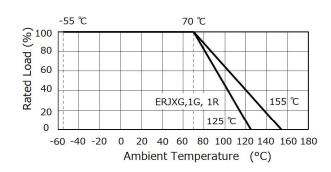
<±1 %>

Part No. (inch size)	Power Rating at 70 °C ⁽¹⁾ (W)	Limiting Element Voltage ⁽²⁾ (V)	Maximum Overload Voltage ⁽³⁾ (V)	Resistance Tolerance (%)	Resista Rang (Ω)	ge	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (°C)	AEC- Q200 Grade
ERJXGN (01005)	0.031	15	30	±1	10 to 1 M ⁽⁴⁾	(E24,E96)	R<100 Ω : ±300 100 Ω ≤R : ±200	-55 to +125	-
ERJ1GN (0201)	0.05	25	50	±1	10 to 1 M ⁽⁴⁾	(E24,E96)	±200	-55 to +125	Grade 1
ERJ2RC (0402)	0.1	50	100	±1	1 to 9.76	(E24,E96)	-100 to +600	-55 to +155	Grade 0
ERJ2RK (0402)	0.1	50	100	±1	10 to 1 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ3EK (0603)	0.1	75	150	±1	10 to 1 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ6EN (0805)	0.125	150	200	±1	10 to 2.2 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ8EN (1206)	0.25	200	400	±1	10 to 2.2 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ14N (1210)	0.5	200	400	±1	10 to 1 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ12N (1812)	0.75	200	500	±1	10 to 1 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ12S (2010)	0.75	200	500	±1	10 to 1 M	(E24,E96)	±100	-55 to +155	Grade 0
ERJ1TN (2512)	1	200	500	±1	10 to 1 M	(E24,E96)	±100	-55 to +155	Grade 0

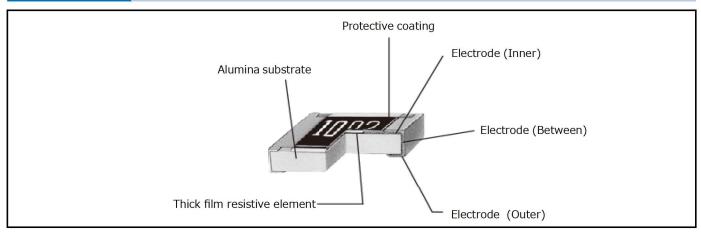
- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.
- (4) Please contact us when you need a type with a resistance of less than 10 $\ensuremath{\Omega}.$

Power Derating Curve

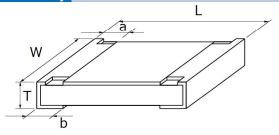
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



Construction



Dimensions in mm (not to scale)



Dort No	Dimensions (mm)									
Part No.	L	W	a	b	Т	(g/1000 pcs)				
ERJXGN	0.40±0.02	0.20±0.02	0.10±0.03	0.10±0.03	0.13±0.02	0.04				
ERJ1GN ERJ1R□	0.60±0.03	0.30±0.03	0.10±0.05	0.15±0.05	0.23±0.03	0.15				
ERJ2R□	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	0.8				
ERJ3R□ ERJ3EK	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2				
ERJ6R□ ERJ6EN	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4				
ERJ8EN	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10				
ERJ14N	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16				
ERJ12N	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27				
ERJ12S	5.00⊥0.20	2.50⊥0.20	0.60⊥0.20	0.60⊥0.20	0.60⊥0.10	27				
ERJ1TN	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45				

Performance

• Series ERJ1R, 2R, 3R, 6R, ±0.5 %(D)

Test Item	Performance Requirements ⊿R	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C
Overload	±2 %	Rated Voltage× 2.5, 5 s
Resistance to Soldering Heat	±1 %	270 °C, 10 s
Rapid Change of Temperature	±1 %	-55 °C (30 min.) / +155 °C (ERJ1R : +125 °C)(30 min.), 100 cycles
High Temperature Exposure	±1 %	+155 °C (ERJ1R : +125 °C), 1000 h
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h
Load Life in Humidity	±2 %	60 °C, 90 % to 95 %RH, Rated Voltage,
Load Life in Humidity	ERJ1R: ±3 %	1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 °C	±2 % ERJ1R : ±3 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h

• Series ERJXGN, 1GN, 2RC, 2RK, 3EK, 6EN, 8EN, 14N, 12N, 12S, 1TN, ±1 %(F)

Test Item	Performance	Test Conditions				
rest item	Requirements ⊿R	rest conditions				
Resistance	Within Specified	20 °C				
Resistance	Tolerance	20 - C				
T. C. R.	Within Specified	+25 °C/+155 °C (ERJXG,ERJ1G : +25℃/+125 °C)				
1. C. K.	T. C. R.	+23 C/+133 C (LK3/G,LK31G . +23 C/+123 C)				
Overload	±2 %	Rated Voltage× 2.5, 5 s				
Resistance to Soldering Heat	±1 %	270 °C, 10 s				
Rapid Change of Temperature	±1 %	-55 °C (30 min.)/+155 °C (ERJXG,ERJ1G: +125 °C)(30 min.),				
Kapid Change of Temperature	11 70	100 cycles				
High Temperature Exposure	±1 %	+155 °C (ERJXG,ERJ1G: +125 °C), 1000 h				
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h				
Load Life in Humidity	±2 %	60 °C, 90 % to 95 %RH, Rated Voltage,				
Load Life III Fluirilaity	ERJXG,1G: ±3 %	1.5 h ON / 0.5 h OFF cycle, 1000 h				
Endurance at 70 °C	±2 %	70 9C Pated Voltage 1 5 h ON / 0 5 h OFF syste 1000 h				
Elludiance at 70 °C	ERJXG,1G: ±3 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h				



Thin Film Chip Resistors, High Stability and Reliability Type

UPGRADE

Thin Film Chip Resistors, High Stability and Reliability Type

ERA V (High resistance value ERA K)

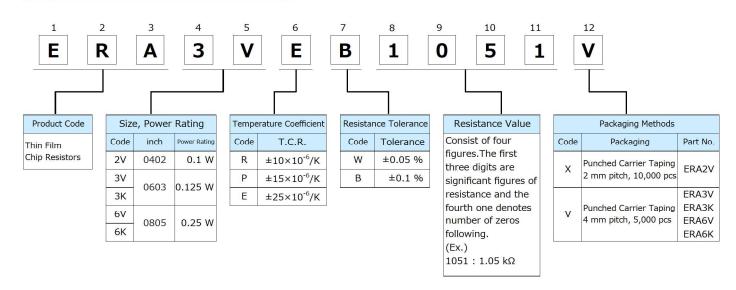
Series: ERA 2V, 3V, 6V (Series: ERA 3K, 6K)



Features

- High Power To realize higher Power Rating, Limiting Element Voltage, and Maximum
 - Overload Voltage than current products
- High reliability ······· Stable at high temperature and humidity
 - (85 °C 85 %RH rated load, Category temperature range : -55 °C to +155 °C)
- High accuracy Low resistance tolerance and Temperature Coefficient of Resistance
- ◆ High performance… Low current noise, excellent linearity
- Anti-ESD·······Original structure for high ESD performance (AEC-Q200-002 HBM Class 1c and above)
- Anti-sulfurated Original structure for sulfurated performance
- Reference Standard······ IEC 60115-8, JIS C 5201-8, JEITA RC-2133C
- AEC-Q200 compliant
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers



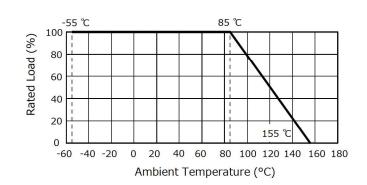
Rat	Ratings Ratings Representation of the Repres												
Part No. (inch size)	Power Rating at 85 °C ⁽¹⁾	Limiting Flement Voltage ⁽²⁾	Maximum Overload Voltage ⁽³⁾	Part No. (detail)	Resistance Tolerance	T.C.R.	Resistance Range $^{(4)}$		Category Temperature Range	AEC-Q200 Grade			
	(W)	(V)	(V)		(%)	(×10 ⁻⁶ /K)			(℃)				
				ERA2VEB	±0.1	±25	47 to 10 k	(E24, E96)					
ERA2V	0.1*	75*	150*	ERA2VPB	±0.1	±15	1 K to 10 k						
(0402)	0.1	/5*	150**	ERA2VRB	±0.1	±10		(E24, E96)					
				ERA2VRW	±0.05	110							
	0.125*	100*	200*	ERA3VEB	±0.1	±25	47 to 100 k	(E24, E96)					
ERA3V				ERA3VPB	±0.1	±15	1 K to 100 k						
(0603)				ERA3VRB	±0.1	±10							
				ERA3VRW	±0.05	±10			FF to 11FF	Cuada 0			
ERA3K (0603)	0.125*	100*	200*	ERA3KEB	±0.1	±25	102 K to 240	k (E24, E96)	-55 to +155	Grade 0			
				ERA6VEB	±0.1	±25	47 to 100 k	(E24, E96)					
ERA6V	0.25*	150*	200*	ERA6VPB	±0.1	±15							
(0805)	0.25	150	300*	ERA6VRB	±0.1	±10	1 K to 100 k	(E24, E96)					
				ERA6VRW	±0.05	110							
ERA6K (0805)	0.25*	150*	300*	ERA6KEB	±0.1	±25	102 K to 750	k (E24, E96)					

- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Values, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (2.5) × RCWV or Maximum Overload Voltage listed above, whichever less.
- (4) E192 series resistance values are also available. The E192 series has custom part numbers. Please contact us for details.
- *: UPGRADE

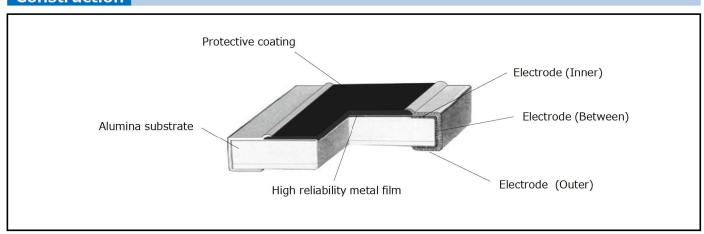
(0805)

Power Derating Curve

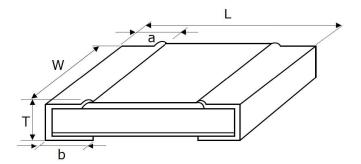
For resistors operated in ambient temperatures above 85 °C, power rating shall be derated in accordance with the figure on the right.



Construction



Dimensions in mm (not to scale)



Part No.	Dimensions (mm)								
rait No.	L	W	a	b	Т	(g/1000 pcs)			
ERA2V	1.00±0.05	0.50+0.10/-0.05	0.25±0.10	0.25±0.10	0.35±0.05	0.6			
ERA3V, 3K	1.60±0.15	0.80±0.10	0.30±0.20	0.30±0.20	0.45±0.10	2			
ERA6V, 6K	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.55±0.10	5			

Performance

Test Item	Performance Requirements ⊿R	Test Conditions			
Resistance	Within Specified Tolerance	20 °C			
T. C. R. Within Specified T. C. R. +25 °C,		+25 °C/+125 °C			
Overload	Overload ±0.1 % Rated Voltage× 2.5, 5 s				
Resistance to Soldering Heat	±0.1 %	270 °C, 10 s			
Rapid Change of Temperature	±0.1 %	-55 °C (30 min.) / +155 °C (30 min.), 1000 cycles			
High Temperature Exposure	±0.1 %	+155 °C, 1000 h			
Damp Heat, Steady State	±0.1 %	85 °C, 85 %RH, 1000 h			
Load Life in Humidity	±0.1 %	85 °C, 85 %RH, 10 % of Rated Power ⁽¹⁾ ,			
Loud Life in Flaminity	10.1 70	1.5 h ON / 0.5 h OFF cycle , 1000 h			
Endurance at 85 °C	±0.1 %	85 °C , Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h			
Electro Static Discharge (HBM)	±0.1 % ⁽²⁾	AEC-Q200-002 : 150 pF, 2000 Ω , positive 5 times, negative 5 times ERA2V : 1.0 kV (Class 1c) ERA3V(3K) : 1.5 kV (Class 1c) ERA6V(6K) : 2.0 kV (Class 2)			

⁽¹⁾ Applied Voltage is " $\sqrt{0.1 \times \text{Power Rating} \times \text{Resistance Values}}$ ", or "Limiting Element Voltage $\times 0.316$ ", whichever less.

⁽²⁾ Depends on resistance value.



Metal Film (Thin Film) Chip Resistors, High Reliability Type

102 102 102

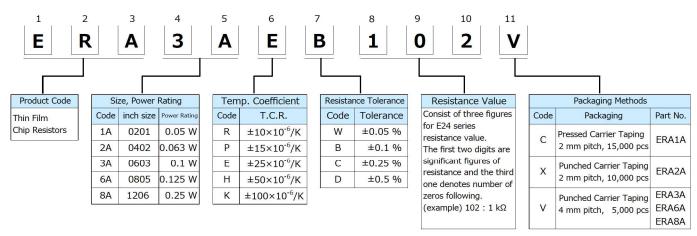
Series: ERA 1A, 2A, 3A, 6A, 8A

Features

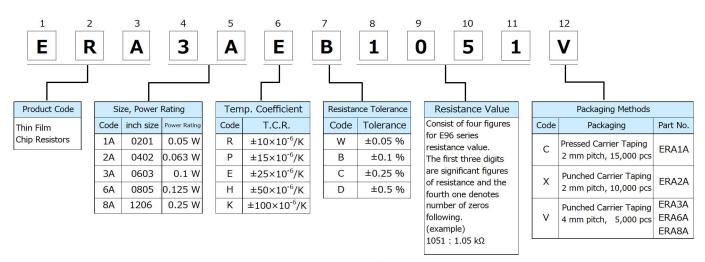
- ◆ High reliability······· Stable at high temperature and humidity
 (85 °C 85 %RH rated load, Category temperature range: -55 °C to +155 °C)
- High accuracy Low resistance tolerance and Temperature Coefficient of Resistance
- High performance…Low current noise, excellent linearity
- Reference Standard······ IEC 60115-8, JIS C 5201-8, JEITA RC-2133C
- AEC-Q200 compliant (except ERA1A)
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers

E24 Series



E96 Series and other Resistance values



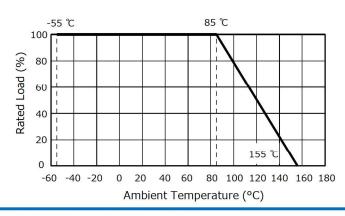
Note: Duplicated resistance values as E24 series part umbers shall follow E24 part numbers. (apply three digit resistance value)

Rat	ings									
Part No. (inch size)	Power Rating at 85 °C ⁽¹⁾	Limiting Element Voltage ⁽²⁾	Maximum Overload Voltage ⁽³⁾	Part No. (detail)	Resistance Tolerance	T.C.R.	Resista Range ⁽		Category Temperature Range	AEC-Q200 Grade
	(W)	(V)	(V)		(%)	(×10 ⁻⁶ /K)	(Ω)		(℃)	
				ERA1AEB	±0.1	±25	100 to 10 k	(E24,E96)		
ERA1A				ERA1AEC	±0.25	-23	100 to 10 K	(221,230)		
(0201)	0.05	25	50	ERA1ARC	±0.25		100 to 10 k	(E24,E96)		-
(0201)				ERA1ARB	±0.1	±10	100 to 10 K	(LZ 1,L30)		
				ERA1ARW	±0.05		1 k to 10 k	(E24,E96)		
				ERA2AKD	±0.5	±100	10 to 46.4	(E24,E96)		
				ERA2AED	±0.5					
				ERA2AEC	±0.25	±25	47 to 100 k	(E24,E96)		
ERA2A (0402) 0.063 50	50	100	ERA2AEB	±0.1					Grade 1	
	30	100	ERA2APC	±0.25	±15	200 to 47 k	(E24,E96)		Grade 1	
				ERA2APB	±0.1	113	200 to 17 K	(221,230)	<u></u>	
			ERA2ARC	±0.25	±10	200 to 47 k	(E24,E96))		
				ERA2ARB	±0.1	_10	200 to 47 K	200 to 47 K (E24,E96)		
				ERA3AHD	±0.5	±50	10 to 46.4	(E24,E96)		
			75 150	ERA3AED	±0.5					
				ERA3AEC	±0.25	±25	47 to 330 k	(E24,E96)		
ERA3A				ERA3AEB	±0.1					
(0603)	0.1	75		ERA3APC	±0.25	±15 ±10	470 to 100 k	(E24,E96)		Grade 0
(0003)				ERA3APB	±0.1		470 to 100 K	(LZ4,L30)		
				ERA3ARC	±0.25				-55 to +155	
				ERA3ARB	±0.1		1 k to 100 k	(E24,E96)	33 (0 1133	
				ERA3ARW	±0.05					
				ERA6AHD	±0.5	±50	10 to 46.4	(E24,E96)		
				ERA6AED	±0.5					
				ERA6AEC	±0.25	±25	47 to 1 M	(E24,E96)		
ERA6A				ERA6AEB	±0.1					
(0805)	0.125	100	200	ERA6APC	±0.25	±15	470 to 100 k	(E24,E96)		Grade 0
(0003)				ERA6APB	±0.1	±13	470 to 100 K	(LZ4,L30)		
				ERA6ARC	±0.25					
				ERA6ARB	±0.1	±10	1 k to 100 k	(E24,E96)		
				ERA6ARW	±0.05					
				ERA8AHD	±0.5	±50	10 to 46.4	(E24,E96)		
				ERA8AED	±0.5					
				ERA8AEC	±0.25	±25	47 to 1 M	(E24,E96)		
ERA8A		5 150		ERA8AEB	±0.1					
(1206)	0.25		150 300	ERA8APC	±0.25		470 to 100 li	/E24 F0C\	6)	Grade 0
(1200)				ERA8APB	±0.1	±15	470 to 100 k (E24,E9	(LZ4,L30)		
				ERA8ARC	±0.25					
				ERA8ARB	±0.1	±10	0 1 k to 100 k (E24	(E24,E96)		
				ERA8ARW	±0.05					

- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Values, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (2.5) \times RCWV or Maximum Overload Voltage listed above, whichever less.
- (4) E192 series resistance values are also available. Please contact us for details.
- (5) Duplicated resistance values between E96, E192 and E24 series shall follow E24 Part Numbers. (apply three digit resistance value)

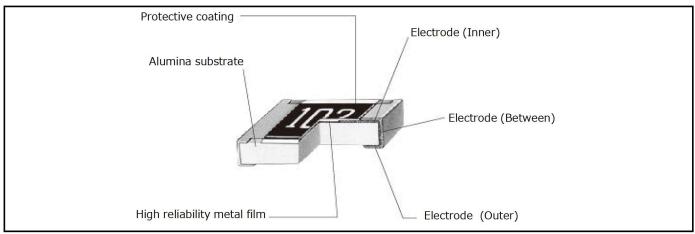
Power Derating Curve

For resistors operated in ambient temperatures above 85 °C, power rating shall be derated in accordance with the figure on the right.



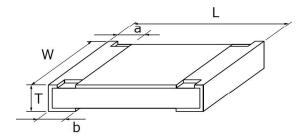


Construction



^{*0201/0402} size or E96 series do not have value markings.

Dimensions in mm (not to scale)



Part No.	Dimensions (mm)								
rait No.	L	W	a	b	Т	(g/1000 pcs)			
ERA1A	0.60±0.03	0.30±0.03	0.15±0.05	0.15±0.05	0.23±0.03	0.14			
ERA2A	1.00±0.10	0.50+0.10/-0.05	0.15±0.10	0.25±0.10	0.35±0.05	0.6			
ERA3A	1.60±0.20	0.80±0.20	0.30±0.20	0.30±0.20	0.45±0.10	2			
ERA6A	2.00±0.20	1.25±0.10	0.40±0.25	0.40±0.25	0.50±0.10	4			
ERA8A	3.20±0.20	1.60+0.05/-0.15	0.50±0.25	0.50±0.25	0.60±0.10	8			



High Precision Thick Film Chip Resistors

High Precision Thick Film Chip Resistors

1004

Series: ERJ PB3, PB6

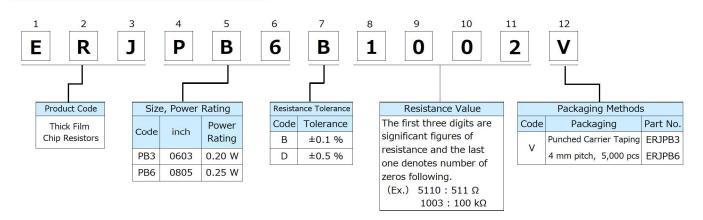
Features

- Achieve the resistance tolerance ±0.1 % with high reliability metal glaze thick film resistor
- Guarantee the temperature coefficient of Resistance $\pm 50 \times 10^{-6}$ /K in high resistance range up to 1 M Ω
- ◆ High power ··· 0.20 W : 0603 inch /1608 mm size (ERJPB3)

0.25 W: 0805 inch /2012 mm size (ERJPB6)

- Reference Standard ··· IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers



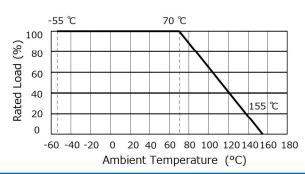
Ratings

Part No. (inch size)	Power Rating at 70 °C (1) (W)	Limiting Element Voltage ⁽²⁾ (V)	Maximum Overload Voltage ⁽³⁾ (V)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (°C)	AEC- Q200 Grade
ERJPB3 (0603)	0.20	150	200	±0.1 ±0.5	200 to 100 k (E24, E96)	±50	-55 to +155	Grade 0
ERJPB6 (0805)	0.25	150	200	±0.1 ±0.5	200 to 1 M (E24, E96)	±50	-55 to +155	Grade 0

- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

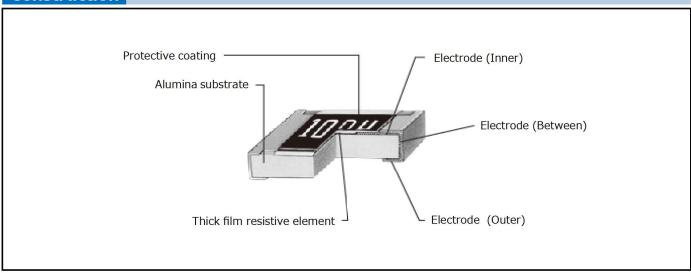
Power Derating Curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.

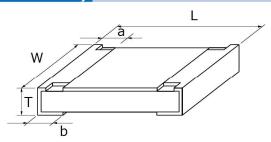


High Precision Thick Film Chip Resistors

Construction



Dimensions in mm (not to scale)



Part No.	Dimensions (mm)						
rait No.	L	W	a	b	Т	(g/1000 pcs)	
ERJPB3	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.25±0.10	0.45±0.10	2	
ERJPB6	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4	

Performance

Test Item	Performance	Test Conditions		
rest term	Requirements ⊿R	rest conditions		
Resistance	Within Specified	20 °C		
Resistance	Tolerance	20 C		
T. C. R.	Within Specified	+25 °C/+125 °C		
1. C. K.	T. C. R.	+25 -0/+125 -0		
Overload	±0.5 %	Rated Voltage× 2.0, 5 s		
Resistance to Soldering Heat	±0.5 %	270 °C, 10 s		
Rapid Change of Temperature	±0.5 %	-55 °C (30 min.) / +155 °C (30 min.), 100 cycles		
High Temperature Exposure	±0.5 %	+155 °C, 1000 h		
Damp Heat, Steady State	±0.5 %	60 °C, 90 % to 95 %RH, 1000 h		
Load Life in Humidity	±0.5 %	60 °C, 90 % to 95 %RH, Rated Voltage,		
Load Life III Haiffidity	±0.5 %	1.5 h ON / 0.5 h OFF cycle, 1000 h		
Endurance at 70 °C	±0.5 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h		



Thick Film Chip Resistors / Low Resistance Type

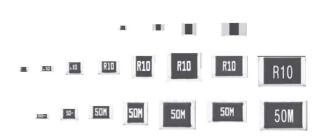
Thick Film Chip Resistors / **Low Resistance Type**

Series: ERJ 2LW, 3LW, 6LW, ERJ 2BW, 3BW, 6BW, 8BW, 6CW, 8CW

ERJ 2B, 3B, 6D, 6B, 8B, 14B,

ERJ 3R, 6R, 8R, 14R, 12R, 12Z, 1TR

ERJ L03, L06, L08, L14, L12, L1D, L1W

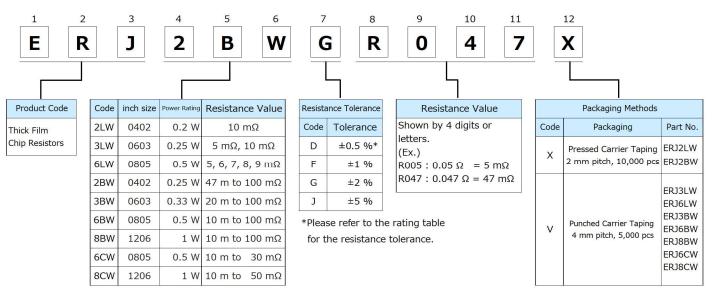


Features

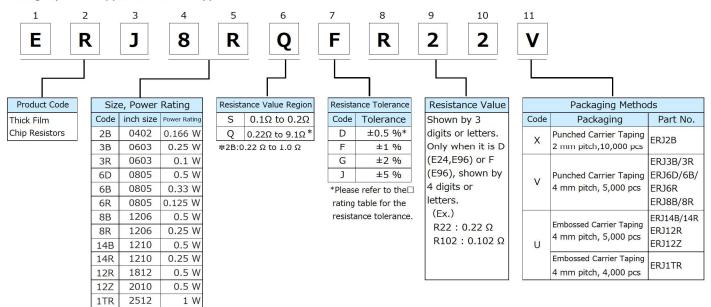
- Current Sensing resistor
- Small size and lightweight
- Realize both low-resistance & High-precision by original thick film resistive element & special electrode structure
- Suitable for both reflow and flow soldering
- Realize High-power by double-sided resistive elements structure that aimed to suppress temperature rising··· ERJ2LW, 3LW, 6LW, 2BW, 3BW, 6BW, 8BW, 6CW, 8CW
- Low TCR······ ±75×10⁻⁶/K (ERJ6CW, ERJ8CW)
- Low Resistance Value ··· Thick film resistors available from 5 m Ω (ERJ3LW, 6LW)
- Reference Standard IEC 60115-8, JIS C 5201-8, JEITA RC-2144
- AEC-Q200 compliant
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers

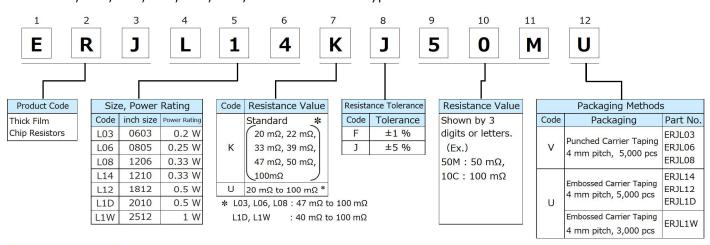
 ERJ2LW, 3LW, 6LW, 2BW, 3BW, 6BW, 8BW, 6CW, 8CW < High power (double-sided resistive elements structure) type>



• ERJ2BS/2BQ, 3BS/3BQ, 6BS/6BQ, 8BS/8BQ, 14BS/14BQ, 6D, 3R, 6R, 8R, 14R, 12R, 12Z, 1TR < High power type/Standard type>



• ERJL03, L06, L08, L14, L12, L1D, L1W <Low TCR type>



Ratings

< High power (double-sided resistive elements structure) type>

Part I (inch s		Power Rating at 70 °C ⁽¹⁾ (W)	Resistance Tolerance (%)	Resistance Range ⁽²⁾ (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range(℃)	AEC- Q200 Grade
ERJ2LW	(0402)	0.2	±1, ±2, ±5	10 m	0 to +500	-55 to +125	Grade 1
ERJ3LW	(0603)	0603) 0.25	±1, ±2, ±5	5 m	0 to +700	55 to 125	Grade 1
LIOSLW	(0003)	0.23	11, 12, 13	10 m	0 to +300	-55 to +125	Orace 1
ERJ6LW	(0805)	0.5	±1, ±2, ±5	5, 6, 7, 8, 9 m	0 to +300	-55 to +125	Grade 1
ERJ2BW	(0402)	0.25	±1, ±2, ±5	47 m to 100 m (E24)	0 to +300	-55 to +155	Grade 0
ERJ3BW	(0603)	0.33	±1, ±2, ±5	20 m to 100 m (E24)	20 mΩ ≤ R < 39 mΩ:0 to +250 39 mΩ ≤ R ≤ 100 mΩ:0 to +150	-55 to +155	Grade 0
ERJ6BW	(0805)	0.5	±1, ±2, ±5	10 m to 100 m (E24)	10 mΩ ≤ R < 15 mΩ:0 to +300 15 mΩ ≤ R ≤ 100 mΩ:0 to +200	-55 to +155	Grade 0
ERJ8BW	(1206)	1	±1, ±2, ±5	10 m to 100 m (E24)	$10 \text{ m}\Omega \le R < 20 \text{ m}\Omega:0 \text{ to } +200$ $20 \text{ m}\Omega \le R < 47 \text{ m}\Omega:0 \text{ to } +150$ $47 \text{ m}\Omega \le R \le 100 \text{ m}\Omega:0 \text{ to } +100$	-55 to +155	Grade 0
ERJ6CW	(0805)	0.5	±0.5, ±1, ±2, ±5	10 m to 30 m (E24)	±75	-55 to +125	Grade 1
ERJ8CW	(1206)	1	±1, ±2, ±5	10 m to 50 m (E24)	±75	-55 to +125	Grade 1

- (1) Use it on the condition that the case temperature is below the upper category temperature.
 - Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value.
 - · Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.
- (2) Please contact us when resistors of irregular series are needed.

Ratings

<High power type>

Part I (inch s		Power Rating at 70 °C ⁽¹⁾ (W)	Resistance Tolerance ⁽²⁾ (%)	Resista Range (Ω)	(3)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range(℃)	AEC- Q200 Grade
ERJ2BS	(0402)	0.166	±1, ±2, ±5	0.10 to 0.20	(E24)	$0.10 \Omega \le R < 0.22 \Omega$: 0 to +300	-55 to +155	Grade 0
ERJ2BQ	(0402)	0.100	11, 12, 13	0.22 to 1.0	(E24)	$0.22 \Omega \le R \le 1.0 \Omega$: 0 to +250	-55 to +155	Grade 0
ERJ3BS	(0603)			0.10 to 0.20	(E24)	$0.10 \Omega \le R < 0.22 \Omega$: 0 to +300		
ERJ3BQ	(0603)	0.25	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega$: 0 to +300	-55 to +155	Grade 0
EKJSBQ	(0003)			1.0 to 9.1	(E24)	$1.0 \Omega \le R \le 9.1 \Omega$: ±200		
ERJ6DS	(0805)			0.10 to 0.20	(E24,E96)	$0.10 \Omega \le R < 0.22 \Omega$: 0 to +150		,
ERJ6DQ	(0805)	0.5	± 0.5 , ± 1 , ± 2 , ± 5	0.22 to 9.1	(E24,E96)	$0.22 \Omega \le R < 1.0 \Omega$: 0 to +100	-55 to +155	Grade 0
EKJODQ	(0003)			0.22 10 9.1	(624,690)	$1.0 \Omega \le R \le 9.1 \Omega$: ±100		
ERJ6BS	(0805)			0.10 to 0.20	(E24)	$0.10 \Omega \le R < 0.22 \Omega$: 0 to +250		
ED16BO	(0805)	0.33	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega$: 0 to +250	-55 to +155	Grade 0
ERJ6BQ	(0805)			1.0 to 9.1	(E24)	$1.0 \Omega \le R \le 9.1 \Omega$: ±200		
ERJ8BS	(1206)			0.10 to 0.20	(E24)	$0.10 \Omega \le R < 0.22 \Omega$: 0 to +250		
ED 10DO	(1206)	0.5	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega$: 0 to +250	-55 to +155	Grade 0
ERJ8BQ	(1206)			1.0 to 9.1	(E24)	$1.0 \Omega \le R \le 9.1 \Omega$: ±200		
ERJ14BS	(1210)			0.10 to 0.20	(E24)	$0.10 \Omega \le R < 0.22 \Omega$: 0 to +200		
ED114BO	(1210)	0.5	±1, ±2, ±5	0.22 to 0.91	(E24)	$0.22 \Omega \le R < 1.0 \Omega$: 0 to +200	-55 to +155	Grade 0
ERJ14BQ	(1210)			1.0 to 9.1	(E24)	$1.0 \Omega \le R \le 9.1 \Omega$: ±100		

- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) E96 series also have ± 0.5 %, ± 1 % line-up.
 - Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\(\overline{Power Rating} \times \text{Resistance Value.} \)
 - · Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.
- (3) Please contact us when resistors of irregular series are needed.

<Standard type>

Part (inch		Power Rating at 70 °C ⁽¹⁾ (W)	Resistance Tolerance (%)	Resistance Range ⁽²⁾ (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (℃)	AEC- Q200 Grade	
ERJ3RS	(0603)			0.10 to 0.20 (E24)	$0.10 \Omega \le R < 0.22 \Omega$: 0 to +300			
ERJ3RQ	(0603)	0.1	$\pm 1, \pm 2, \pm 5$	0.22 to 0.91 (E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +300$	-55 to +155	Grade 0	
LIBSING	(0003)			1.0 to 9.1 (E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 200$			
ERJ6RS	(0805)			0.10 to 0.20 (E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega$: 0 to +250			
ERJ6RQ	(0805)	0.125	$\pm 1, \pm 2, \pm 5$	0.22 to 0.91 (E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +250$	-55 to +155	Grade 0	
LIBORQ	(0003)			1.0 to 9.1 (E24)	$1.0 \Omega \le R \le 9.1 \Omega$: ±200			
ERJ8RS	(1206)			0.10 to 0.20 (E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega$: 0 to +250			
ERJ8RQ	(1206)	0.25	0.25	±1, ±2, ±5	0.22 to 0.91 (E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +250$	-55 to +155	Grade 0
LIBORQ	(1200)			1.0 to 9.1 (E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 200$			
ERJ14RS	(1210)			0.10 to 0.20 (E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega$: 0 to +200			
ERJ14RQ	(1210)	0.25	±1, ±2, ±5	0.22 to 0.91 (E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +200$	-55 to +155	Grade 0	
LISTING	(1210)			1.0 to 9.1 (E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 100$			
ERJ12RS	(1812)			0.10 to 0.20 (E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega$: 0 to +200			
ERJ12RQ	(1812)	0.5	±1, ±2, ±5	0.22 to 0.91 (E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +200$	-55 to +155	Grade 0	
LIGIZINQ	(1012)			1.0 to 9.1 (E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 100$			
ERJ12ZS	(2010)			0.10 to 0.20 (E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega$: 0 to +200			
ERJ12ZQ	(2010)	0.5	±1, ±2, ±5	0.22 to 0.91 (E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +200$	-55 to +155	Grade 0	
LIGIZZQ	2Q (2010)			1.0 to 9.1 (E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 100$			
ERJ1TRS	(2512)			0.10 to 0.20 (E24)	$0.10 \ \Omega \le R < 0.22 \ \Omega$: 0 to +200			
ERJ1TRQ	(2512)	1	±1, ±2, ±5	0.22 to 0.91 (E24)	$0.22 \Omega \le R < 1.0 \Omega : 0 \text{ to } +200$	-55 to +155	Grade 0	
LIGITIQ	(2312)			1.0 to 9.1 (E24)	$1.0 \Omega \le R \le 9.1 \Omega : \pm 100$			

- (1) Use it on the condition that the case temperature is below the upper category temperature.
 - Rated Continuous Working Voltage (RCWV) shall be determined from RCWV= $\sqrt{\text{Power Rating}} \times \text{Resistance Value}$.
 - · Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.
- (2) Please contact us when resistors of irregular series are needed.

Ratings

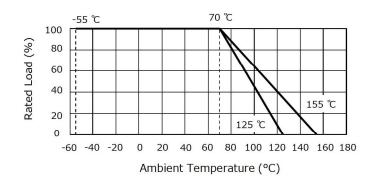
<Low TCR type>

Part (inch		Power Rating at 70 °C ⁽¹⁾ (W)	Resistance Tolerance (%)	Resistance Range ⁽²⁾ (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range(℃)	AEC- Q200 Grade
ERJL03	(0603)	0.2	±1, ±5	47 m to 100 m	±200	-55 to +125	Grade 1
ERJL06	(0805)	0.25	±1, ±5	47 m to 100 m	±100	-55 to +125	Grade 1
ERJL08	(1206)	0.33	±1, ±5	47 m to 100 m	±100	-55 to +125	Grade 1
ERJL14	(1210)	0.33	±1, ±5	20 m to 100 m		-55 to +125	Grade 1
ERJL12	(1812)	0.5	±1, ±5	20 m to 100 m	$R < 47 \text{ m}\Omega : \pm 300$	-55 to +125	Grade 1
ERJL1D	(2010)	0.5	±1, ±5	40 m to 100 m	$R \ge 47 \text{ m}\Omega: \pm 100$	-55 to +125	Grade 1
ERJL1W	(2512)	1	±1, ±5	40 m to 100 m		-55 to +125	Grade 1

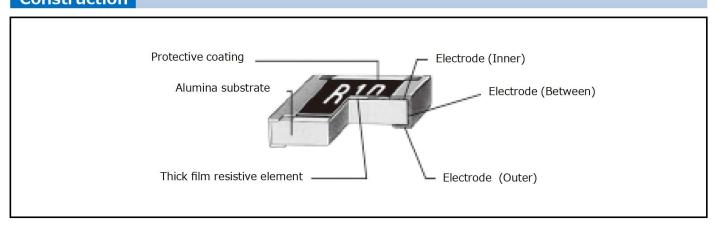
- (1) Use it on the condition that the case temperature is below the upper category temperature.
 - Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\(\sqrt{Power Rating} \times \text{Resistance Value}.
 - · Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.
- (2) Standard R.V. : 20 m Ω , 22 m Ω , 33 m Ω , 39 m Ω , 47 m Ω , 50 m Ω , 100 m Ω , Custom R.V. : Each 1 m Ω within upper range.

Power Derating Curve

For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure on the right.

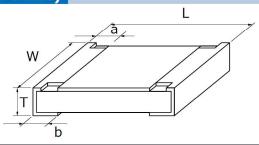


Construction





Dimensions in mm (not to scale)



Part No.			Dimensions (mm)		0	Mass (Weight)
Part No.	L	W	a	b	Т	(g/1000pcs)
ERJ2LW	1.00±0.10	0.50+0.10/-0.05	0.25±0.10	0.25±0.10	0.40±0.05	0.8
ERJ2BW	1.00±0.10	0.50+0.10/-0.05	0.24±0.10	0.24±0.10	0.35±0.05	0.8
ERJ2B	1.00±0.10	0.50+0.10/-0.05	0.20±0.10	0.27±0.10	0.35±0.05	0.8
ERJ3LW (5 mΩ)	1.60±0.15	0.80±0.15	0.50±0.20	0.50±0.20	0.55±0.10	3
ERJ3LW (10 m Ω) ERJ3BW	1.60±0.15	0.80±0.15	0.40±0.20	0.40±0.20	0.55±0.10	3
ERJ3R ERJ3B ERJL03	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2
ERJ6LW	2.00±0.20	1.25±0.20	0.63±0.20	0.63±0.20	0.70±0.10	6
ERJ6BW	2.00±0.20	1.25±0.20	0.55±0.20	0.55±0.20	0.65±0.10	6
ERJ6CW (10 to 13 mΩ) ERJ6CW	2.05±0.20	1.30±0.20	0.60±0.20	0.60±0.20	0.65±0.10	6
(15 to 30 mΩ)			0.45±0.20	0.45±0.20		
ERJ6D	2.00±0.20	1.25±0.10	0.40±0.20	0.55±0.25	0.60±0.10	5
ERJ6R ERJ6B ERJL06	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	5
ERJ8BW	3.20±0.20	1.60±0.20	1.00±0.20	1.00±0.20	0.65±0.10	13
ERJ8CW (10 to 16 mΩ)	3.20±0.20	1.60±0.20	1.10±0.20	1.10±0.20	0.65±0.10	13
ERJ8CW (18 to 50 mΩ)	3.20±0.20	1.60±0.20	0.60±0.20	0.60±0.20	0.65±0.10	13
ERJ8R ERJ8B ERJL08	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10
ERJ14R ERJ14B ERJL14	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16
ERJ12R ERJL12	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27
ERJ12Z ERJL1D	5.00±0.20	2.50±0.20	0.60±0.20	0.60±0.20	0.60±0.10	27
ERJ1TR	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45
ERJL1W	6.40±0.20	3.20±0.20	0.65±0.20	1.30±0.20	1.10±0.10	79



Performance

ERJ2LW, 3LW, 6LW, 2BW, 3BW, 6BW, 8BW, 6CW, 8CW
 High power (double-sided resistive elements structure) type>

Test Item	Performance Requirements ⊿R	Test Conditions			
Resistance	Within Specified	20 °C			
Resistance	Tolerance	20 C			
T. C. R.	Within Specified	 +25 °C/+125 °C			
1. C. K.	T. C. R.	+23 °C/+123 °C			
		ERJ6LW : Rated Voltag× 1.77, 5 s			
Overload	±2 %	ERJ8BW (R > 0.05 Ω) : Rated Voltag× 1.77, 5 s			
		Other : Rated Voltag× 2.0 , 5 s			
Resistance to Soldering Heat	±1 %	270 °C, 10 s			
D :16	±1 %	-55 °C (30min.) / +155 °C (ERJ□LW, ERJ□CW : +125 °C)			
Rapid Change of Temperature	ERJ2LW: ±2 %	(30 min.), 100 cycles			
High Temperature Exposure	±1 %	+155 °C (ERJ□LW, ERJ□CW : +125 °C), 1000 h			
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h			
Load Life in Humidity	±3 %	60 °C, 90 % to 95 %RH, Rated Voltage,			
Load Life in Humidity	±3 %	1.5 h ON / 0.5 h OFF cycle , 1000 h			
Endurance at 70 °C	±3 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h			

ERJ2BS/2BQ, 3BS/3BQ, 6BS/6BQ, 8BS/8BQ, 14BS/14BQ, 6D, 3R, 6R, 8R, 14R, 12R, 12Z, 1TR
 High power type/Standard type>

Test Item	Performance Requirements ⊿R	Test Conditions		
Resistance	Within Specified	20 °C		
Resistance	Tolerance	20 0		
T. C. R.	Within Specified	+25 °C/+125 °C		
1. C. K.	T. C. R.	+23 C/ +123 C		
Overload	±2 %	Rated Voltage× 2.5 (ERJ6D: ×1.77), 5 s		
Resistance to Soldering Heat	±1 %	270 °C, 10 s		
Rapid Change of Temperature	±1 %	-55 °C (30 min.) / +155 °C (30 min.), 100 cycles		
High Temperature Exposure	±1 %	+155 °C, 1000 h		
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h		
Load Life in Humidity	±3 %	60 °C, 90 % to 95 %RH, Rated Voltage,		
Load Life in Fidifilally	13 %	1.5 h ON / 0.5 h OFF cycle , 1000 h		
Endurance at 70 °C	±3 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h		

• ERJL03, L06, L08, L14, L12, L1D, L1W < Low TCR type >

Test Item	Performance Requirements ⊿R	Test Conditions		
Resistance	Within Specified Tolerance	20 °C		
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C		
Overload	±2 %	Rated Voltage× 2.5, 5 s		
Resistance to Soldering Heat	±1 %	270 °C, 10 s		
Rapid Change of Temperature	±1 %	-55 °C (30 min.) / +125 °C (30 min.), 100 cycles		
High Temperature Exposure	±1 %	+125 °C, 1000 h		
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h		
Load Life in Humidity ±3 9		60 °C, 90 % to 95 %RH, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle , 1000 h		
Endurance at 70 °C	±3 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h		



Current Sensing Resistors, Metal Plate Type

Current Sensing Resistors, Metal Plate Type

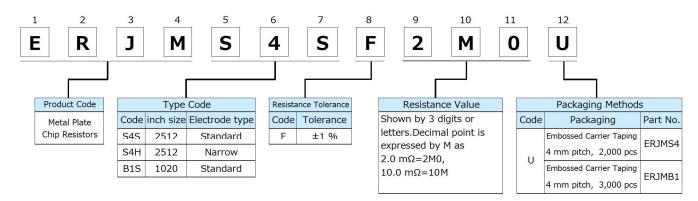
11

Series: ERJ MS4, MB1

Features

- Ideal for current sensing solution
- Small case size with high power
- Metal plate bonding technology. Excellent long term stability
- Outer Resin with high heat dissipation. Wide temperature range (-65 $^{\circ}$ to +170 $^{\circ}$)
- AEC-Q200 compliant
- RoHS compliant
- ISO9001, ISO/TS16949 certified
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers



Ratings

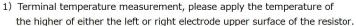
Part No. (inch size)	Power Rating at 70 °C (W)	Resistance Range (mΩ)	Resistance Tolerance (%)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (℃)	Terminal temp. upper limit (℃)	AEC-Q200 Grade
ERJMS4S (2512)	3	1, 2, 3, 4	F: ±1	±75	-65 to +170	130	Grade 0
ERJMS4H	3	5, 6	F: ±1	±75	-65 to +170	130	Grade 0
(2512)	2	7, 8, 9, 10	F: ±1	±75	-65 to +170	100	Grade 0
ERJMB1S (1020)	2	1, 2, 3, 4, 5	F: ±1	±75	-65 to +170	130	Grade 0

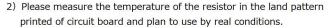
^{*} Please contact us when resistors of irregular series are needed.

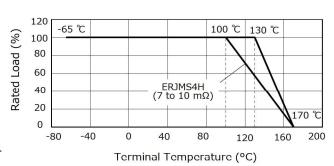
Power Derating Curve

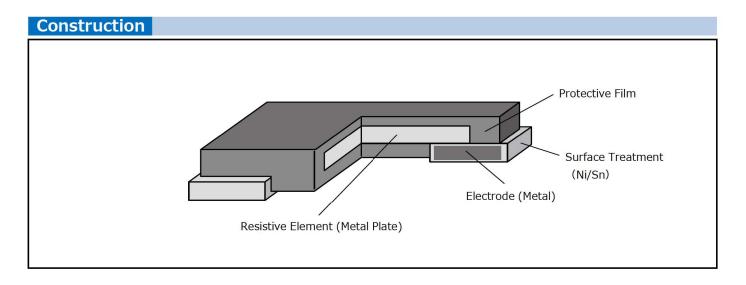
If the terminal temperature of the resistor is more than terminal temperature upper limit value of the rated table, please reduce the rated power according to the Power Derating Curve shown in the figure on the right. <Supplemented>

In the case of the temperature measurement of the terminal portion of the resistor, Please perform under the following conditions.





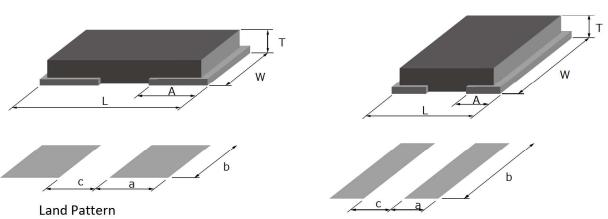




Dimensions in mm (not to scale), Recommended Land Pattern



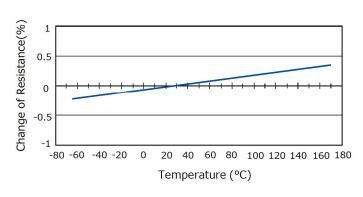


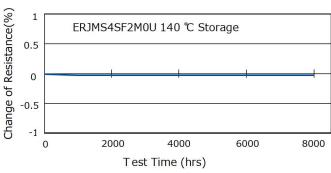


Part No.		Dimensio	Recomm	Mass (Weight)				
	L	W	Α	Т	a	b	С	(g/1000 pcs)
ERJMS4S	6.40±0.25	3.20±0.25	2.20±0.25	1.20±0.15	2.7	3.4	2.0	120
ERJMS4H	6.40±0.25	3.20±0.25	1.25±0.25	1.20±0.15	1.7	3.4	4.0	115
ERJMB1S	2.55±0.25	5.00±0.25	0.68 +0.15/-0.20	0.90±0.15	1.15	5.5	1.1	40

Typical Temp. dependence of electrical resistance

Long-term stability





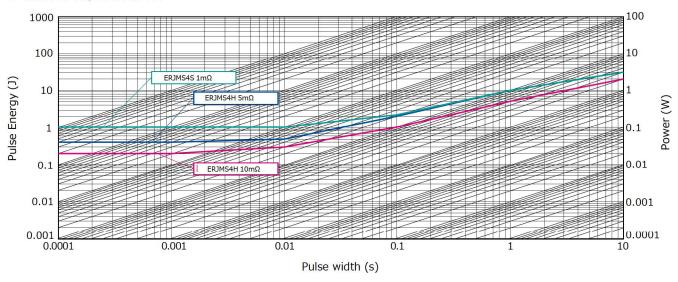
Maximum pulse energy respectively pulse power for continuous operation

Referance Data

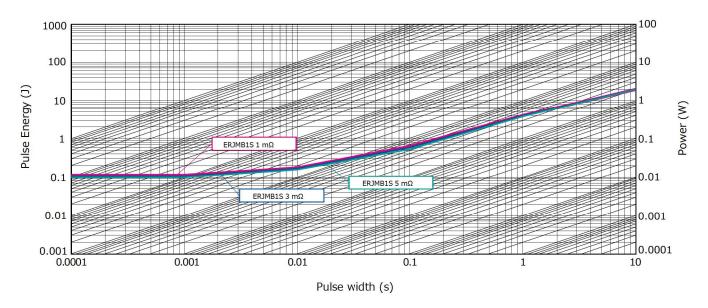
Condition: Room Temperature, OFF: 10 s, 1000 cycle, Wave form: Square

Change of Resistance = ± 1 %

ERJMS4S/ERJMS4H



• ERJMB1S



Performance (AEC-Q200)

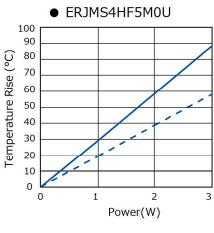
• ERJMS4S/ERJMS4H

Test Item	Performance Requirements ⊿R	Typical value ⊿R	Test Condition
Thermal Shock	±1 %	0.20 %	-55 °C / +155 °C, 1000 cycles
Overload	±0.5 %	0.10 %	Rated Power× 3, 5 s
Solderability	> 95% coverage	> 95% coverage	245 °C, 3 s
Resistance to Solvents	No damage	No damage	MIL-STD-202 method 215, 2.1a, 2.1d
Low Temperature Storage and Operation	±0.5 %	0.03 %	−65 °C, 24 h
Resistance to Soldering Heat	±0.5 %	0.10 %	MIL-STD-202 method 210 (260 °C, 10 s)
Moisture Resistance	±0.5 %	0.10 %	MIL-STD-202 method 106
Shock	±0.5 %	0.10 %	MIL-STD-202 method 213-A
Vibration, High Frequency	±0.5 %	0.05 %	10 to 2000 (Hz)
Life	±1 %	0.30 %	70 °C, Rated Power, 2000 h
Storage Life at Elevated Temperature	±1 %	0.30 %	170 °C, 2000 h
High Temperature Characteristics	±0.5 %	0.05 %	140 °C, 2000 h
Frequency Characteristics	< 5 nH	< 2 nH	Inductance

FRJMB1

Test Item	Performance Requirements ⊿R	Typical value ⊿R	Test Condition
Thermal Shock	±1 %	0.30 %	−55 °C / +155 °C, 1000 cycles
Overload	±1 %	0.30 %	Rated Power× 2.5, 5 s
Solderability	> 95% coverage	> 95% coverage	245 °C, 3 s
Resistance to Solvents	No damage	No damage	MIL-STD-202 method 215, 2.1a, 2.1d
Low Temperature Storage and Operation	±0.5 %	0.03 %	−65 °C, 24 h
Resistance to Soldering Heat	±0.5 %	0.10 %	MIL-STD-202 method 210 (260 °C, 10 s)
Moisture Resistance	±0.5 %	0.10 %	MIL-STD-202 method 106
Shock	±0.5 %	0.10 %	MIL-STD-202 method 213-A
Vibration, High Frequency	±0.5 %	0.05 %	10 to 2000 (Hz)
Life	±1 %	0.30 %	70 °C, Rated Power, 2000 h
Storage Life at Elevated Temperature	±1 %	0.30 %	170 °C, 2000 h
High Temperature Characteristics	±0.5 %	0.05 %	140 °C, 2000 h
Frequency Characteristics	< 5 nH	< 2 nH	Inductance

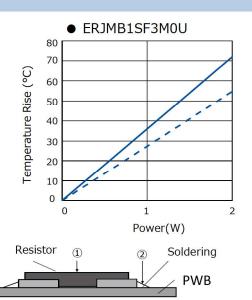
Temperature Rise



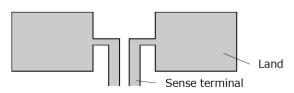
Condition>

Base material : FR-4 (t 1.6 mm)

Copper Thickness : 70 µm, Two layer



Sense terminal-Layout





Current Sensing Resistors, Metal Plate Type

Current Sensing Resistors, Metal Plate Type

Series: ERJ MS6



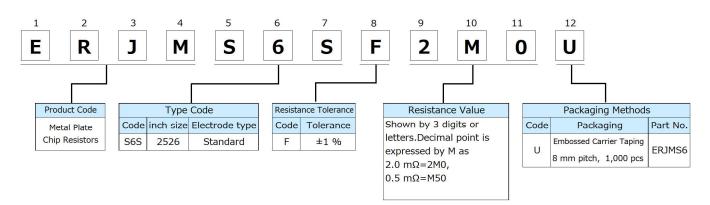
This series is not a recommended product. Not recommended for new design.



Features

- Ideal for current sensing solution
- Small case size with high power
- Metal plate bonding technology. Excellent long term stability
- ullet Outer Resin with high heat dissipation. Wide temperature range (-65 $^{\circ}$ to +170 $^{\circ}$)
- AEC-Q200 compliant
- RoHS compliant
- ISO9001, ISO/TS16949 certified
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers



Ratings

Part No. (inch size)	Power Rating at 70 °C (W)	Resistance Range (mΩ)	Resistance Tolerance (%)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (℃)	Terminal temp. upper limit (℃)
ERJMS6S (2526)	5	0.5, 1, 2	F: ±1	±75	-65 to +170	130

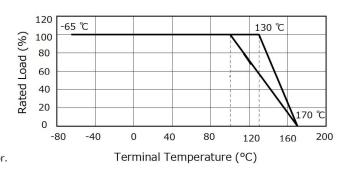
Power Derating Curve

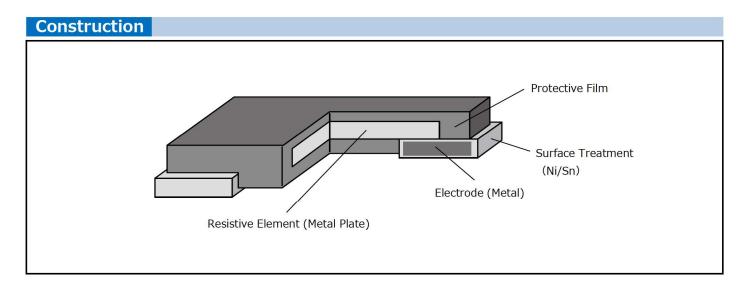
If the terminal temperature of the resistor is more than terminal temperature upper limit value of the rated table, please reduce the rated power according to the Power Derating Curve shown in the figure on the right.

<Supplemented>

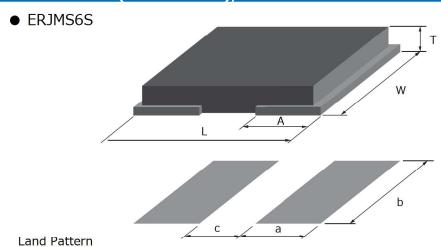
In the case of the temperature measurement of the terminal portion of the resistor, Please perform under the following conditions.

- Terminal temperature measurement, please apply the temperature of the higher of either the left or right electrode upper surface of the resistor.
- 2) Please measure the temperature of the resistor in the land pattern printed of circuit board and plan to use by real conditions.



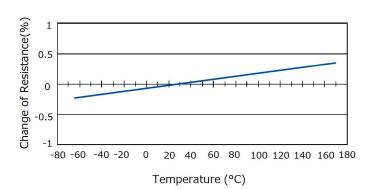


Dimensions in mm (not to scale), Recommended Land Pattern



Part No.	Dimensions (mm)				Recommended Land Pattern (mm)			Mass (Weight)
	L	W	Α	Т	a	b	С	(g/1000 pcs)
ERJMS6S	6.40±0.25	6.80±0.25	2.20±0.25	1.20±0.15	2.7	7	2.0	260

Typical Temp. dependence of electrical resistance





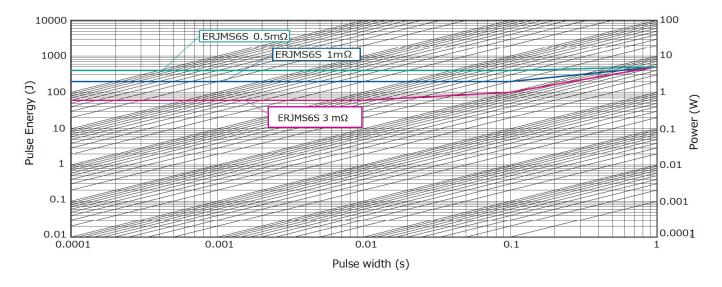
Maximum pulse energy respectively pulse power for continuous operation

Referance Data

Condition: Room Temperature, OFF: 10 s, 1000 cycle, Wave form: Square

Change of Resistance = ±1 %

ERJMS6



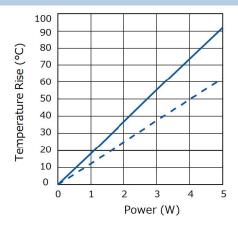
Performance (AEC-Q200)

ERJMS6

Test Item	Performance Requirements ⊿R	Typical value ⊿R	Test Condition
Thermal Shock	±1 %	0.20 %	−55 °C / +155 °C, 1000 cycles
Overload	±0.5 %	0.10 %	Rated Power× 3, 5 s
Solderability	> 95% coverage	> 95% coverage	245 °C, 3 s
Resistance to Solvents	No damage	No damage	MIL-STD-202 method 215, 2.1a, 2.1d
Low Temperature Storage and Operation	±0.5 %	0.03 %	−65 °C, 24 h
Resistance to Soldering Heat	±0.5 %	0.10 %	MIL-STD-202 method 210 (260 °C, 10 s)
Moisture Resistance	±0.5 %	0.10 %	MIL-STD-202 method 106
Shock	±0.5 %	0.10 %	MIL-STD-202 method 213-A
Vibration, High Frequency	±0.5 %	0.05 %	10 to 2000 (Hz)
Life	±1 %	0.30 %	70 °C, Rated Power, 2000 h
Storage Life at Elevated Temperature	±1 %	0.30 %	170 °C, 2000 h
High Temperature Characteristics	±0.5 %	0.05 %	140 °C, 2000 h
Frequency Characteristics	< 5 nH	< 2 nH	Inductance

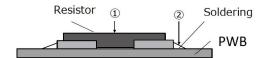
Temperature Rise

ERJMS6SF2M0U

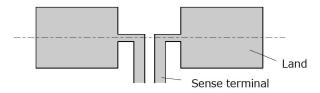


<Condition>
Base material: FR-4 (t 1.6 mm)

Copper Thickness : 70 μm, Two layer



Sense terminal-Layout





Current Sensing Resistors, Metal Plate Type

Current Sensing Resistors, Metal Plate Type



Series: ERJ MP2, MP3, MP4 This series is not recommended for new design.

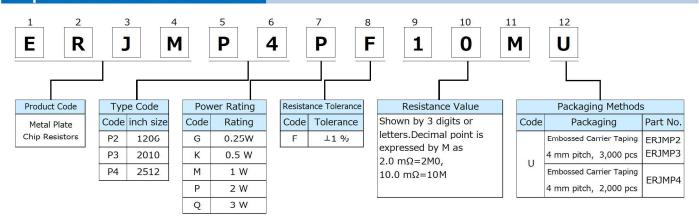
Click here for replacement.

NRFND Replacement
ERJMP2,MP3 ERJMB1
ERJMP4 ERJMS4

Features

- Ideal for current sensing solution
- Small case size with high power
- Metal plate bonding technology. Excellent long term stability
- ullet Outer Resin with high heat dissipation. Wide temperature range (-65 $^{\circ}$ to +170 $^{\circ}$)
- AEC-Q200 compliant
- RoHS compliant
- ISO9001, ISO/TS16949 certified
- As for Packaging Methods, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers



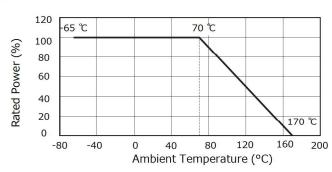
Ratings

Part No. (inch size)	Power Rating at 70 °C (W)	Resistance Range* (mΩ)	Resistance Tolerance (%)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (℃)
ERJMP2G (1206)	0.25				
ERJMP2K (1206)	0.5			F: ±1 ±75	-65 to +170
ERJMP2M (1206)	1				
ERJMP3K (2010)	0.5	1 2 2 5			
ERJMP3M (2010)	1	1, 2, 3, 5,	F: ±1		
ERJMP3P (2010)	2	10, 15			
ERJMP4M (2512)	1				
ERJMP4P (2512)	2				
ERJMP4Q (2512)	3				

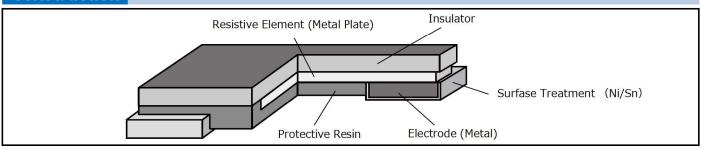
^{*} Please contact us when resistors of irregular series are needed.

Power Derating Curve

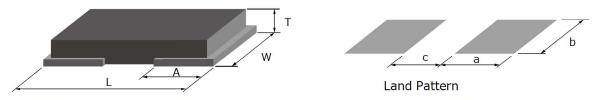
If the ambient terminal temperature of the resistor is more than ambient temperature upper limit value of the rated table, please reduce the rated power according to the Power Derating Curve shown in the figure on the right.



Construction

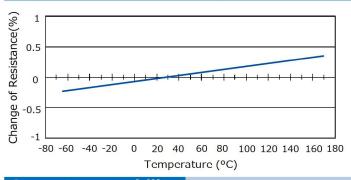


Dimensions in mm (not to scale), Recommended Land Pattern

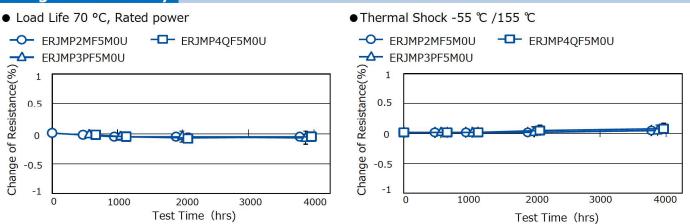


Part No.	Rating Code	Resistance Value (mΩ)		Dimensions (mm)			Recommended Land Pattern (mm)			Mass (Weight)
(inch size)	(IIICIT SIZE)	value (IIIsz)	L	W	А	Т	а	b	С	(g/1000 pcs)
		1		3.20±0.25 1.60±0.25	1.04±0.25	1.00±0.25	1.5	1.8	1.0	
ERJMP2	ERJMP2 G, K, M	2	3 20+0 25		0.64±0.25	1.00±0.25				30
(1206)	G, K, 11	3, 5	3.20-0.23		100.000	0.64±0.25	1.1	1.8	1.8	
		10, 15			0.50±0.25	0101-0120				
ERJMP3	К, М, Р	1	5.00±0.25		1 47+0 25	0.90±0.25	2.1	3.1	1.9	
(2010)		2, 3, 5		2.50±0.25	.25 1.47±0.25	0.64±0.25	2.1	5.1	1.5	70
(2010)		10, 15			0.50±0.25	0.04±0.25	1.3	3.1	3.5	
		1			2.20±0.25	0.90±0.25				
ERJMP4	M, P, Q	2, 3			2.20±0.23	0.74±0.25	3.0	3.4	2.0	100
(2512)		5	6.40±0.25	3.20±0.25	1.20±0.25	0.74±0.23				
(2312)	M, P	10, 15			0.76±0.25	0.64±0.25	2.0	3.4	4.0	
	Q	10, 13				0.83±0.25	2.0	5.4	4.0	

Typical Temperature dependence of electrical resistance



Long-term stability

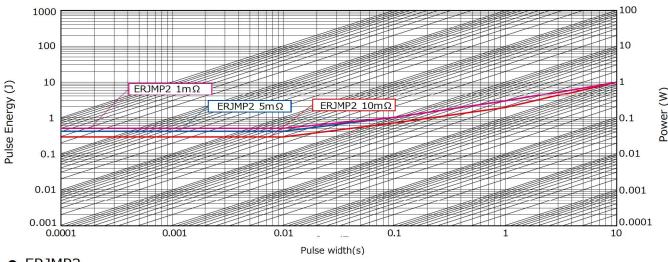


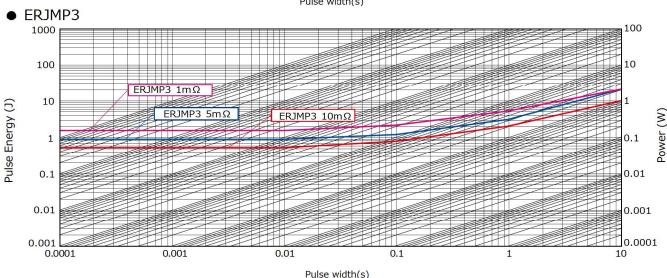
Maximum pulse energy respectively pulse power for continuous operation

Referance Data

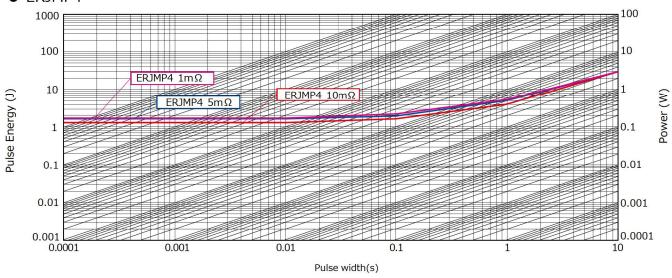
Condition: Room Temperature, OFF: 10 s, 1000 cycle, Wave form: Square, Change of Resistance=±1 %

ERJMP2





ERJMP4



This pulse data is reference characteristic data measured under Panasonic test method and it does not guarantee the performance / characteristics of this product. (The performance / characteristics will change due to the test board, land pattern, amount and type of solder, influence of test equipment and surrounding parts, etc.)

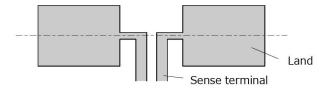
Therefore, please use it after sufficiently confirming its reliability under your using conditions.



Current Sensing Resistors, Metal Plate Type

Performance (AEC-Q200)			
Test Item	Performance Requirements ⊿R	Typical value ⊿R	Test Condition
Thermal Shock	±1 %	0.20 %	-55 °C / +155 °C, 1000 cycles
Overload	±0.5 %	0.10 %	Rated Power× 3, 5 s
Solderability	> 95% coverage	> 95% coverage	245 °C, 3 s
Resistance to Solvents	No damage	No damage	MIL-STD-202 method 215, 2.1a, 2.1d
Low Temperature Storage and Operation	±0.5 %	0.03 %	-65 °C, 24 h
Resistance to Soldering Heat	±0.5 %	0.10 %	MIL-STD-202 method 210 (260 °C, 10 s)
Moisture Resistance	±0.5 %	0.10 %	MIL-STD-202 method 106
Shock	±0.5 %	0.10 %	MIL-STD-202 method 213-A
Vibration, High Frequency	±0.5 %	0.05 %	10 to 2000 (Hz)
Life	±1 %	0.30 %	70 °C, Rated Power, 2000 h
Storage Life at Elevated Temperature	±1 %	0.30 %	170 °C, 2000 h
High Temperature Characteristics	±0.5 %	0.05 %	140 °C, 2000 h
Frequency Characteristics	< 5 nH	< 2 nH	Inductance

Sense terminal-Layout





Current Sensing Resistors, Metal Plate Type

Current Sensing Resistors,

Metal Plate Type

Series: ERJ M1W

This series is not recommended for new design. Click here for replacement.

NRFND

Replacement

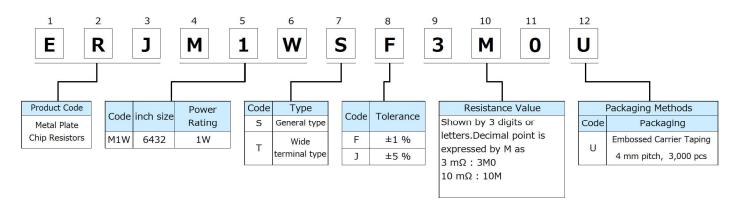
ERJM1W

ERJMS4

Features

- Low resistance values and high precision (1 m Ω to 20 m Ω)
- Stable resistance not influenced by measurement position
- High heat emission
- Low profile, strong body
- Inductance less than 1.0 nH for the metal plate structure
- RoHS compliant
- As for Packaging Methods, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers



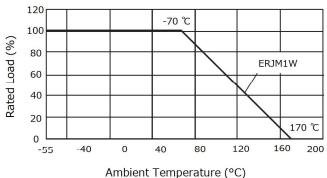
Ratings

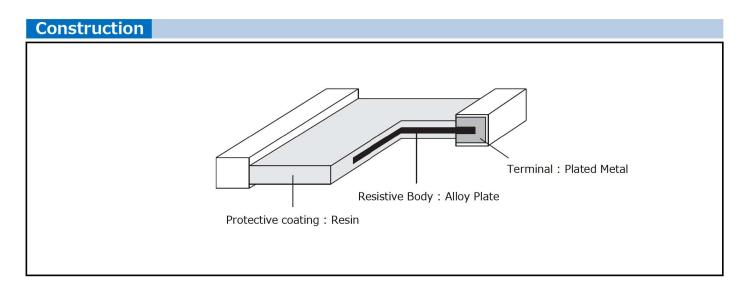
Part No. (inch size)	Power Rating at 70 °C (W)	Standard Resistance (mΩ)	Resistance Tolerance (%)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (℃)	Circuit board of use
ERJM1WS		3, 4		±350		You should use the
(2512)	4	5, 6, 10, 15, 20	F: ±1	±100	-55 ~ +170	aluminum substrate when the added
ERJM1WT	1	1, 1.5	J: ±5	350±100	-55 ~ +1/0	wattage exceeds
(2512)		2, 3, 4		100±50		0.5 W.

^{*} Please contact the factory for other values and the range

Power Derating Curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



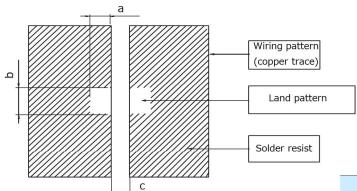


Dimensions in mm (not to scale)

Type	Part No.		Mass (Weight)			
Type	Part No.	L	W	Т	а	(g/1000 pcs)
S Type	ERJM1WS	6.40±0.25	3.20±0.25	0.80±0.30	1.00±0.25	70
Т Туре	ERJM1WT	6.40±0.40	J.ZU±0.Z3	0.60±0.50	2.10±0.30	90

Recommended Land Pattern

An example of a land pattern



Part No.	Dimensions (mm)					
rait NO.	a	b c 3.4 4.2	С			
ERJM1WS	2.1	3.4	4.2			
ERJM1WT	3.1	3.4	2.2			



High Power Chip Resistors / Wide Terminal Type

High Power Chip Resistors / Wide Terminal Type







Series: ERJ A1, B1, B2, B3

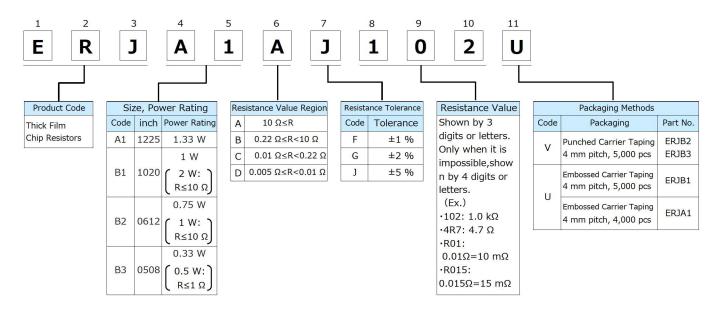
Features

- High solder-joint reliability by wide terminal construction
- Excellent heat dissipation characteristics by wide terminal construction
- AEC-Q200 compliant
- RoHS compliant

Recommended Applications

- Automotive electronic circuits including ECUs (Electrical control unit), anti-lock breaking systems and air-bag systems.
- Current sensing for power supply circuits in a variety of equipment.
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions,
 Please see Data Files

Explanation of Part Numbers



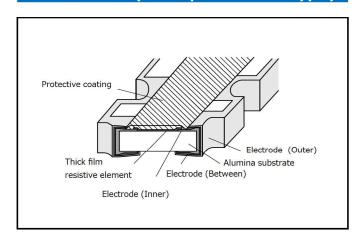


Ratings

Part No. (inch size)	Power Rating at 70 °C ⁽¹⁾ (W)	Limiting Element Voltage ⁽²⁾ (V)	Maximum Overload Voltage ⁽³⁾ (V)	Resistance Tolerance (%)	Resistance Range (Ω)	е	T.C.R. (×10 ⁻⁶ /k	()	Category Temperature Range (°C)	AEC- Q200 Grade
ERJA1				±1	100 m to 10 k	(E24)	±100			
(1225)	1.33	200	400	±2, ±5	10 m to 10 k	(E24)	R<100mΩ 100mΩ≤R	: ±350 : ±200		Grade 0
ERJB1	1	200	400	±1	10 m to 10 k	(E24)	22mΩ ≤R< 47mΩ	: 0 to +350 : 0 to +200 : 0 to +150 : ±100	-55 to +155	Grade 0
(1020) 2(R	2(R ≤ 10 Ω))		±2, ±5	10 m to 10 k	(E24)	$R < 22m\Omega$ $22m\Omega \le R < 100m\Omega$ $100m\Omega \le R$: 0 to +350 : 0 to +200 : ±200		
ERJB2 (0612)	0.75 1(R ≤ 10 Ω)	200	400	±1		(E24)	$22m\Omega \le R < 47m\Omega$ $47m\Omega \le R < 100m\Omega$ $100m\Omega \le R < 220m\Omega$ $220m\Omega \le R$: 0 to +150 : 0 to +100 : ±100		Grade 0
(0012)	I(K ≤ 10 Ω)			±2 ±5	5 m, 6 m,	(E24)	22mΩ ≤R< 47mΩ 47mΩ <r<100mω< td=""><td>: 0 to +300 : 0 to +200 : 0 to +150 : 0 to +200 : ±200</td><td>Stade 0</td></r<100mω<>	: 0 to +300 : 0 to +200 : 0 to +150 : 0 to +200 : ±200		Stade 0
ERJB3 (0508)	0.33 0.5(R ≤ 1 Ω)	150	200	±1	20 m to 10	(E24)	$R < 47m\Omega$ $47m\Omega \le R < 1\Omega$ $1\Omega \le R$ $R < 47m\Omega$: 0 to +300 : 0 to +200 : ±100 : 0 to +300		Grade 0
					20 m to 10	(E24)	47mΩ ≤R< 1Ω $1Ω ≤R$: 0 to +200 : ±200		

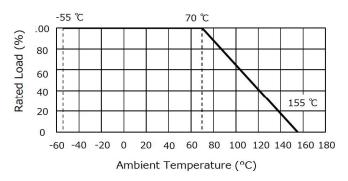
- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Construction (Example : ERJA1 type)



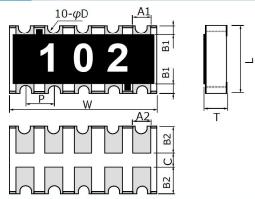
Power Derating Curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure below.

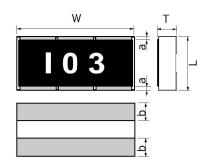




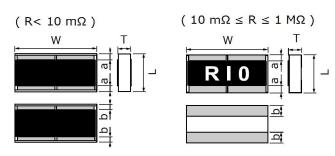
Dimensions in mm (not to scale)



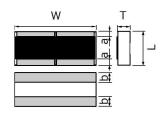
Part No.	Dimensions (mm)						
Part NO.	L	W	Т	A ₁	B ₁	(g/1000 pcs)	
-	3.20±0.20	6.40±0.20	0.55±0.10	0.70±0.20	0.45±0.20		
ERJA1	A ₂	B ₂	Р	φD	С	40	
	0.70±0.20	1.25±0.15	1.27±0.10	0.30+0.10/-0.20	0.4 min.		



Part No.		Dimensions (mm)						
rait No.	L	W	Т	a	b	(g/1000 pcs)		
ERJB1	2.50±0.20	5.00±0.20	0.55±0.20	0.25±0.20	0.90±0.20	27		



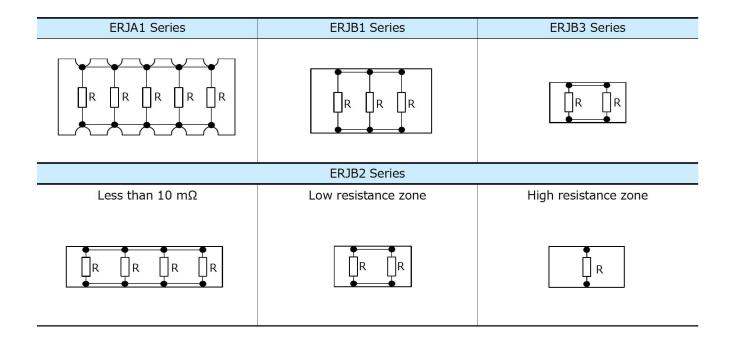
Part No.	Dimensions (mm)					
ERJB2	L	W	Т	a	b	(g/1000 pcs)
5 mΩ≤R< 10 mΩ			0.65±0.15	0.30±0.20	0.30±0.20	
10 mΩ≤R<220 mΩ	1.60±0.15	3.20±0.20	0.55±0.15	0.30±0.20	0.50±0.20	11
220 mΩ≤R≤ 1 MΩ			0.55±0.15	0.25±0.20	0.50±0.20	



Part No.	Dimensions (mm)					
Pait NO.	L	W	Т	a	b	(g/1000 pcs)
ERJB3	1.25±0.10	2.00±0.15	0.50±0.10	0.25±0.20	0.40±0.20	4.8



Circuit Configuration



Test Item	Performance Requirements ⊿R	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C
Overload	±2 %	$ \begin{array}{llllllllllllllllllllllllllllllllllll$
Resistance to Soldering Heat	±1 %	270 °C, 10 s
Rapid Change of Temperature	±2 %	-55 °C (30 min.) / +125 °C(30 min.), 1000 cycles
High Temperature Exposure	±1 %	+155 °C, 1000 h
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h
Load Life in Humidity	±3 %	60 °C, 90 % to 95 %RH, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 °C	±3 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h



Low TCR High Power Chip Resistors / Wide Terminal Type

.010



Series: ERJ D1, D2

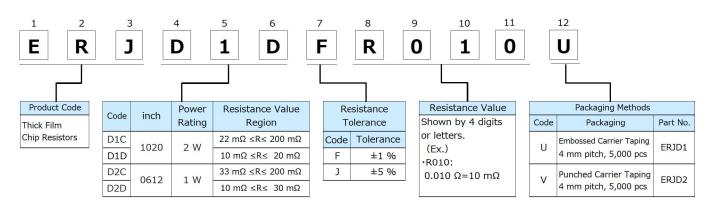
Features

- ullet Achieved High power and low TCR ($\pm 100 \times 10^{-6}$ /K) using wide terminal electrode structure and original material
- Suitable for small size/high power current detection (Low TCR enables high accuracy of current detection)
- High solder-joint reliability by wide terminal construction
- Excellent heat dissipation characteristics by wide terminal construction
- AEC-Q200 compliant
- RoHS compliant

Recommended Applications

- Automotive electronic circuits including ECUs (Electrical control unit), anti-lock breaking systems and air-bag systems.
- Current sensing for power supply circuits in a variety of equipment.
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers



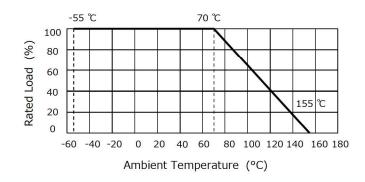
Ratings

Part No. (inch size)	Power Rating at 70 °C (1) (W)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (℃)	AEC- Q200 Grade
ERJD1 (1020)	2	±1, ±5	10 m to 200 m (E24)	±100	55 to 1155	Crado 0
ERJD2 (0612)	1	±1, ±5	10 m to 200 m (E24)	±100	-55 to +155	Grade 0

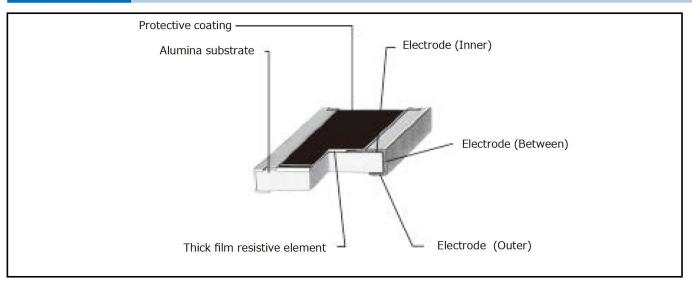
- (1) Use it on the condition that the case temperature is below the upper category temperature.
 - · Please contact us when resistors of irregular series are needed.
 - Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\(Power Rating \times Resistance Value. \)
 - · Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV.

Power Derating Curve

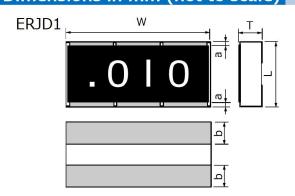
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.

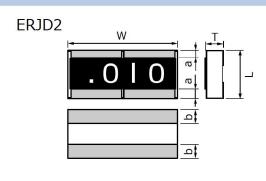


Construction



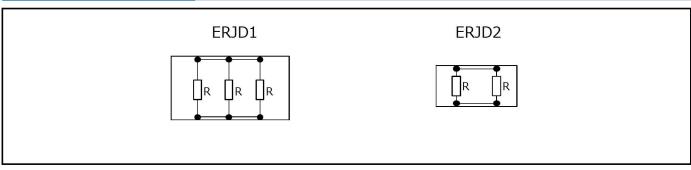
Dimensions in mm (not to scale)





Part No.	Dimensions (mm)					
Part No.	L W		Т	a	b	(g/1000 pcs)
ERJD1	2.50±0.20	5.00±0.20	0.60±0.20	0.30±0.20	0.90±0.20	27
ERJD2	1.60±0.15	3.20±0.20	0.65±0.15	0.30±0.20	0.50±0.20	11

Circuit Configuration





Test Item	Performance Requirements ⊿R	Test Conditions		
Resistance	Within Specified Tolerance	20 °C		
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C		
Overload	±2 %	Rated Voltag× 2.0 , 5 s		
Resistance to Soldering Heat	±1 %	270 °C, 10 s		
Rapid Change of Temperature	±2 %	-55 °C (30 min.) / +125 °C(30 min.), 1000 cycles		
High Temperature Exposure	±1 %	+155 °C, 1000 h		
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h		
Load Life in Humidity ±3 %		60 °C, 90 % to 95 %RH, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h		
Endurance at 70 °C	±3 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h		



Current Sensing Resistors, Metal Foil Type

Current Sensing Resistors, Metal Foil Type

Series: ERJ MFBA

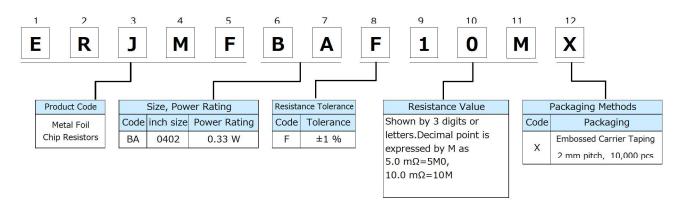


This series is not a recommended product. Not recommended for new design.

Features

- Suitable for current sensing for smartphones and other small devices
- Unique metal foil process achieved high power and low temperature coefficient
- RoHS compliant
- ISO9001 certified
- As for Packaging Methods, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers



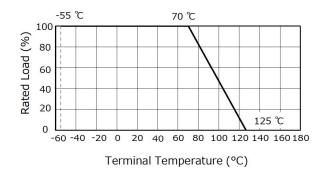
Ratings

Part No. (inch size)	Power Rating at 70 °C (W)	Resistance Range* (mΩ)	Resistance Tolerance (%)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (℃)
ERJMFBA (0402)	0.33	5, 10, 20	F: ±1	±150	-55 to +125

^{*} Use it on the condition that the case temperature is below 125 °C.

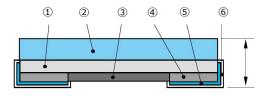
Power Derating Curve

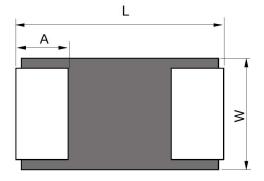
If the ambient temperature of the resistor is more than ambient temperature upper limit value of the rated table, please reduce the rated power according to the Power Derating Curve shown in the figure on the right.

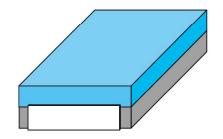




Construction, Dimensions in mm (not to scale)



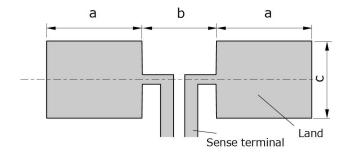




	Name				
1	Resistive element				
2	Base material				
3	Protective Resin				
4	Electrode (Inner)				
(5)	Electrode (Between)				
6	Electrode (Outer)				

	Part No.	Mass (Weight)				
Part No.	L	W	А	t	(g/1000 pcs)	
	ERJMFBA	1.00±0.10	0.56±0.10	0.25±0.10	0.30±0.10	0.73

Recommended Land Pattern, Sense terminal-Layout



Part No.	Recommended Land Pattern (mm)				
Part No.	a	b	С		
ERJMFBA	0.40	0.50	0.50		

Test Item	Performance Requirements ⊿R	Typical value ⊿R	Test Condition
Thermal Shock	±2 %	0.20 %	-55 °C / +125 °C, 5 cycles
Overload	±2 %	0.20 %	Rated Power× 3, 5 s
Solderability	> 95% coverage	> 95% coverage	245 °C, 3 s
Resistance to Solvents	No damage	No damage	MIL-STD-202 method 215, 2.1a, 2.1d
Low Temperature Storage and Operation	±1 %	0.10 %	−65 °C, 24 h
Resistance to Soldering Heat	±1 %	0.10 %	MIL-STD-202 method 210 (260 °C, 10 s)
Moisture Resistance	±1 %	0.10 %	MIL-STD-202 method 106
Shock	±1 %	0.10 %	MIL-STD-202 method 213-A
Vibration, High Frequency	±1 %	0.10 %	10 to 2000 (Hz)
Life	±3 %	0.30 %	70 °C, Rated Power, 1000 h
Storage Life at Elevated Temperature	±1 %	0.10 %	125 °C, 1000 h
Frequency Characteristics	< 5 nH	< 2 nH	Inductance



Anti-Surge Thick Film Chip Resistors

Anti-Surge Thick Film Chip Resistors



Series: ERJ PA2, P03, PA3, P06, P08, P14

Features

- ESD surge characteristics superior to standard metal film resistors
- High reliability...Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- High power… 0.20 W: 0402 inch / 1005 mm size (ERJPA2), 0603 inch / 1608 mm size (ERJP03)

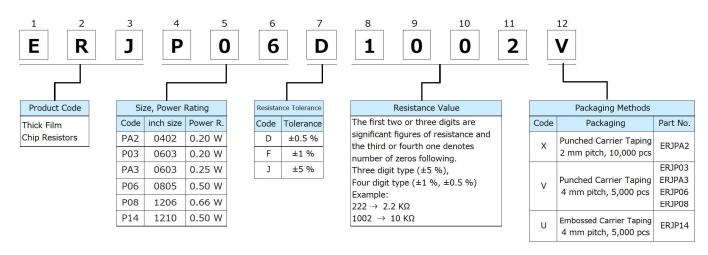
0.25 W: 0603 inch / 1608 mm size (ERJPA3)

0.50 W: 0805 inch / 2012 mm size (ERJP06), 1210 inch / 3225 mm size (ERJP14)

0.66 W: 1206 inch / 3216 mm size (ERJP08)

- Reference Standard · · · IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers



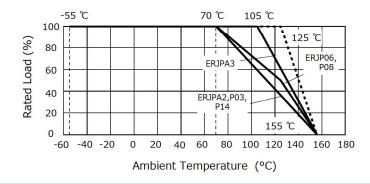
Ra	ti.	n	a	C
/C	L	ш	ч	9

Part No. (inch size)	Power Rating at 70 °C (1) (W)	Limiting Element Voltage ⁽²⁾ (V)	Maximum Overload Voltage ⁽³⁾ (V)	Resistance Tolerance (%)	Rai	tance nge Ω)		C.R. D ⁻⁶ /K)	Category Temperature Range (°C)	AEC-Q200 Grade
ERJPA2	0.20	50	100	±0.5, ±1	10 to 1 M	(E24, E96)	±	100		Grade 1
(0402)	0.20	30	100	±5	10 to 1 M	(E24)	±2	200		Orduc 1
				±0.5	10 to 1 M	(E24, E96)	±	150		
ERJP03	0.20	150	200	±1	10 to 1 M	(E24, E96)	±2	200		Grade 0
(0603)	0.20	130	200	±5	1 to 1 M	(E24)	R<10Ω	: -150 to +400		Grade 0
				Ξ3	1 10 1 14	(24)	10Ω≤R	; ⊥200		
ERJPA3	0.25	150	200	±0.5, ±1	10 to 1 M	(E24, E96)	±	100		Grade 0
(0603)	(105 ℃)	130	200	±5	1 to 1.5 M	1 to 1.5 M (E24)		±200		Graue 0
				105 11	10 to 1 M	(F24 F0C)	R<33Ω	: ±300		
ED 100 C				±0.5, ±1	10 to 1 M	(E24, E96)	33Ω≤R	: ±100	-55 ~ +155	
ERJP06 (0805)	0.50	400	600				R<10Ω	: -100 to +600		Grade 0
(0003)				±5	1 to 3.3 M	(E24)	10Ω≤R<33Ω	: ±300		
							33Ω≤R	: ±200		
				±0.5, ±1	10 to 1 M	(E24, E96)	±	100		·
ERJP08 (1206)	0.66	500	1000		1 t- 10 M	(524)	R<10Ω	: -100 to +600		Grade 0
(1206)				±5	1 to 10 M	(E24)	10Ω≤R	: ±200		
				±0.5, ±1	10 to 1 M	(E24, E96)	±	100		
ERJP14	0.50	200	400			(50.4)	R<10Ω	: -100 to +600		Grade 0
(1210)				±5	1 to 1 M	to 1 M (E24)	10Ω≤R	: ±200		

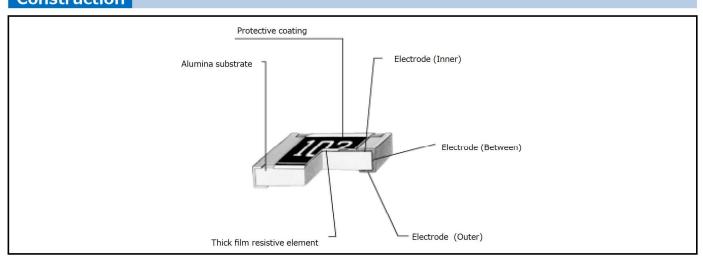
- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) \times RCWV or Maximum Overload Voltage listed above, whichever less.

Power Derating Curve

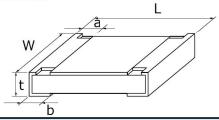
For resistors operated in rated temperatures above 70 °C or 105 °C, power rating shall be derated in accordance with the figure on the right. * When the temperature of ERJP14 is 155 °C or less, the derating start temperature can be changed to 125 °C. (See the dotted line)



Construction

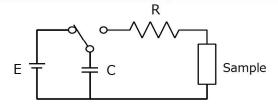


Dimensions in mm (not to scale)



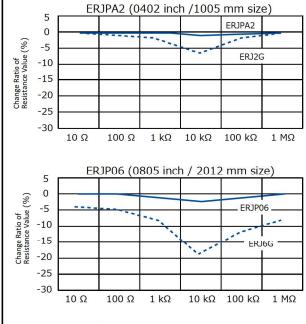
Part No.	Dimensions (mm)					Mass (Weight)
Ture Ho.	L	W	a	b	t	(g/1000 pcs)
ERJPA2	1.00±0.05	0.50±0.05	0.20±0.15	0.25±0.05	0.35±0.05	0.8
ERJP03	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.30±0.15	0.45±0.10	2
ERJPA3	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.25±0.10	0.45±0.10	2
ERJP06	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4
ERJP08	3.20+0.05/-0.20	1.60+0.05/-0.15	0.40±0.20	0.50±0.20	0.60±0.10	10
ERJP14	3.20±0.20	2.50±0.20	0.35±0.20	0.50±0.20	0.60±0.10	16

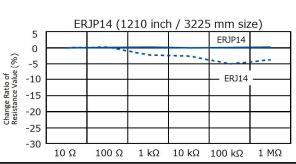
ESD Characteristic

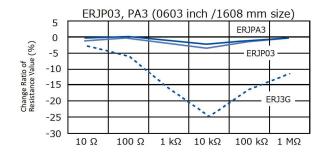


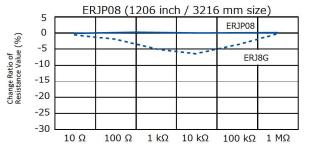
Size (inch)	0402	0603, 0805, 1206, 1210
R	1.5 kΩ	R=0 Ω(≤1.5 kΩ) / 150 Ω(>1.5 kΩ)
С	100 pF	150 pF
Е	±1 kV	±3 kV

Anti-Surge Thick Film Chip Resistors (ERJP Series)
Thick Film Chip Resistors (ERJ Series)









**This data is for reference purposes.
Please check with the actual equipment before use.



Anti-Surge Thick Film Chip Resistors

Test Item	Performance Requirements ⊿R	Test Conditions		
Resistance	Within Specified Tolerance	20 °C		
T. C. R.	Within Specified T. C. R.	+25 °C/+155 °C (ERJPA2 : +125 °C)		
		ERJP06 : Rated Voltag× 1.77, 5 s		
Overload	$\pm 2\%$ Only when it is ERJP03 (D), P14 (D): $\pm 0.5\%$	ERJPA2, ERJPA3, ERJP08: Rated Voltag× 2.0, 5 s		
	Only When it is Elon 03 (5), 114 (5) : 10.3 %	ERJP03, ERJP14 : Rated Voltag× 2.5 , 5 s		
Resistance to	D: ±0.5 %, F, J: ±1 %	270 °C, 10 s		
Soldering Heat	D: 20.3 70, 1, 3: 21 70			
Rapid Change of	±1 %	-55 °C (30min.) / +155 °C (ERJPA2 : +125 °C) (30min.),		
Temperature	-1 //	100 cycles		
High Temperature	±1 %	+155 °C, 1000 h		
Exposure	-1 /0			
Damp Heat, Steady	±1 %	60 °C, 90 % to 95 %RH, 1000 h		
State	=1 /0	00 C, 50 70 to 55 701(11, 1000 11		
Load Life in Humidity	±3 %	60 °C, 90 % to 95 %RH, Rated Voltage,		
Load Life in Humidity	Only when it is ERJP03 (D), P14 (D): ±1 %	1.5 h ON / 0.5 h OFF cycle, 1000 h		
Endurance at 70 °C	±3 %	70 °C (ERJPA3 : +105 °C), Rated Voltage,		
(ERJPA3 : 105 °C)	Only when it is ERJP03 (D), P14 (D) : ± 1 %	1.5 h ON / 0.5 h OFF cycle, 1000 h		



Anti-Pulse Thick Film Chip Resistors

Anti-Pulse Thick Film Chip Resistors









Series: ERJ T06, T08, T14

ERJ T14L

Features

Anti-Pulse characteristics
 High pulse characteristics achieved by the optimized trimming specifications (ERJT06, T08, T14)

- Further high pulse characteristics achieved by trimming-less specifications (ERJT14L)
- High reliability ····· Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- High power 0.25 W: 0805 inch /2012 mm size (ERJT06)

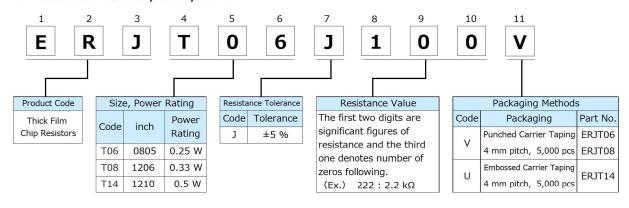
0.33 W: 1206 inch /3216 mm size (ERJT08)

0.50 W: 1210 inch /3225 mm size (ERJT14, ERJT14L)

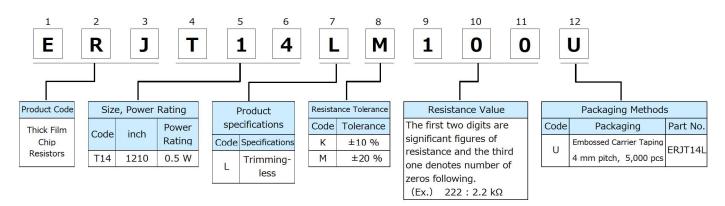
- Reference Standard ··· IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers

Series ERJT06, T08, T14



Series ERJT14L



* Please contact us for 0805 (inch) and 1206 (inch) size trimming-less types.

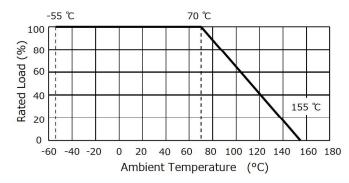
\mathbf{D}	+i			
Ka	ш	ш	u	

Part No. (inch size)	Power Rating at 70 °C (1) (W)	Limiting Element Voltage ⁽²⁾ (V)	Maximum Overload Voltage ⁽³⁾ (V)	Resistance Tolerance (%)	Resista Ran (Ω	ge	T.C.R. (×10 ⁻⁶ /K)		Category Temperature Range (°C)	AEC- Q200 Grade
ERJT06 (0805)	0.25	150	200	±5	1 to 1 M	(E24)	R<10 Ω 10 Ω≤R<33 33 Ω≤R	: $-100 \text{ to } +600$ Ω : ± 300 : ± 200	-55 to +155	Grade 0
ERJT08 (1206)	0.33	200	400	±5	1 to 1 M	(E24)	R<10 Ω 10 Ω≤R	: -100 to +600 : ±200	-55 to +155	Grade 0
ERJT14 (1210)	0.50	200	400	±5	1 to 1 M	(E24)	R<10 Ω 10 Ω≤R	: -100 to +600 : ±200	-55 to +155	Grade 0
ERJT14L (1210)	0.50	200	400	±10 ±20	1 to 1 M	(E12)	R<10 Ω 10 Ω≤R	: -100 to +600 : ±200	-55 to +155	Grade 0

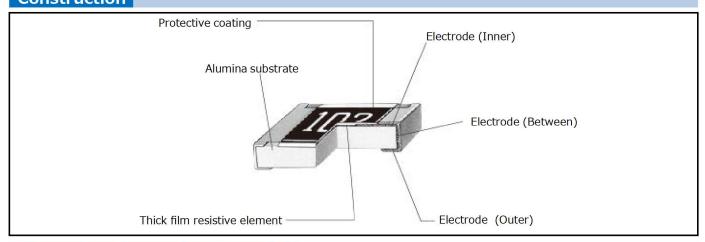
- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Power Derating Curve

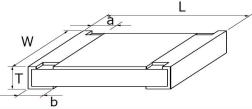
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



Construction



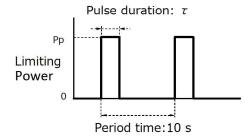
Dimensions in mm (not to scale)



Dart No	Dimensions (mm)								
Part No.	L W		L W a b		b	Т	(g/1000 pcs)		
ERJT06	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4			
ERJT08	3.20+0.05/-0.20	1.60+0.05/-0.15	0.40±0.20	0.50±0.20	0.60±0.10	10			
ERJT14 ERJT14L	3.20±0.20	2.50±0.20	0.35±0.20	0.50±0.20	0.60±0.10	16			

Limiting Power Curve

• In rush pulse Characteristic



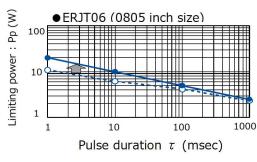
Test cycle: 1000 cycles

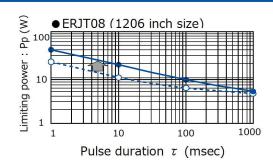
Spec : Resistance value = within $\pm 5 \%$

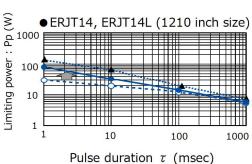
▲: Anti-Pulse Thick Film Chip Resistors (Series ERJT14L)

• : Anti-Pulse Thick Film Chip Resistors (Series ERJT)

 \bigcirc : Thick Film Chip Resistors (Series ERJ : 1 Ω)







- %This data is for reference purposes.
 Please check with the actual equipment before use.
- Please contact us for 0805 (inch) and 1206 (inch) size trimming-less types.

Test Item	Performance Requirements ⊿R	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C/+155 °C
Overload	±2 %	Rated Voltage× 2.5, 5 s
Resistance to Soldering Heat	±1 %	270 °C±3 °C, 10 s ±1 s
Rapid Change of Temperature	±1 %	-55 °C (30 min.) / +155 °C (30 min.), 100 cycles
High Temperature Exposure	±1 %	+155 °C, 1000 h
Damp Heat, Steady State	±1 %	60 °C ±2 °C, 90 % to 95 %RH, 1000 h
Load Life in Humidity	±3 %	60 °C ± 2 °C, 90 % to 95 %RH, Rated Voltage , 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 °C	±3 %	70 °C \pm 2 °C, Rated Voltage , 1.5 h ON / 0.5 h OFF cycle, 1000 h



Anti-Sulfurated Thick Film Chip Resistors

Anti-Sulfurated Thick Film Chip Resistors

102 102 102

ERJ S (Au-based inner electrode type)

Series: ERJ S02, S03, S06, S08, S14, S12, S1D, S1T

ERJ U (Ag-Pd-based inner electrode type)

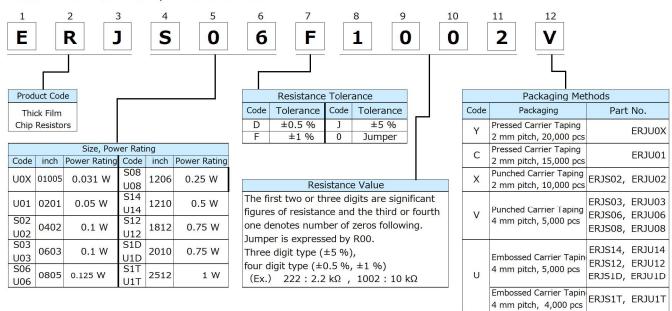
Series: ERJ U0X, U01, U02, U03, U06, U08, U14, U12, U1D, U1T, U6S, U6Q

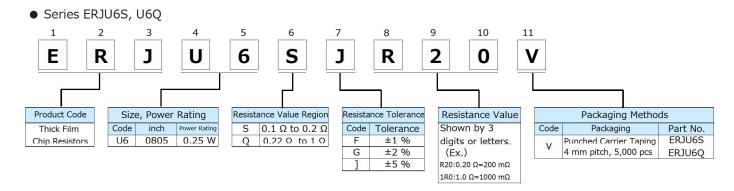
Features

- High resistance to sulfurization achieved by adopting an Au-based inner electrode (Series ERJS) and Ag-Pd-based inner electrode (Series ERJU)
- High reliability...Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- \bullet Low Resistance type ···Series ERJU6S, U6Q : 0.1 Ω to 1 Ω
- Reference Standard ··· IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant (except ERJU0X, ERJU01)
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers

Series ERJS02 to ERJS1T, ERJU0X to ERJU1T





Rat	ings								
Part No. (inch size)	Power Rating at 70 °C ⁽¹⁾ (W)	Limiting Element Voltage ⁽²⁾ (V)	Maximum Overload Voltage ⁽³⁾ (V)	Resistance Tolerance (%)	Ra	stance nge Ω)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (°C)	AEC- Q200 Grade
ERJU0X (01005)	0.031	15	30	±1 ±5	10 to 1 M	(E24, E96) (E24)	R<10 Ω : -100 to +600 10 Ω≤R<100 Ω : ±300 100 Ω≤R : ±200	-55 to +125	2
ERJU01 (0201)	0.05	25	50	±1 ±5	10 to 1 M 1 to 1 M	(E24, E96) (E24)	R<10 Ω: -100 to +600	-55 to +125	-
ERJS02 ERJU02 (0402)	0.1	50	100	±0.5, ±1 ±5	1 to 1 M 1 to 3.3 M	(,,	10 Ω to 1 M Ω : ±200 1 M Ω <r :<br="">-400 to +150</r>	-55 to +155	Grade 0
ERJS03 ERJU03 (0603)	0.1	75	150	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)		-55 to +155	Grade 0
ERJS06 ERJU06 (0805)	0.125	150	200	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)	R<10 Ω :	-55 to +155	Grade 0
ERJS08 ERJU08 (1206)	0.25	200	400	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)	-100 to +600	-55 to +155	Grade 0
ERJS14 ERJU14 (1210)	0.5	200	400	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)	10 Ω to 1 M Ω : ±200 (± 5 %) ±100 (±0.5 %, ±1 %)	-55 to +155	Grade 0
ERJS12 ERJU12 (1812)	0.75	200	500	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)	1 MΩ <r :<="" td=""><td>-55 to +155</td><td>Grade 0</td></r>	-55 to +155	Grade 0
ERJS1D ERJU1D (2010)	0.75	200	500	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)	-400 to +150	-55 to +155	Grade 0
ERJS1T ERJU1T (2512)	1.0	200	500	±0.5, ±1 ±5	1 to 1 M 1 to 10 M	(E24, E96) (E24)		-55 to +155	Grade 0

- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

[Low Resistance type]

Part No. (inch size)	Power Rating at 70 °C (1) (W)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (℃)	AEC- Q200 Grade
ERJU6S (0805)	0.25	±1 ±2 ±5	0.1 to 0.2 (E24)	0 to +150	-55 to +155	Grade 0
ERJU6Q (0805)	0.25	±1, ±2, ±5	0.22 to 1 (E24)	0 (0 +150	-55 (0 +155	Grade 0

- (1) Use it on the condition that the case temperature is below the upper category temperature.
 - Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=\(\sqrt{Power Rating} \times \text{Resistance Value.}\)
 - · Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

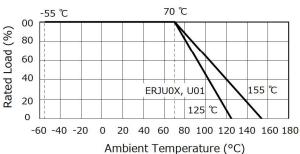
[For Jumper]

ti oi suilipe				
Part No.	Resistance(Ω)	Rated Current(A)	Maximum Overload Current (A) ⁽¹⁾	
ERJU0X		0.5	1	
ERJU01				
ERJS02 ERJU02		1	2	
ERJS03 ERJU03				
ERJS06 ERJU06	100 mΩ or less			
ERJS08 ERJU08	100 11112 01 1635			
ERJS14 ERJU14		2	4	
ERJS12 ERJU12		_		
ERJS1D ERJU1D				
ERJS1T ERJU1T				

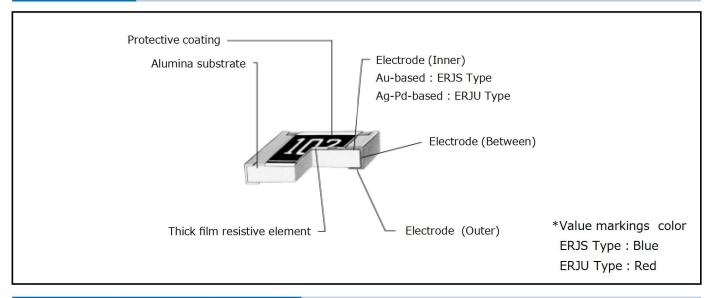
(1) Overload test current

Power Derating Curve

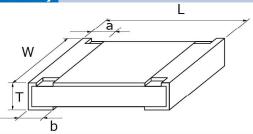
For resistors operated in ambient temperatures above 70 $^{\circ}$ C, power rating shall be derated in accordance with the figure below.



Construction



Dimensions in mm (not to scale)



Part No.	Dimensions (mm)									
Part No.	L	W	a	b	T	(g/1000 pcs)				
ERJU0X	0.40±0.02	0.20±0.02	0.10±0.03	0.10±0.03	0.13±0.02	0.04				
ERJU01	0.60±0.03	0.30±0.03	0.10±0.05	0.15±0.05	0.23±0.03	0.15				
ERJS02 ERJU02	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.10	0.35±0.05	0.8				
ERJS03 ERJU03	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2				
ERJS06 ERJU06	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4				
ERJU6□	2.00±0.20	1.25±0.10	0.45±0.20	0.45±0.20	0.55±0.10	6				
ERJS08 ERJU08	3.20+0.05/-0.20	1.60+0.05/-0.15	0.50±0.20	0.50±0.20	0.60±0.10	10				
ERJS14 ERJU14	3.20±0.20	2.50±0.20	0.50±0.20	0.50±0.20	0.60±0.10	16				
ERJS12 ERJU12	4.50±0.20	3.20±0.20	0.50±0.20	0.50±0.20	0.60±0.10	27				
ERJS1D ERJU1D	5.00±0.20	2.50±0.20	0.60±0.20	0.60±0.20	0.60±0.10	27				
ERJS1T ERJU1T	6.40±0.20	3.20±0.20	0.65±0.20	0.60±0.20	0.60±0.10	45				

Performance

• Series ERJS02 to ERJS1T, ERJU0X to ERJU1T

Test Item	Performance Re	equirements ⊿R	Test Conditions			
rest Item	Resistor type	Jumper type	rest conditions			
Resistance	Within Specified	100 mΩ or less	20 °C			
Resistance	Tolerance	100 11132 01 1655	20 °C			
T. C. R.	Within Specified	200 mΩ or less	+25 °C/+155 °C (ERJU0X,U01 : +25 °C/+125 °C)			
1. C. N.	T. C. R.		+23 C/+133 C (LK300X,001 : +23 C/+123 C)			
Overload	±2 %	100 mΩ or less	Rated Voltage× 2.5, 5 s			
Overload	12 70	100 11132 01 1633	Jumper type : Max. Overload Current, 5 s			
Resistance to	±1 %	100 mΩ or less	270 °C, 10 s			
Soldering Heat	±1 /0	100 11132 01 1633	270 C, 10 S			
Rapid Change of	±1 %	100 mΩ or less	-55 °C (30min.)/+155 °C (ERJU0X,U01 : +125 °C)			
Temperature	11 /0	100 11132 01 1633	(30min.), 100 cycles			
High Temperature	±1 %	100 mΩ or less	+155 °C (ERJU0X,U01 : +125 °C), 1000 h			
Exposure	<u> </u>	100 11132 01 1033	+133 C (LR300X,001 : +123 C), 1000 II			
Damp Heat, Steady	±1 %	100 mΩ or less	60 °C, 90 % to 95 %RH, 1000 h			
State	-1 /0	100 11112 01 1000	00° C, 50° 70° C0° 55° 761K11, 1000° 11			
Load Life in Humidity	±3 %	100 mΩ or less	60 °C, 90 % to 95 %RH, Rated Voltage (Jumper type :			
Load Life in Hamilaity	±5 70	100 1132 01 1033	Rated Current) , 1.5 h ON / 0.5 h OFF cycle, 1000 h			
Endurance at 70 °C	±3 %	100 mΩ or less	70 °C, Rated Voltage (Jumper type :Rated Current),			
Lindulatice at 70 °C	±3 70	100 HIS OF 1622	1.5 h ON / 0.5 h OFF cycle, 1000 h			

• Series ERJU6S, U6Q

Test Item	Performance Requirements ⊿R	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C
Overload	±1 %	Rated Voltage× 2.5, 5 s
Resistance to Soldering Heat	±1 %	270 °C, 10 s
Rapid Change of Temperature	±1 %	-55 °C (30 min.) / +125 °C(30min.), 100 cycles
High Temperature Exposure	±1 %	+155 °C, 1000 h
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h
Load Life in Humidity	±3 %	60 °C, 90 % to 95 %RH, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 70 °C	±3 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h



Anti-Sulfurated Thick Film Chip Resistors/Precision Type

Anti-Sulfurated Thick Film Chip Resistors / Precision Type







Series: ERJ U2R, U3R, U6R

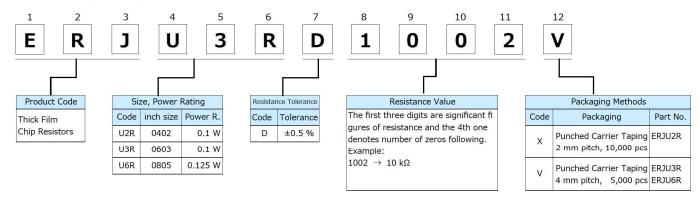
(Ag-Pd-based inner electrode type)

Features

- High resistance to sulfurization achieved by adopting an Ag-Pd-based inner electrode.
- High precision ··· Resistance tolerance : ± 0.5 %, TCR : $\pm 50 \times 10^{-6}$ /K
- High reliability ··· Metal glaze thick film resistive element and three layers of electrodes.
- Suitable for both reflow and flow soldering.
- Reference Standard ··· IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers

ERJU2R, U3R, U6R Series



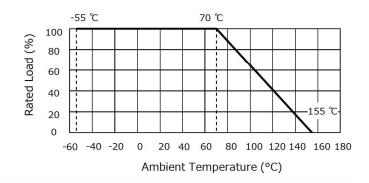
Ratings

Part No. (inch size)	Power Rating at 70 °C ⁽¹⁾ (W)	Limiting Element Voltage ⁽²⁾ (V)	Maximum Overload Voltage ⁽³⁾ (V)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (℃)	AEC- Q200 Grade
ERJU2R (0402)	0.1	50	100	±0.5	100 to 100 k (E24, E96)		-55 to +155	Grade 0
ERJU3R (0603)	0.1	50	100	±0.5	100 to 100 k (E24, E96)	±50	-55 to +155	Grade 0
ERJU6R (0805)	0.125	150	200	±0.5	100 to 100 k (E24, E96)		-55 to +155	Grade 0

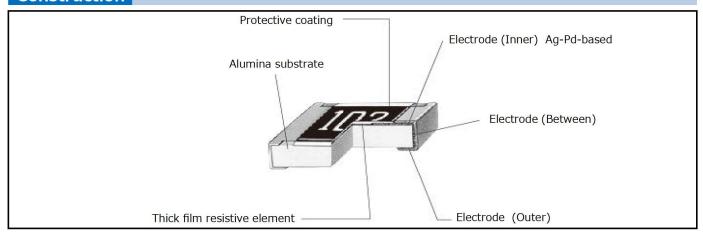
- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Power Derating Curve

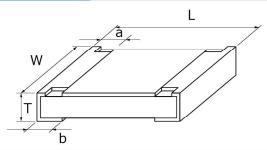
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



Construction



Dimensions in mm (not to scale)



Part No.	Dimensions (mm)								
Part No.	L	L W a b		b	Т	(g/1000 pcs)			
ERJU2R	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.10	0.35±0.05	0.8			
ERJU3R	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2			
ERJU6R	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4			

Test Item Performa Requireme		Test Conditions		
Resistance	Within Specified Tolerance	20 °C		
T. C. R.	Within Specified T. C. R.	+25 °C/+155 °C		
Overload	±2 %	Rated Voltage × 2.5, 5 s		
Resistance to Soldering Heat	±1 %	270 °C, 10 s		
Rapid Change of Temperature	±1 %	-55 °C (30 min.) / +155 °C(30 min.), 100 cycles		
High Temperature Exposure	±1 %	+155 °C, 1000 h		
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h		
Load Life in Humidity	±2 %	60 °C, 90 % to 95 %RH, Rated Voltage,		
Load Life III Hullidity	±2 %	1.5 h ON / 0.5 h OFF cycle , 1000 h		
Endurance at 70 °C ±2 % 70 °C, , Rated Voltage, 1.5 h ON / 0.5 h OFF of		70 °C, , Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h		



Anti-Sulfurated Thick Film Chip Resistors / Anti-Surge Type

102

Series: ERJ UP3, UP6, UP8

Features

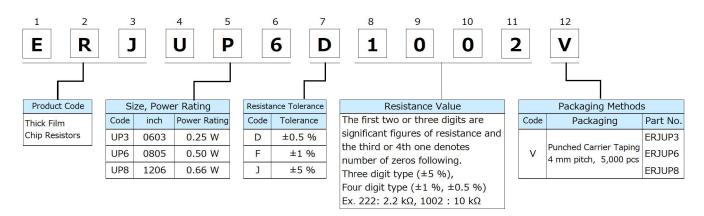
- High resistance to sulfurization achieved by adopting Anti-Sulfurated electrode material (Ag-Pd-based inner electrode) and structure
- ESD surge characteristics superior to standard metal film resistors
- High reliability... Metal glaze thick film resistive element and three layers of electrodes
- Suitable for both reflow and flow soldering
- High power 0.25 W: 0603 inch / 1608 mm size (ERJUP3)

0.50 W: 0805 inch / 2012 mm size (ERJUP6)

0.66 W: 1206 inch / 3216 mm size (ERJUP8)

- Reference Standard ··· IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers



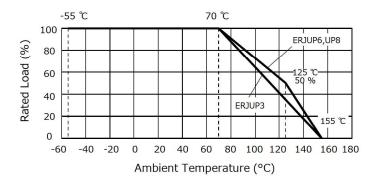
Ratings

Part No. (inch size)	Power Rating ⁽¹⁾ at 70 °C (W)	Limiting Element Voltage ⁽²⁾ (V)	Maximum Overload Voltage ⁽³⁾ (V)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (°C)	AEC-Q200 Grade
ERJUP3	0.25	150	200	±0.5, ±1	10 to 1 M (E24, E96)	±100	-55 to +155	Grade 0
(0603)	0.23	130	200	±5	1 to 1.5 M (E24)	±200	-33 to +133	L
ERJUP6				±0.5, ±1	10 to 1 M (E24, E96)	±100		
(0805)	0.50	400	600	±5	1 to 3.3 M (E24)	R<10 Ω : -100 to +600	-55 to +155	Grade 0
(0003)					1 to 3.3 M (L24)	10 Ω≤R : ±200		
ED 11 IDO				±0.5, ±1	10 to 1 M (E24, E96)	±100		
(1206)	ERJUP8 0.66 500	500	500 1000	±5	1 to 10 M (E24)	R<10 Ω : -100 to +600	-55 to +155	Grade 0
(1200)				-5	1 10 10 19 (E24)	10 Ω≤R : ±200		

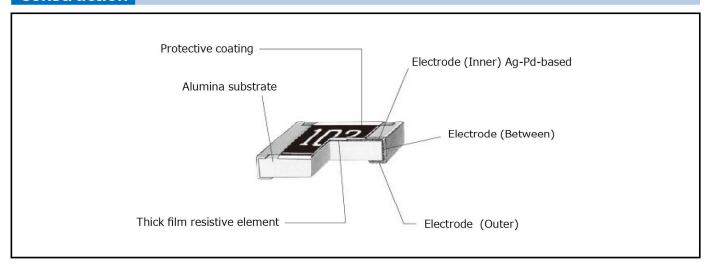
- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Power Derating Curve

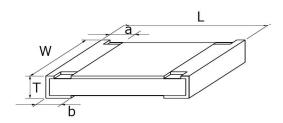
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



Construction



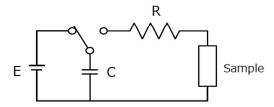
Dimensions in mm (not to scale)



Part No.	Dimensions (mm)						
Part No.	L W		a	b	b T		
ERJUP3	1.60±0.15	0.80+0.15/-0.05	0.15+0.15/-0.10	0.25±0.10	0.45±0.10	2	
ERJUP6	2.00±0.20	1.25±0.10	0.25±0.20	0.40±0.20	0.60±0.10	4	
ERJUP8	3.20+0.05/-0.20	1.6+0.05/-0.15	0.40±0.20	0.50±0.20	0.60±0.10	10	

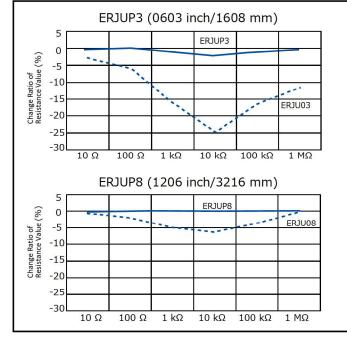


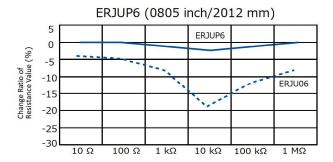
ESD Characteristic



R	R=0 Ω(\leq 1.5 kΩ) / 150 Ω($>$ 1.5 kΩ)					
С	150 pF					
Е	±3 kV					

Anti-Sulfurated Thick Film Chip Resistors / Anti-Surge Type (ERJUP Type) Anti-Sulfurated Thick Film Chip Resistors (ERJU Type)





**This data is for reference purposes.

Please check with the actual equipment before use.

Test Item	Performance Requirements ⊿R	Test Conditions		
Resistance	Within Specified Tolerance	20 °C		
T. C. R.	Within Specified T. C. R.	+25 °C/+155 °C		
Overload	±2 %	ERJUP6 : Rated Voltag× 1.77, 5 s		
		ERJUP3, ERJUP8 : Rated Voltag× 2.0 , 5 s		
Resistance to	D: ±0.5 %, F, J: ±1 %	270.90 10.6		
Soldering Heat	D . ±0.5 %, 1, 3 . ±1 %	270 °C, 10 s		
Rapid Change of	±1 %	-55 °C (30 min.) / +155 °C (30 min.), 100 cycles		
Temperature	11 70			
High Temperature	±1 %	11FF 0C 1000 b		
Exposure	11 70	+155 °C, 1000 h		
Damp Heat, Steady	±1 %	60.9C 00.0/ 05.0/DH 1000.b		
State	±1 70	60 °C, 90 % ~ 95 %RH, 1000 h		
Land life in Uranidita	13.0/	60 °C, 90 % ~ 95 %RH, Rated Voltage,		
Load Life in Humidity	±3 %	1.5 h ON / 0.5 h OFF cycle , 1000 h		
Endurance at 70.00	12.0/	70 °C, Rated Voltage,		
Endurance at 70 °C	±3 %	1.5 h ON / 0.5 h OFF cycle, 1000 h		



Anti-Sulfurated High Power Chip Resistors / Wide Terminal Type

ROI

Series: ERJ C1

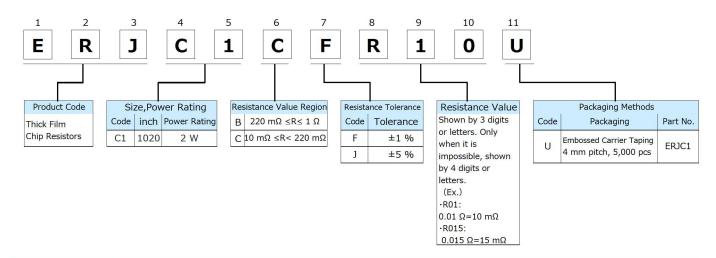
Features

- High resistance to sulfurization achieved by adopting Anti-Sulfurated electrode material (Ag-Pd-based inner electrode) and structure (Covered electrode)
- High solder-joint reliability by wide terminal construction
- Excellent heat dissipation characteristics by wide terminal construction
- AEC-Q200 compliant
- RoHS compliant

Recommended Applications

- Motor control circuit of the industrial equipment
- Automotive electronic circuits including ECUs (Electrical control unit), anti-lock breaking systems and air-bag systems
- Current sensing for power supply circuits in a variety of equipment
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers



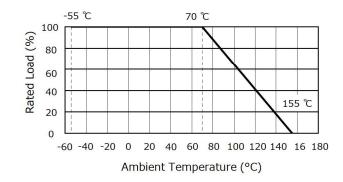
Ratings

Part No. (inch size)	Power Rating at 70 °C ⁽¹⁾ (W)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (℃)	AEC- Q200 Grade
ERJC1 (1020)	2	±1	10 m to 1 (E24)	$10 \text{ m}\Omega \le R < 22 \text{ m}\Omega : 0 \text{ to } +350$ $22 \text{ m}\Omega \le R < 47 \text{ m}\Omega : 0 \text{ to } +200$ $47 \text{ m}\Omega \le R < 100 \text{ m}\Omega : 0 \text{ to } +150$ $100 \text{ m}\Omega \le R \le 1 \Omega : \pm 100$		Grade 0
(1020)		±5		10 mΩ ≤ R < 22 mΩ : 0 to +350 22 mΩ ≤ R < 100 mΩ : 0 to +200 100 mΩ ≤ R ≤ 1 Ω : \pm 200		

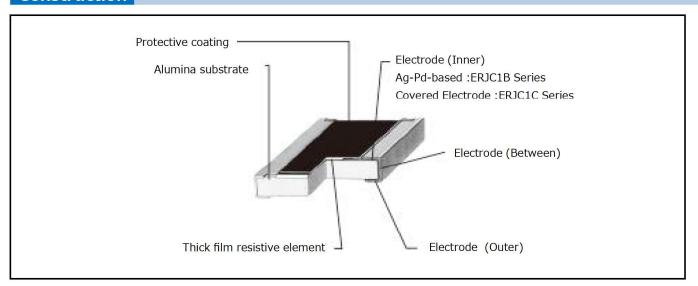
- (1) Use it on the condition that the case temperature is below the upper category temperature.
 - Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value.
 - · Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCW.

Power Derating Curve

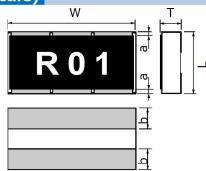
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



Construction

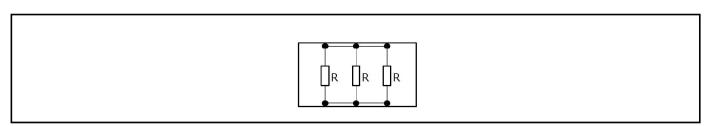


Dimensions in mm (not to scale)



Part No.	Dimensions (mm)						
L L		W	Т	a	b	(g/1000 pcs)	
ERJC1B	2.50±0.20	5.00±0.20		0.35⊥0.20	0.90±0.20	27	
ERJC1C	2.30±0.20	3.00±0.20	0.55±0.20	0.60±0.20	0.90±0.20	27	

Circuit Configuration





Test Item	Performance Requirements ⊿	Test Conditions		
Resistance	Within Specified Tolerance	20 °C		
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C		
Overload	±2 %	Rated Voltage× 2.0, 5 s		
Resistance to Soldering Heat	±1 %	270 °C, 10 s		
Rapid Change of Temperature	±2 %	-55 °C (30 min.) / +125 °C (30 min.), 1000 cycles		
High Temperature Exposure	±1 %	+155 °C, 1000 h		
Damp Heat, Steady State ±1 %		60 °C, 90 % to 95 %RH, 1000 h		
Load Life in Humidity ±3 %		60 °C, 90 % to 95 %RH, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle , 1000 h		
Endurance at 70 °C	±3 %	70 °C, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h		



High Temperature Thick Film Chip Resistor

High Temperature Thick Film Chip Resistor (Automotive Grade)

NEW



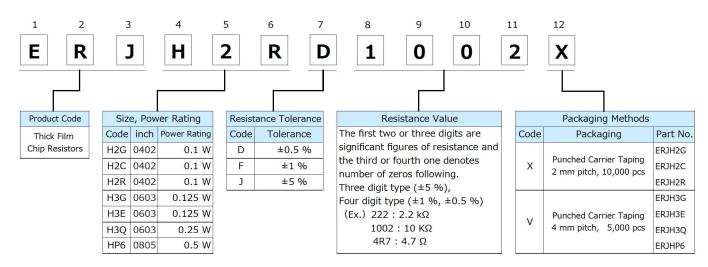
Series: ERJ H2G, H2C, H2R, H3G, H3E, H3Q H6G, HP6

Features

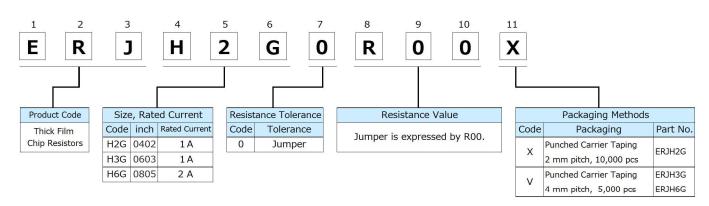
- High reliability...Metal glaze thick film resistive element and high temperature of electrodes structure
- ullet Achieve maximum category temperature 175 $^{\circ}$ C and rated category temperature 105 $^{\circ}$ C
- Compatible with placement machines ··· Taping packaging available
- Suitable for both reflow and flow soldering
- Reference Standard ··· IEC 60115-8, JIS C 5201-8, JEITA RC-2134C
- AEC-Q200 compliant
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers

● Series ERJH2G, H2C, H2R, H3G, H3E, H3Q, HP6, ±0.5 %, ±1 %, ±5 %



Series ERJH2G, H3G, H6G, Jumper



Ratings

(For Resistor)

Part No. (inch size)	Power Rating at 105 °C ⁽¹⁾ (W)	Limiting Element Voltage ⁽²⁾ (V)	Maximum Overload Voltage ⁽³⁾ (V)	Resistance Tolerance (%)	Resista Ran (Ω	ge		T.C.R. <10 ⁻⁶ /K)	Category Temperature Range (℃)	AEC- Q200 Grade
ERJH2G (0402)	0.1	50	100	±5	1 to 300 k	(E24)	R<10Ω 10Ω≤R	: -100 to +600 : ±200	-55 to +175	Grade 0
ERJH2C (0402)	0.1	50	100	±1	1 to 9.76	(E24,E96)	-10	0 to +600	-55 to +175	Grade 0
ERJH2R (0402)	0.1	50	100	±0.5,±1	10 to 300 k	(E24,E96)		±100	-55 to +175	Grade 0
ERJH3G (0603)	0.125	75	150	±5	1 to 300 k	(E24)	R<10Ω 10Ω≤R	: -100 to +600 : ±200	-55 to +175	Grade 0
ERJH3E (0603)	0.125	75	150	±0.5,±1	10 to 300 k	(E24,E96)		±100	-55 to +175	Grade 0
ERJH3Q (0603)	0.25	, - :	-	±0.5,±1 ±5	1 to 9.76 1 to 9.1	(E24,E96) (E24)		±200	-55 to +175	Grade 0
	0.5	400	600	±0.5	10 to 300 k	(E24,E96)	R<33Ω 33Ω≤R	: ±300 : ±100	-55 to +175	Grade 0
ERJHP6 (0805)	0.5	400	600	±1	1 to 300 k	(E24,E96)	R<10Ω 10Ω≤R<33Ω 33Ω≤R	: -100 to +600 : ±300 : ±100	-55 to +175	Grade 0
	0.5	400	600	±5	1 to 300 k	(E24)	R<10Ω 10Ω≤R<33Ω 33Ω≤R	: -100 to +600 : ±300 : ±100	-55 to +175	Grade 0

(1) Use it on the condition that the case temperature is below the upper category temperature.

(2) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.

(3) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

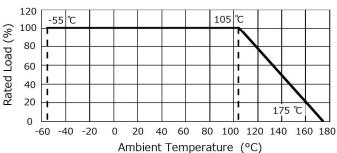
[For Jumper]

Part No.	Resistance	Rated Current	Maximum Overload Current (1)
ERJH2G		1 A	2 A
(0402)		17	27
ERJH3G	50 mΩ or less	1 A	2 A
(0603)	30 11132 01 1033	1.7	2.5
ERJH6G		2 A	4 A
(0805)		2.7	7/

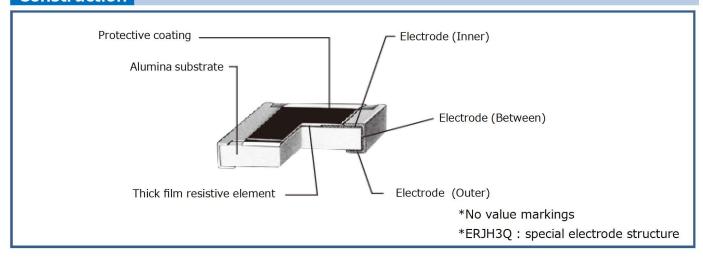
(1) Overload test current

Power Derating Curve

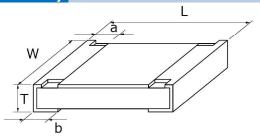
For resistors operated in ambient temperatures above 105 °C, power rating shall be derated in accordance with the figure below.



Construction



Dimensions in mm (not to scale)



Part No.		Dimensions (mm)					
rait NO.	L	W	a	b	Т	(g/1000 pcs)	
ERJH2G	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	0.8	
ERJH2C	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	0.8	
ERJH2R	1.00±0.05	0.50±0.05	0.20±0.10	0.25±0.05	0.35±0.05	0.8	
ERJH3G	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2	
ERJH3E	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2	
ERJH3Q	1.60±0.15	0.80+0.15/-0.05	0.30±0.20	0.30±0.15	0.45±0.10	2	
ERJH6G	2.00±0.20	1.25±0.10	0.40±0.20	0.40±0.20	0.60±0.10	4	
ERJHP6	2.00+0.20	1.25+0.10	0.25+0.20	0.40+0.20	0.60+0.10	4	

Test Item	Performance Re	equirements ⊿R	Test Conditions
rest Item	Resistor type	Jumper type	- Test Conditions
Resistance	Within Specified Tolerance	50 mO or less	20 °C
T. C. R.	Within Specified T. C. R.	50 m Ω or less	+25 °C/+175 °C
			ERJH2G, H2C, H2R, H3G, H3E, H3Q : Rated Voltage× 2.5, 5 s
Overload	±2 %	50 m Ω or less	ERJHP6 : Rated Voltage× 1.77, 5 s
			Jumper type : Max. Overload Current, 5 s
Resistance to Soldering Heat	±1 %	$50 \text{ m}\Omega$ or less	270 °C, 10 s
Rapid Change of Temperature	±1 %	50 mΩ or less	-55 °C (30 min.) / +175 °C (30 min.), 1000 cycles
High Temperature Exposure	±1 %	50 mΩ or less	+175 °C, 1000 h
Damp Heat, Steady State	±1 %	50 mΩ or less	85 °C, 85 %RH, 1000 h
Load Life in Humidity	±3 %	50 mΩ or less	85 °C, 85 %RH, Rated Voltage (Jumper type : Rated Current), 1.5 h ON / 0.5 h OFF cycle, 1000 h
Endurance at 105 °C	±3 %	50 mΩ or less	105 °C, Rated Voltage (Jumper type : Rated Current), 1.5 h ON / 0.5 h OFF cycle, 1000 h



Chip Resistors Array

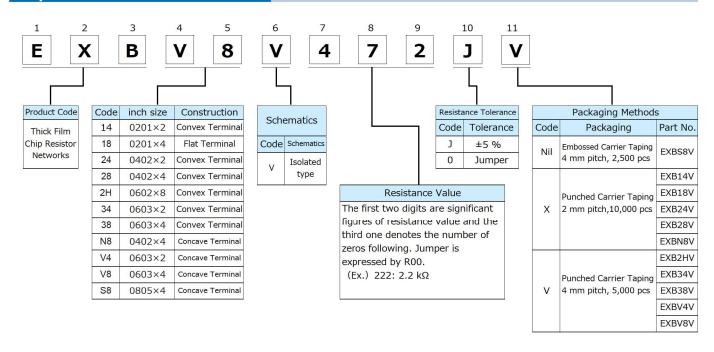
Series: EXB 14V, 18V, 24V, 28V, N8V, 2HV, 34V, V4V, 38V, V8V, S8V



Features

- High density
- 2 resistors in 0.8 mm \times 0.6 mm size / 0302 inch size : EXB14V
- 4 resistors in 1.4 mm × 0.6 mm size / 0502 inch size : EXB18V
- 2 resistors in 1.0 mm × 1.0 mm size / 0404 inch size : EXB24V
- 4 resistors in 2.0 mm × 1.0 mm size / 0804 inch size : EXB28V, N8V
- 8 resistors in 3.8 mm \times 1.6 mm size / 1506 inch size : EXB2HV
- 2 resistors in 1.6 mm × 1.6 mm size / 0606 inch size : EXB34V, V4V
- 4 resistors in 3.2 mm × 1.6 mm size / 1206 inch size : EXB38V, V8V
- 4 resistors in 5.1 mm × 2.2 mm size / 2009 inch size : EXBS8V
- Improvement of placement efficiency
 - Placement efficiency of Chip Resistor Array is two, four or eight times of the flat type chip resistor
- Reference Standard ··· IEC 60115-9, JIS C 5201-9, EIAJ RC-2129
- AEC-Q200 compliant (EXB2, EXB3)
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers



Ratings

(For Resistor)

Part No. (inch size)	Power Rating at 70 °C (W/element)	Limiting Element Voltage ⁽¹⁾ (V)	Maximum Overload Voltage ⁽²⁾ (V)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (°C)	AEC- Q200 Grade
EXB14V (0201×2)	0.031	12.5	25	±5	10 to 1 M (E24)		-55 to +125	-
EXB18V (0201×4)	0.031 (0.1 W / package)	12.5	25	±5	10 to 1 M (E24)		-55 to +125	-
EXB24V (0402×2)	0.063	50	100	±5	1 to 1 M (E24)	R<10 Ω: -200 to +600	-55 to +125	Grade 1
EXB28V (0402×4)	0.063	50	100	±5	1 to 1 M (E24)		-55 to +125	Grade 1
EXB2HV (0602×8)	0.063 (0.25 W / package)	25	50	±5	10 to 1 M (E24)		-55 to +125	Grade 1
EXB34V (0603×2)	0.063	50	100	±5	1 to 1 M (E24)		-55 to +125	Grade 1
EXB38V (0603×4)	0.063	50	100	±5	1 to 1 M (E24)	$10~\Omega$ to $1~\text{M}\Omega$:	-55 to +125	Grade 1
EXBN8V (0402×4)	0.031	50	100	±5	10 to 1 M (E24)	±200	-55 to +125	-
EXBV4V (0603×2)	0.063	50	100	±5	10 to 1 M (E24)		-55 to +125	-
EXBV8V (0603×4)	0.063	50	100	±5	10 to 1 M (E24)		-55 to +125	-
EXBS8V (0805×4)	0.1	100	200	±5	10 to 1 M (E24)		-55 to +125	r -

- (1) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV= $\sqrt{\text{Power Rating}} \times \text{Resistance Value}$, or Limiting Element Voltage listed above, whichever less.
- (2) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

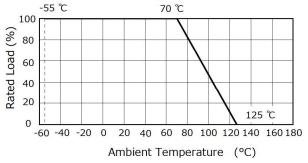
[For Jumper]

Part No.	Resistance(Ω)	Rated Current (A / element)	Maximum Overload Current (A) ⁽¹⁾
EXB14V		0.5	1
EXB18V		0.5	1
EXB24V		1	2
EXB28V		1	2
EXB2HV	50 mΩ or less	1	2
EXB34V		50 mΩ or less 1	
EXB38V		1	2
EXBN8V		1	2
EXBV4V		1	2
EXBV8V		1	2
EXBS8V		2	4

(1) Overload test current

Power Derating Curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure below.

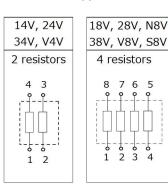


Construction(Example : Concave Terminal)

Protective coating Alumina substrate Electrode (Outer) Thick film resistive Electrode (Inner)

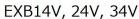
Schematics

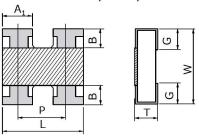
Isolated type

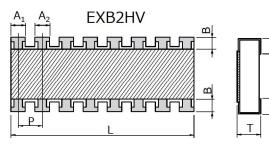


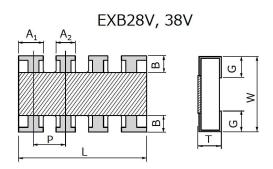
Dimensions in mm (not to scale)

(1) Convex Terminal type









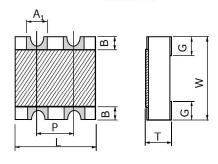
Part No.				Dimensio	ns (mm)				Mass (Weight)
(inch size)	L	W	Т	A ₁	A ₂	В	Р	G	(g/1000 pcs)
EXB14V (0603X2)	0.80±0.10	0.60±0.10	0.35±0.10	0.35±0.10	_	0.15±0.10	(0.50)	0.15±0.10	0.5
EXB24V (1005×2)	1.00±0.10	1.00±0.10	0.35±0.10	0.40±0.10	-	0.18±0.10	(0.65)	0.25±0.10	1.2
EXB28V (1005×4)	2.00±0.10	1.00±0.10	0.35±0.10	0.45±0.10	0.35±0.10	0.20±0.10	(0.50)	0.25±0.10	2.0
EXB2HV (1605×8)	3.80±0.10	1.60±0.10	0.45±0.10	0.35±0.10	0.35±0.10	0.30±0.10	(0.50)	0.30±0.10	9.0
EXB34V (1608×2)	1.60±0.20	1.60±0.15	0.50±0.10	0.65±0.15	_	0.30±0.20	(0.80)	0.30±0.20	3.5
EXB38V (1608×4)	3.20±0.20	1.60±0.15	0.50±0.10	0.65±0.15	0.45±0.15	0.30±0.20	(0.80)	0.35±0.20	7.0

≥

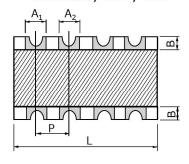
) Reference

(2) Concave Terminal type

EXBV4V



EXBN8V, V8V, S8V



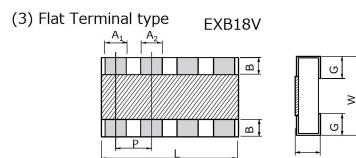
	<u></u> 5
	> [0]
T	T

Part No.		Dimensions (mm)									
(inch size)	L	W	Т	A ₁	A ₂	В	Р	G	(g/1000 pcs)		
EXBN8V (1005×4)	2.00±0.10	1.00±0.10	0.45±0.10	0.30±0.10	0.30±0.10	0.20±0.15	(0.50)	0.30±0.15	3.0		
EXBV4V	1.60	1.60	0.60±0.10	0.60±0.10	_	0.30±0.15	(0.80)	0.45±0.15	5.0		
(1608×2)	+0.20/-0.10	+0.20/-0.10	0.00±0.10								
EXBV8V	3.20	1.60	0.60±0.10	0.60±0.10	0.60±0.10	0.30±0.15	(0.80)	0.45±0.15	10		
(1608×4)	+0.20/-0.10	+0.20/-0.10	0.00±0.10	0.00±0.10	0.00±0.10	0.30±0.13					
EXBS8V	5.08	2.20	0.70±0.20	0.80±0.15	0.80±0.15	0.50±0.15	(1.27)	0.55±0.15	30		
(2012×4)	+0.20/-0.10	+0.20/-0.10	0.70±0.20	0.00±0.13	0.0010.13	0.30±0.13	(1.27)	0.55±0.15	50		

() Reference



Dimensions in mm (not to scale)



Part No.		Dimensions (mm)									
(inch size)	L	W	Т	A ₁	A_2	В	Р	G	(g/1000 pcs)		
EXB18V (0603×4)	1.40±0.10	0.60±0.10	0.35±0.10	0.20±0.10	0.20±0.10	0.10±0.10	(0.40)	0.20±0.10	1.0		

() Reference

Performance

Test Item	Performance Requirements ⊿R	Test Conditions					
Resistance	Within Specified Tolerance	20 °C					
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C					
Overload	±2 %	ated Voltage× 2.5,5 s umper type : Max. Overload Current,5 s					
Resistance to Soldering Heat	±1 %	270 °C, 10 s					
Rapid Change of Temperature	±1 %	-55 °C (30 min.) / +155 °C (30 min.), 100 cycles					
High Temperature Exposure	±1 %	+125 °C, 1000 h					
Damp Heat, Steady State	±1 %	60 °C, 90 % to 95 %RH, 1000 h					
Load Life in Humidity	±3 %	60 °C, 90 % to 95 %RH, Rated Voltage (Jumper type : Rated Current), 1.5 h ON / 0.5 h OFF cycle, 1000 h					
Endurance at 70 °C	±3 %	70 °C, Rated Voltage (Jumper type :Rated Current), 1.5 h ON / 0.5 h OFF cycle, 1000 h					



Anti-Sulfurated Chip Resistors Array

Anti-Sulfurated Chip Resistors Array



Series: EXB U14, U18, U24,

U28, U2H, U34, U38

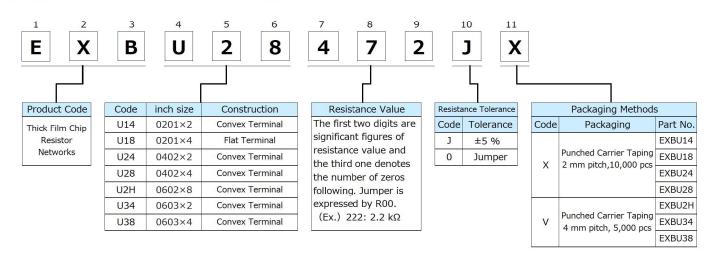
Features

- High resistance to sulfurization achieved by adopting an Ag-Pd-based inner electrode
- High density
 - 2 resistors in 0.8 mm \times 0.6 mm size / 0302 inch size : EXBU14
 - 4 resistors in 1.4 mm × 0.6 mm size / 0502 inch size : EXBU18
 - 2 resistors in 1.0 mm × 1.0 mm size / 0404 inch size : EXBU24
 - 4 resistors in 2.0 mm × 1.0 mm size / 0804 inch size : EXBU28
 - 8 resistors in 3.8 mm \times 1.6 mm size / 1506 inch size : EXBU2H
 - 2 resistors in 1.6 mm × 1.6 mm size / 0606 inch size : EXBU34
 - 4 resistors in 3.2 mm × 1.6 mm size / 1206 inch size : EXBU38
- Improvement of placement efficiency

Placement efficiency of Chip Resistor Array is two, four or eight times of the flat type chip resistor

- Reference Standard ··· IEC 60115-9, JIS C 5201-9, EIAJ RC-2129
- AEC-Q200 compliant (EXBU2, EXBU3)
- RoHS compliant
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers



Ratings

[For Resistor]

Part No. (inch size)	Power Rating at 70 °C (W/element)	Limiting Element Voltage ⁽¹⁾ (V)	Maximum Overload Voltage ⁽²⁾ (V)	Resistance Tolerance (%)	Resistance Range (Ω)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (°C)	AEC- Q200 Grade
EXBU14 (0201×2)	0.031	12.5	25	±5	10 to 1 M (E24)		-55 to +125	-
EXBU18 (0201×4)	0.031 (0.1 W / package)	12.5	25	±5	10 to 1 M (E24)	R<10 Ω: -200 to +600	-55 to +125	-
EXBU24 (0402×2)	0.063	50	100	1 5	1 to 1 M (E24)		-55 to +125	Grade 1
EXBU28 (0402×4)	0.063	50	100	±5	1 to 1 M (E24)		-55 to +125	Grade 1
EXBU2H (0602×8)	0.063 (0.25 W / package)	25	50	±5	10 to 1 M (E24)	10 Ω to 1 M Ω : ±200	-55 to +125	Grade 1
EXBU34 (0603×2)	0.063	50	100	±5	1 to 1 M (E24)		-55 to +125	Grade 1
EXBU38 (0603×4)	0.063	50	100	±5	1 to 1 M (E24)		-55 to +125	Grade 1

- (1) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (2) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

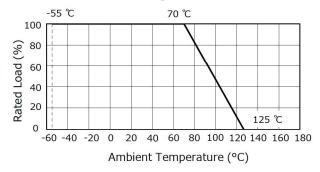
[For Jumper]

Part No.	Resistance(Ω)	Rated Current (A / element)	Maximum Overload Current (A) ⁽¹⁾		
EXBU24					
EXBU28					
EXBU2H	100 m Ω or less	1	2		
EXBU34					
EXBU38					

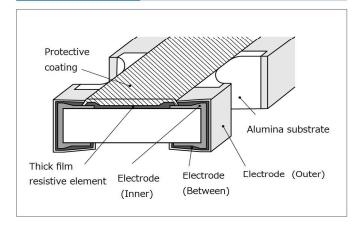
(1) Overload test current

Power Derating Curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure below.

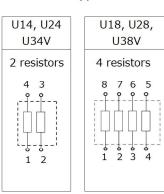


Construction

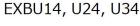


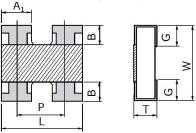
Schematics

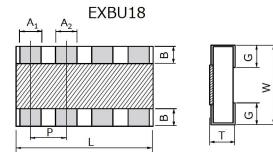
Isolated type

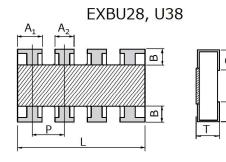


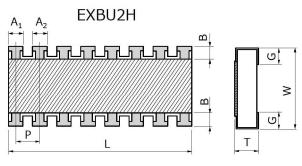
Dimensions in mm (not to scale)











Part No.				Dimensio	ns (mm)				Mass (Weight)
(inch size)	L	W	Т	A ₁	A ₂	В	Р	G	(g/1000 pcs)
EXBU14 (0201X2)	0.80±0.10	0.60±0.10	0.35±0.10	0.35±0.10	_	0.15±0.10	(0.50)	0.15±0.10	0.5
EXBU18 (0201×4)	1.40±0.10	0.60±0.10	0.35±0.10	0.20±0.10	0.20±0.10	0.10±0.10	(0.40)	0.20±0.10	1.0
EXBU24 (0402×2)	1.00±0.10	1.00±0.10	0.35±0.10	0.40±0.10	_	0.18±0.10	(0.65)	0.25±0.10	1.2
EXBU28 (0402×4)	2.00±0.10	1.00±0.10	0.35±0.10	0.45±0.10	0.35±0.10	0.20±0.10	(0.50)	0.25±0.10	2.0
EXBU2H (0602×8)	3.80±0.10	1.60±0.10	0.45±0.10	0.35±0.10	0.35±0.10	0.30±0.10	(0.50)	0.30±0.10	9.0
EXBU34 (0603×2)	1.60±0.20	1.60±0.15	0.50±0.10	0.65±0.15	_	0.30±0.20	(0.80)	0.30±0.20	3.5
EXBU38 (0603×4)	3.20±0.20	1.60±0.15	0.50±0.10	0.65±0.15	0.45±0.15	0.30±0.20	(0.80)	0.35±0.20	7.0

Performance

Test Item	Performance	Test Conditions					
rest item	Requirements ⊿R	rest conditions					
Resistance	Within Specified	20 °C					
Resistance	Tolerance	20 °C					
T. C. R.	Within Specified	+25 °C/+125 °C					
1. C. R.	T. C. R.	F23 G/ T123 C					
Overload	±2 %	Rated Voltage× 2.5, 5 s					
Overload	12 70	Jumper type: Max. Overload Current, 5 s					
Resistance to Soldering	±1 %	270.0C 10 a					
Heat	±1 %	270 °C, 10 s					
Rapid Change of	±1 %	-55 °C (30 min.) / +125 °C (30 min.), 100 cycles					
Temperature	<u> </u>						
High Temperature	±1 %	+125 °C, 1000 h					
Exposure	1 70	+125 C, 1000 H					
Damp Heat, Steady	±1 %	60 °C, 90 % to 95 %RH, 1000 h					
State	1 1 70						
Load Life in Humidity	±3 %	60 °C, 90 % to 95 %RH, Rated Voltage (Jumper type : Rated Current),					
Load Life in Humblely	±5 /0	1.5 h ON / 0.5 h OFF cycle, 1000 h					
Endurance at 70 0C	12.0/	70 °C, Rated Voltage (Jumper type :Rated Current),					
Endurance at 70 °C	±3 %	1.5 h ON / 0.5 h OFF cycle, 1000 h					



Chip Resistors Networks

Chip Resistors Networks

02 102 102 --- 121

Series: EXB D, E, A, Q

Features

- High density placing for digital signal circuits
 - ·Bussed 8 or 15 resistors for pull up/down circuits

EXBD : $3.2 \text{ mm} \times 1.6 \text{ mm} \times 0.55 \text{ mm}$, 0.635 mm pitch EXBE : $4.0 \text{ mm} \times 2.1 \text{ mm} \times 0.55 \text{ mm}$, 0.8 mm pitch EXBA : $6.4 \text{ mm} \times 3.1 \text{ mm} \times 0.55 \text{ mm}$, 1.27 mm pitch EXBQ : $3.8 \text{ mm} \times 1.6 \text{ mm} \times 0.45 \text{ mm}$, 0.5 mm pitch

- ·Available direct placing on the bus line by means of half pitch spacing without through-holes on PWB ("High density placing" is shown below)
- High speed mounting using conventional placing machine
- Reference Standard ··· IEC 60115-9, JIS C 5201-9, EIAJ RC-2130
- RoHS compliant

[High density placing]

Pull up resistors

Direct placement on the bus line

EXBE10C

EXBA10P

Vcc

Vcc

Vcc

IC

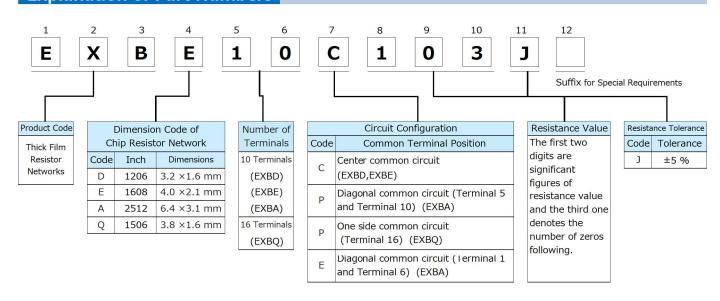
No through hole

O.4 mm pitch

O.635 mm pitch

■ As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers

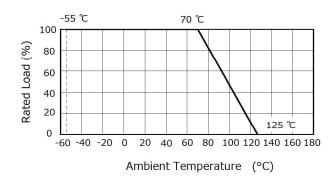


Rat	Ratings Ratings Representation of the second											
Part No. (inch size)	Resistance Range (Ω)	Resistance Tolerance (%)	Number of Terminals	Number of Resistors	Power Rating (1) at 70 °C (W/element)	Limiting Element Voltage ⁽²⁾ (V)	Maximum Overload Voltage ⁽³⁾ (V)	T.C.R. (×10 ⁻⁶ /K)	Category Temperature Range (°C)	AEC- Q200 Grade		
EXBD (1206)			10 terminals	8 element	0.05 / element	25	50	±200	-55 to +125	-		
EXBE (1608)	47 to 1 M (E12)	±5			0.063 / element	25	50	±200	-55 to +125	-		
EXBA (2512)		π5			0.063 / element	50	100	±200	-55 to +125	-		
EXBQ (1506)	100 to 470 k (E6)		16 terminals	15 element	0.025 / element	25	50	±200	-55 to +125	_		

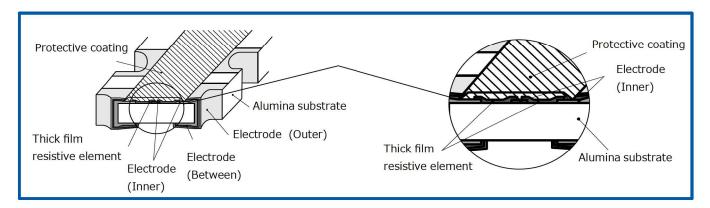
- (1) Use it on the condition that the case temperature is below the upper category temperature.
- (1) Rated Continuous Working Voltage (RCWV) shall be determined from RCWV=√Power Rating × Resistance Value, or Limiting Element Voltage listed above, whichever less.
- (2) Overload Test Voltage (OTV) shall be determined from OTV=Specified Magnification (refer to performance) × RCWV or Maximum Overload Voltage listed above, whichever less.

Power Derating Curve

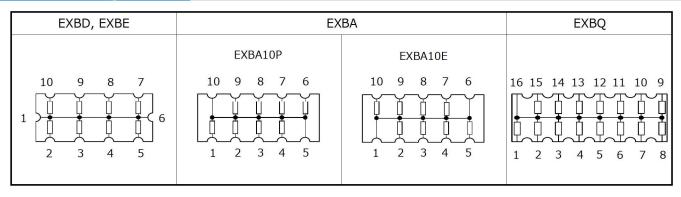
For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.



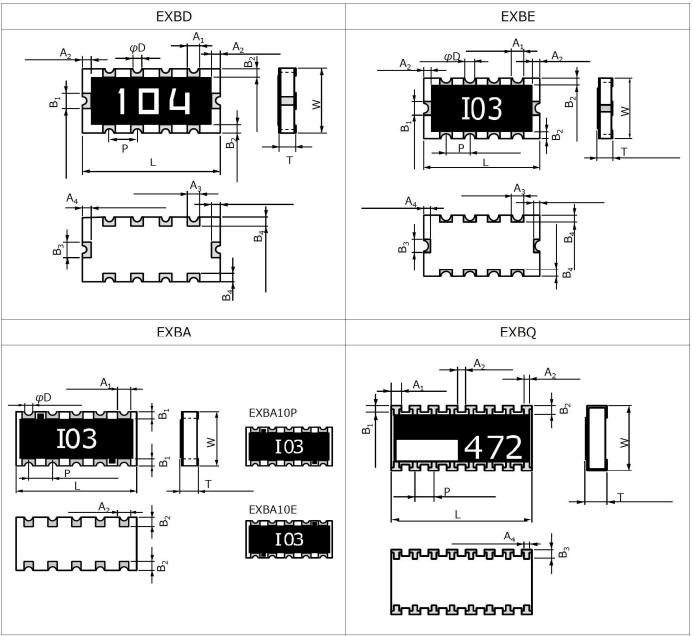
Construction(Example : EXBD)



Circuit Configuration



Dimensions in mm (not to scale)



D. I.N.			Di	mensions (mi	n)			Mass (Weight)
Part No.	L	W	Т	A ₁	A ₂	B ₁	B ₂	(g/1000 pcs)
	3.20±0.15	1.60±0.15	0.55±0.10	0.33±0.15	0.2±0.1	0.40±0.15	0.2±0.1	
EXBD	A ₃	A ₄	B ₃	B ₄	Р	φD		10
	0.3±0.1	0.25±0.10	0.40±0.15	0.35±0.15	0.635±0.10	0.2±0.1		
			Di	mensions (mi	n)			Mass (Weight)
Part No.	L	W	T	A ₁	A ₂	B ₁	B ₂	(g/1000 pcs)
	4.0±0.2	2.1±0.2	0.55±0.10	0.5±0.2	0.3±0.2	0.5±0.2	0.25±0.20	
EXBE	A_3	A ₄	B ₃	B ₄	Р	φD		16
	0.4±0.2	0.35±0.20	0.5±0.2	0.4±0.2	0.8±0.1	0.3+0.1/-0.2		1
5			Di	mensions (mi	n)			Mass (Weight)
Part No.	L	W	Т	A ₁	B ₁	A ₂	B ₂	(g/1000 pcs)
	6.4±0.2	3.1±0.2	0.55±0.10	0.7±0.2	0.3±0.2	0.5±0.2	0.5±0.20	
EXBA	b	φD						40
	1.27±0.10	0.3+0.1/-0.2						
			Di	mensions (mi	n)			Mass (Weight)
Part No.	L	W	T	A ₁	A ₂	A ₃	B ₁	(g/1000 pcs)
	3.8±0.2	1.6±0.2	0.45±0.10	0.3±0.1	0.2±0.1	0.15+0.15/-0.05	0.15+0.15/-0.05	
EXBQ	B ₂	A ₄	B ₃	Р				9
	0.25±0.15	0.15+0.20/-0.05	0.30±0.15	0.5±0.1				

Performance

Test Item	Performance Requirements ⊿R	Test Conditions
Resistance	Within Specified Tolerance	20 °C
T. C. R.	Within Specified T. C. R.	+25 °C/+125 °C
Overload	±3 %	Rated Voltage× 2.5, 5 s
Resistance to Soldering Heat	±1 %	260 °C ±5 °C, 5 s ±1 s
Rapid Change of Temperature	±2 %	-55 °C (30 min.) / +125 °C (30 min.), 5 cycles
High Temperature Exposure	±3 %	+125 °C, 100 h
Load Life in Humidity	±3 %	60 °C±2 °C, 90 % to 95 %RH, Rated Power × 0.1, 1.5 h ON / 0.5 h OFF cycle, 500 h
Endurance at 70 °C	±5 %	70 °C±2 ℃, Rated Voltage, 1.5 h ON / 0.5 h OFF cycle, 1000 h



Chip Attenuator



Series: EXB 14AT, 24AT

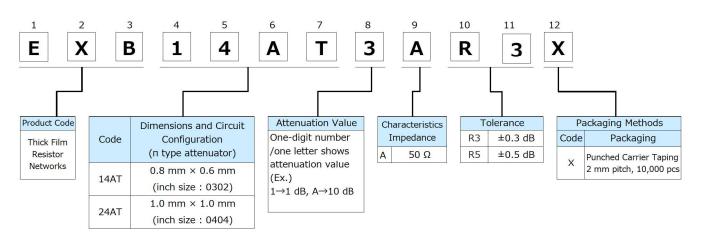
Features

- Unbalanced π type attenuator circuit in one chip EXB14AT(0.8 mm×0.6 mm), EXB24AT(1.0 mm×1.0 mm)
- Reduced mounting area :
 - EXB14AT : About 60 % smaller than the area of an attenuator circuit consisting of three 0603 chip resistors, almost equal to the area of three 0402 chip resistors
 - EXB24AT : About 50 % smaller than the area of an attenuator circuit consisting of three 1005 chip resistors, almost equal to the area of three 0603 chip resistors
- Mounting cost reduction: (Only 1 chip placed as compared to 3)
- Attenuation: 1 dB to 10 dB
- RoHS compliant

Recommended Applications

- Attenuation / level control / impedance matching of high frequency (communication signalling equipment cellular phones(GSM, CDMA, PDC, etc.), PHS, PDAs)
- As for Packaging Methods, Land Pattern, Soldering Conditions and Safety Precautions, Please see Data Files

Explanation of Part Numbers



Ratings Part No. EXB14AT, EXB24AT Attenuation Value 1 dB, 2 dB, 3 dB, 4 dB, 5 dB, 6 dB, 10 dB* 1 dB, 2 dB, 3 dB, 4 dB, 5dB: ±0.3 dB Attenuation Value Tolerance 6 dB, 10 dB : ±0.5 dB Characteristic Impedance 50 Ω Power Rating at 70 °C 0.04 W/ package Frequency Range DC to 3.0 GHz VSWR (Voltage Standing Wave Ratio) 1.3 max. Number of Resistors 3 resistors **Number of Terminals** 4 terminals

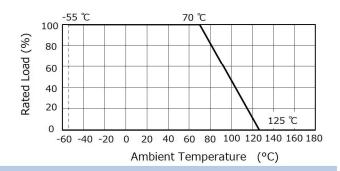
-55 °C to +125 °C

Category Temperature Range

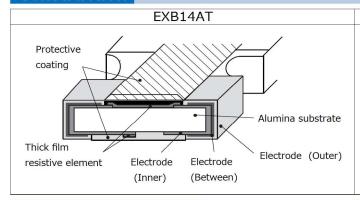
^{*} Please inquire about the other Attenuator value

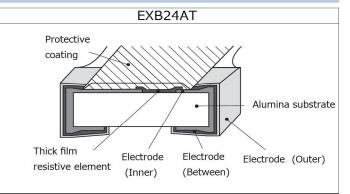
Power Derating Curve

For resistors operated in ambient temperatures above 70 °C, power rating shall be derated in accordance with the figure on the right.

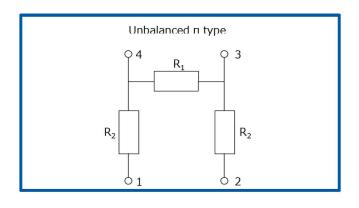


Construction

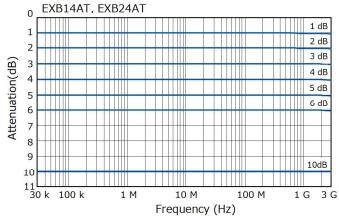




Circuit Confi guration

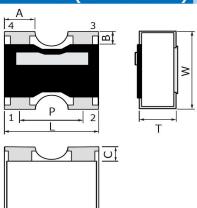


Attenuation-Frequency Characteristics

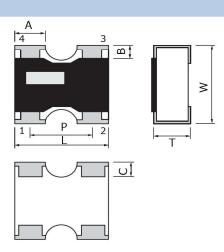


Dimensions in mm (not to scale)

EXB14AT



EXB24AT



< Marking Configuration>
The bar marking for recognizing terminal direction is located on the side of terminal 3, 4.

< Marking Configuration>
The bar marking for recognizing terminal direction is located on the side of terminal 4.

Part No.	Dimensions (mm)										
rare ito:	L	W	T	Α	В	С	P(typical value)	(g/1000 pcs)			
EXB14AT	0.80 ± 0.10	0.60 ± 0.10	0.35 ± 0.10	0.35 ± 0.10	0.15 ± 0.10	0.15 ± 0.10	0.50	0.7			
EXB24AT	1.00±0.10	1.00±0.10	0.35±0.10	0.40±0.10	0.15±0.10	0.25±0.10	0.65	1.1			



Surface	Mount Resistors Seri	es	Pa	ackaging (Standard	I Quantity : pcs/re	el)
		Ciza mm	Pressed	Punched	Punched	Embossed
Products	Part No.	Size mm (inch)	Carrier Taping	Carrier Taping	Carrier Taping	Carrier Taping
		(IIICII)	(2 mm pitch)	(2 mm pitch)	(4 mm pilch)	(4 mm pilch)
	ERJXGN	0402(01005)	20,000 *	- ×	_	40,000 **
	ERJ1GN	0603(0201)	15,000	_	_	_
	ERJ2GE	1005(0402)	_	10,000	·—	_
	ERJ3GE	1608(0603)	_	_	5,000	_
Thick Film	ERJ6GE	2012(0805)	1	_	5,000	_
Chip Resistors	ERJ8GE	3216(1206)	_	—	5,000	_
	ERJ14	3225(1210)	_	_	_	5,000
	ERJ12	4532(1812)	-	—	_	5,000
	ERJ12Z	5025(2010)	_	_	_	5,000
	ERJ1T	6432(2512)	_		_	4,000
	ERJXGN	0402(01005)	20,000 *	_	_	40,000 **
	ERJ1GN/1RH	0603(0201)	15,000	 e	-	_
	ERJ2RC/2RH/2RK	1005(0402)	_	10,000	_	_
	ERJ3RB/3RE/3EK	1608(0603)	_		5,000	-
Precision	ERJ6RB/6RE/6EN	2012(0805)	_	_	5,000	_
Thick Film Chip Resistors	ERJ8EN	3216(1206)	_	_	5,000	_
Chip Resistors	ERJ14N	3225(1210)	_		_	5,000
	ERJ12N	4532(1812)	_	_	n 	5,000
	ERJ12S	5025(2010)	_	_	-	5,000
	ERJ1TN	6432(2512)	_	_	_	4,000
Metal Film	ERA1A	0603(0201)	15,000	_	_	_
(Thin Film)	ERA2A/2V	1005(0402)	_	10,000	×	_
Chip Resistors,	ERA3A/3V/3K	1608(0603)	-	_	5,000	_
High Reliability	ERA6A/6V/6K	2012(0805)	_		5,000	_
Туре	ERA8A	3216(1206)	_	_	5,000	_
(ERJ2LW/2BW	1005(0402)	10,000		_	_
	ERJ2BS/2BQ	1005(0402)	_	10,000		_
	ERJ3L/3B/3R/L03	1608(0603)	_	_	5,000	_
	ERJ6L/6B/6C					
Thick Film	ERJ6D/6R/L06	2012(0805)	_	_	5,000	_
Chip Resistors/Low	ERJ8B/8C/8R/L08	3216(1206)	_	_	5,000	_
Resistance Type	ERJ14B/14R/L14	3225(1210)	_	_		5,000
7.1	ERJ12R/L12	4532(1812)				5,000
	ERJ12Z/L1D	5025(2010)	_	_	_	5,000
	ERJ1TR	6432(2512)		_		4,000
	ERJL1W	6432(2512)		_	_	3,000
	ERJMP2	3216(1206)	_	_	_	3,000
	ERJMP3	5025(2010)			· —	3,000
Current Sensing	ERJMP4	6432(2512)		_		2,000
Resistors, Metal	ERJMS4	6432(2512)		_		2,000
Plate Type	ERJMS6	6468(2526)		_	_	1,000 (8mm Pitch)
	ERJMB1	2550(1020)	<u> </u>	_		3,000 (8mm Pitch)
	ERJM1W	6432(2512)				3,000
Current Sensing Resistors, Metal	ERJMFBA	1005(0402)	_	10,000	_	_
Foil Type	ED141	3264(1225)				4.000
High Power	ERJA1 ERJB1/ERJC1 ⁽¹⁾	2550(1020)		_		4,000 5,000
Chip Resistors/Wide	2.001					fire fire fire fire fire fire fire fire
Terminal Type	ERJB2/ERJD2 ⁽²⁾	1632(0612)	_	— ×	5,000	_
	ERJB3	1220(0508)	_	_	5,000	_

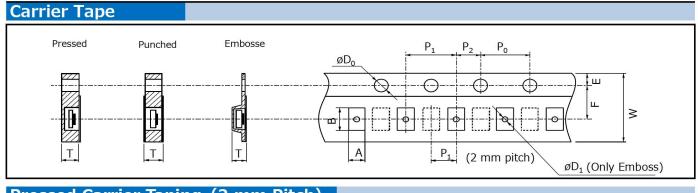
^{*}W8P2 : Width 8 mm, Pitch 2 mm, ** W4P1 : Width 4 mm, Pitch 1 mm

 $[\]hbox{(1) Anti-Sulfurated High Power Chip Resistors / Wide Terminal Type}\\$

⁽²⁾ Low TCR High Power Chip Resistors / Wide Terminal Type

Surface	Mount Resistors Ser	ies	Pa	ackaging (Standard	Quantity: pcs/re	el)
		Size mm	Pressed	Punched	Punched	Embossed
Products	Part No.	(inch)	Carrier Taping (2 mm pilch)	Carrier Taping (2 mm pilch)	Carrier Taping (4 mm pilch)	Carrier Taping (4 mm pilch)
High Precision Thick	FR IPB3	1608(0603)	_	_	5,000	_
Film Chip Resistors	ERJPB6	2012(0805)	_	_	5,000	_
	ERJPA2	1005(0402)	_	10,000		_
	ERJP03/PA3	1608(0603)	_	_	5,000	_
Anti-Surge Thick	ERJP06	2012(0805)		_	5,000	_
Film Chip Resistors	ERJP08	3216(1206)		_	5,000	_
	ERJP14	3225(1210)				5,000
	ERJT06	2012(0805)		_	5,000	
Anti-Pulse Thick	ERJT08	3216(1206)	_	_	5,000	_
Film Chip Resistors	ERJT14	3225(1210)		_		5,000
	ERJU0X	0402(01005)	20,000	_	_	_
	ERJU01	0603(0201)	15,000	_	_	_
	ERJS02/U02	1005(0402)	13,000	10,000		
	ERJS03/U03	1608(0603)		10,000	5,000	
Anti-Sulfurated	ERJS06/U06	1000(0003)		_	3,000	
Thick Film		2012(0805)	_	_	5,000	_
Chip Resistors	ERJU6S/U6Q	224 ((4.206)				
Chip Resistors	ERJS08/U08	3216(1206)	_	_	5,000	_
	ERJS14/U14	3225(1210)	-	-		5,000
	ERJS12/U12	4532(1812)		_	Ţ	5,000
	ERJS1D/U1D	5025(2010)		_	_	5,000
Anti-Sulfurated	ERJS1T/U1T	6432(2512)	_	_	_	4,000
Thick Film Chip	ERJU2R	1005(0402)	_	10,000		_
Resistors / Precision	ERJU3R	1608(0603)	_	_	5,000	
Type Anti-Sulfurated	ERJU6R	2012(0805)		_	5,000	_
Thick Film Chip	ERJUP3	1608(0603)	_	_	5,000	_
Resistors / Anti-Surge	ERJUP6	2012(0805)		_	5,000	_
Type	ERJUP8	3216(1206)		_	5,000	_
High Temperature Thick Film Chip	ERJH2G/2C/2R	1005(0402)		10,000	_ 	_
Resistor	ERJH3G/3E/3Q	1608(0603)		_	5,000 5,000	_
	ERJH6G/HP6	2012(0805)	<u> </u>	10.000	5,000	
	EXB14V	0806(0302) 1010(0404)		10,000	_	_
	EXB24V		_	10,000		_
	EXB34V	1616(0606)		_	5,000 5,000	_
	EXBV4V	1616(0606)	<u> </u>	10.000	5,000	_
Chip Resistor	EXB18V	1406(0502)		10,000	_	
Array	EXB28V	2010(0804)	_	10,000	-	_
	EXBN8V	2010(0804)	=	10,000	_ 	—
	EXB38V	3216(1206)	_	_	5,000	_
	EXBV8V	3216(1206)	_	_	5,000	_ 2 F00
	EXBS8V	5022(2009)		_	_ 	2,500
	EXB2HV	3816(1506)			5,000	_
	EXBU14	0806(0302)	_	10,000	_	_
	EXBU18	1406(0502)		10,000	_	_
Anti-Sulfurated	EXBU24	1010(0404)		10,000	_	_
Chip Resistor Array	EXBU34	1616(0606)	_	_	5,000	_
	EXBU28	2010(0804)		10,000	_	_
	EXBU38	3216(1206)		_	5,000	_
	EXBU2H	3816(1506)	_	_	5,000	_
	EXBD	3216(1206)	_	_	5,000	_
Chip Resistor	EXBE	4021(1608)		_		4,000
Networks	EXBA	6431(2512)	_	_	_	4,000
	EXBQ	3816(1506)	_	_	5,000	_
Chip Attenuator	EXB14AT	0806(0302)	_	10,000	_	_
/	EXB24AT	1010(0404)	_	10,000	_	





Pressea	Carrier	laping	(2 mi	m Pitcr	1)						
Chip Resis	stors / Precision	on Chip / N	1etal Film(Thin Film)(Chip / Low	Resistance	/ Anti-Su	lfurated		(Unit	: mm)
	Size mm (inch)	Α	В	W	F	Е	P ₁	P ₂	P ₀	øD ₀	Т
ERJXGN	0402	0.24±0.03	0.45±0.03								0.31±0.05
ERJUOX ERJ1GN											
ERJ1R□										. ==	
ERJU01	0603	0.38±0.05	0.68±0.05	8.00±0.20	3.50±0.05	1.75±0.10	2.00±0.10	2.00±0.05	4.00±0.10	1.50 +0.10/0	0.42±0.05

Punched Carrier Taping (2 mm Pitch)

• Chip Resistors / Precision Chip / Thin Film Chip / Low Resistance / Anti-Surge / Anti-Sulfur / High Temperature / Metal Foil Type (Unit: r											
Part No.	Size mm (inch)	Α	В	W	F	E	P ₁	P ₂	P ₀	øD ₀	Т
ERJ2□											
ERJPA2											
ERJ□□2	1005	0.67±0.05	1 17+0 05	8 00+0 30	3 50+0 05	1 75±0 10	2 00+0 10	2 00+0 05	4 00±0 10	1.50	0.52±0.05
ERJ□2□	1005	0.67±0.03	1.17±0.03	8.00±0.20	3.30±0.03	1.75±0.10	2.00±0.10	2.00±0.03	4.00±0.10	+0.10/0	
ERA2□											
ERJMFBA											0.60±0.05

Chip Resis	stor Array / A	nti-Sulfura	ted Chip R	esistor Arra	ay / Chip A	ttenuator				(Unit	: mm)
Part No.	Size mm (inch)	Α	В	W	F	E	P ₁	P ₂	P ₀	ϕD_0	Т
EXB14V	0806	0.70	0.95								
EXB14AT	0000	+0.10/-0.05	+0.05/-0.10								
EXB18V	1406		1.60±0.10								
EXB24V										1 50	
EXBU24	1010		1.20±0.10	8.00±0.20	3.50±0.05	1.75±0.10	2.00±0.10	2.00±0.05	4.00±0.10	1.50	0.52±0.05
EXB24AT		1.20±0.10								+0.10/0	
EXB28V											
EXBU28	2010		2.20±0.10								
EXBN8V											

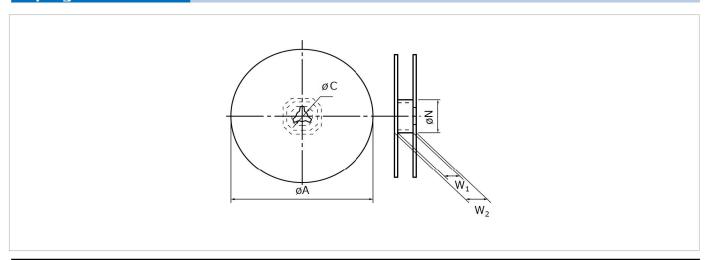
Punched Carrier Taping (4 mm Pitch)

I difficile	a carric	Імрііі	9 (1111		117						
● Chip Resis	stors / Precisi	on Chip / N	/letal Film(Thin Film)(Chip / Low	Resistance	e / High Po	wer / High	Precision,	/ Anti-Surg	je /
Anti-Pulse	/ Anti-Sulfur	ated / High	h Tempera	ture						(Unit	: mm)
Part No.	Size mm (inch)	Α	В	W	F	E	P ₁	P ₂	P ₀	øD ₀	Т
ERJ3											
ERJ3LW(10mΩ)											
ERJ3BW	1.000	1 1010 10	1 00 10 10								0.70±0.05
ERJ□3 ERJ□3□	1608	1.10±0.10	1.90±0.10								
ERJ□ 3 □ ERA3□											
ERJ3LW(5mΩ)	-										
ERJ6□											
ERJ□□6	10 Sec. 2005										
ERJ□6□	2012	1.65±0.15	2.50±0.20								0.84±0.05
ERA6□		CONTRACTOR DESCRIPTION		8.00±0.20	3.50±0.05	1.75±0.10	4.00±0.10	2.00±0.05	4.00±0.10	1.50 +0.10/0	2010/2014
ERJB3	1220									+0.10/0	
ERJ6BW											
ERJ6LW	2012	1.55±0.15	2.30±0.20								0.94±0.05
ERJ6C											0.54±0.05
ERJ8□											
ERJ8□W	3216										
ERJ□□8		2.00±0.15	3.60±0.20								0.84±0.05
ERA8□ ERJB2		-									
ERID2	1632										

	istor Array / A						Netwo		_			t : mm)
Part No.	Size mm (inch)	Α	В	W	F	E		P ₁	P_2	P ₀	øD ₀	Т
EXB34V	1616		1.95±0.20									
XBU34 XB38V		-		al .								
EXBU38	3216		3.60±0.20									0.70±0.0
XB2HV	2016	1.95±0.15	4 10 10 15	9								
XBU2H	3816		4.10±0.15	8.00±0.20	3.50±0.05	1.75±0.	10 4.0	0±0.10	2.00±0.05	4.00±0.10	1.50	
XBV4V	1616		1.95±0.20								+0.10/0	0.0410.0
EXBV8V	3216		3.60±0.20									0.84±0.0
EXBD	3216	2.00±0.20	3.60±0.20									0.84±0.1
EXBQ	3816	1.90±0.20		4								0.64±0.0
_NDQ	5010	1.90±0.20	7.1020.20									0.01=0.0
Emboss	sed Carri	er Tapi	ng (1	mm Pi	tch)							
● Chip Resi		_									/ 1.lm:	+
Part No.	Size mm (inch)	Α	В	W	F	Е		P ₁	P ₂	P ₀		t:mm)
				15.65	-		10 1 0			_	øD ₀	0 E max
RJXGN	0402	0.25±0.05	0.45±0.05	4.00±0.20	1.80±0.05	0.90±0	.10 1.0	0±0.10	1.00±0.10	2.00±0.10	0.80±0.10	0.5 max
Embos	sed Carri	or Tani	na (4	mm Di	tch)							
						1: 6		.: D .	/ A 1: C	16 1		
	istors / Precisi						20 100		580			it : mm)
Part No.	Size mm (inch)	Α	В	W	F	Е	P ₁	P ₂	P ₀	øD ₀	T	$ \emptyset D_1 $
ERJ14□	3225	2.80±0.20	3.50±0.20	8.00±0.30	3.50±0.05							1.00
RJ□14 RJ12□												+0.10/0
RJ∏12	4532	3.50±0.20	4.80±0.20									
ERJ12Z				S.								
ERJ12S	5025										1 00 10 10	
RJ□1D		2.80±0.20	E 20±0 20			1.75	4.00	2.00	4.00	1.50	1.00±0.10	
RJB1		2.80±0.20	3.30±0.20	12.00±	5.50±0.20	±0.10	±0.10	±0.05	±0.10	+0.10/0		15 min
RJC1	2550			0.30	3.30±0.20							13 11111
RJD1		3.60±0.20										
ERJ1T□												
ERJ□1T	6432	3.60±0.20	6.90±0.20								4 601040	
ERJL1W ERJA1	3264	3.50±0.20	C 00 10 20								1.60±0.10	
LNJAI	3204	3.30±0.20	0.80±0.20								1.10±0.20	
Current 9	Sensing Resist	ors, Metal	Plate Type								(Uni	t : mm)
Part No.	Size mm (inch)	A	В	W	F	Е	P ₁	P ₂	P ₀	øD ₀	T	ØD₁
ERJMP2							. 1	. 2	. 0	220		201
(1 mΩ)	3216										1.55±0.20	_
ERJMP2	2216	1 00 1 0 20	2 50 10 20	0.0010.20	2 501010						4 40 10 20	
(2 mΩ)	3216	1.90±0.20	3.50±0.20	8.00±0.30	3.50±0.10						1.40±0.20	
ERJMP2	3216										1.10±0.20	
(3~50 mΩ)	3210										1.10±0.20	
ERJMP3	5025										1.55±0.20	_
(1 ~2 mΩ)				12.00±		1.75	4.00	2.00	4.00	1.50		
ERJMP3	5025	2.90±0.20	5.40±0.20	0.30	5.50±0.10	±0.10	±0.10	±0.05		+0.10/0	1.15±0.20	_
(3~50 mΩ) ERJMB1	3550	-									S. S	24
	2550										1.55±0.20	
								1	1	1	1.60±0.20	1.5 min
ERJMP4	6432											I .
ERJMP4 (1 ~2 mΩ)				12 00+								
ERJMP4 (1 ~2 mΩ) ERJMP4	6432 6432	3.50±0.20	6.90±0.20	12.00±	5.50±0.10						1.20±0.20	_
ERJMP4 (1 \sim 2 mΩ) ERJMP4 (3 \sim 50 mΩ)		3.50±0.20	6.90±0.20	12.00± 0.30	5.50±0.10							1.5 mir
ERJMP4 $(1 \sim 2 \text{ m}\Omega)$ ERJMP4 $(3 \sim 50 \text{ m}\Omega)$ ERJMS4	6432	3.50±0.20	6.90±0.20		5.50±0.10						1.20±0.20	
ERJMP4 $(1 \sim 2 \text{ m}\Omega)$ ERJMP4 $(3 \sim 50 \text{ m}\Omega)$ ERJMS4 ERJM1W	6432 6432 6432			0.30	5.50±0.10						1.20±0.20 1.60±0.20 1.80±0.20	1.5 mir
ERJMP4 (1 ~2 mΩ) ERJMP4 (3~50 mΩ) ERJMS4 ERJM1W Chip Resi	6432 6432 6432 istor Array / C	hip Resisto	r Networks	0.30							1.20±0.20 1.60±0.20 1.80±0.20 (Uni	1.5 mir t : mm)
ERJMP4 $(1 \sim 2 \text{ m}\Omega)$ ERJMP4 $(3 \sim 50 \text{ m}\Omega)$ ERJMS4 ERJM1W	6432 6432 6432			0.30	5.50±0.10	E	P ₁	P ₂	P ₀	øD ₀	1.20±0.20 1.60±0.20 1.80±0.20	1.5 mir
ERJMP4 (1 ~2 mΩ) ERJMP4 (3~50 mΩ) ERJMS4 ERJM1W Chip Resi Part No.	6432 6432 6432 istor Array / C	hip Resisto	r Networks B	0.30 S		E					1.20±0.20 1.60±0.20 1.80±0.20 (Uni	1.5 mir t : mm)
ERJMP4 (1 ~2 mΩ) ERJMP4 (3~50 mΩ) ERJMS4 ERJM1W Chip Resi Part No. EXBS8V	6432 6432 6432 istor Array / C	thip Resisto	r Networks B 5.70±0.20	0.30 S W 12.00±		E 1.75	4.00	2.00	4.00	1.50	1.20±0.20 1.60±0.20 1.80±0.20 (Uni T 1.6 max.	1.5 mir t : mm) ØD ₁
ERJMP4 (1 ~2 mΩ) ERJMP4 (3~50 mΩ) ERJMS4 ERJM1W • Chip Resi Part No. EXBS8V EXBE	6432 6432 6432 istor Array / C Size mm (inch) 5022 4021	A 2.80±0.20 2.50±0.20	r Networks B 5.70±0.20 4.40±0.20	0.30 S	F	E			4.00		1.20±0.20 1.60±0.20 1.80±0.20 (Uni	1.5 mir t : mm) ØD ₁
ERJMP4 (1 ~2 mΩ) ERJMP4 (3~50 mΩ) ERJMS4 ERJM1W • Chip Resi Part No. EXBS8V EXBE	6432 6432 6432 istor Array / C Size mm (inch) 5022	hip Resisto A 2.80±0.20	r Networks B 5.70±0.20 4.40±0.20	0.30 S W 12.00±	F	E 1.75	4.00	2.00	4.00	1.50	1.20±0.20 1.60±0.20 1.80±0.20 (Uni T 1.6 max.	1.5 min t : mm) ØD ₁
ERJMP4 (1 ~2 mΩ) ERJMP4 (3~50 mΩ) ERJMS4 ERJM1W • Chip Resi Part No. EXBS8V EXBE	6432 6432 istor Array / C Size mm (inch) 5022 4021 6431	hip Resisto A 2.80±0.20 2.50±0.20 3.50±0.20	r Networks B 5.70±0.20 4.40±0.20 6.80±0.20	0.30 W 12.00± 0.30	F 5.50±0.20	E 1.75	4.00	2.00	4.00	1.50	1.20±0.20 1.60±0.20 1.80±0.20 (Uni T 1.6 max.	1.5 min t : mm) ØD ₁
ERJMP4 (1 ~2 mΩ) ERJMP4 (3~50 mΩ) ERJMS4 ERJM1W • Chip Resi Part No. EXBS8V EXBE EXBA	6432 6432 istor Array / C Size mm (inch) 5022 4021 6431	hip Resisto A 2.80±0.20 2.50±0.20 3.50±0.20	r Networks B 5.70±0.20 4.40±0.20 6.80±0.20	0.30 W 12.00± 0.30	F 5.50±0.20	E 1.75	4.00	2.00	4.00	1.50	1.20±0.20 1.60±0.20 1.80±0.20 (Uni T 1.6 max.	1.5 mir t : mm) ØD ₁
ERJMP4 (1 ~2 mΩ) ERJMP4 (3~50 mΩ) ERJMS4 ERJM1W • Chip Resi Part No. EXBS8V EXBE EXBA • Current S	6432 6432 istor Array / C Size mm (inch) 5022 4021 6431 sed Carri Gensing Resist	hip Resistor A 2.80±0.20 2.50±0.20 3.50±0.20 er Tapi ors, Metal	r Networks B 5.70±0.20 4.40±0.20 6.80±0.20 ng (8 Plate Type	0.30 W 12.00± 0.30	F 5.50±0.20	E 1.75 ±0.10	4.00 ±0.10	2.00 ±0.05	4.00 ±0.10	1.50 +0.10/0	1.20±0.20 1.60±0.20 1.80±0.20 (Uni T 1.6 max. 1.10±0.20	1.5 mir t : mm) ØD ₁ 1.5 min
ERJMP4 (1 ~2 mΩ) ERJMP4 (3~50 mΩ) ERJMS4 ERJM1W • Chip Resi Part No. EXBS8V EXBE EXBA	6432 6432 istor Array / C Size mm (inch) 5022 4021 6431	hip Resisto A 2.80±0.20 2.50±0.20 3.50±0.20	r Networks B 5.70±0.20 4.40±0.20 6.80±0.20	0.30 W 12.00± 0.30 mm Pi	F 5.50±0.20	E 1.75 ±0.10	4.00 ±0.10	2.00 ±0.05	4.00 ±0.10	1.50 +0.10/0	1.20±0.20 1.60±0.20 1.80±0.20 (Uni T 1.6 max. 1.10±0.20	ØD ₁
ERJMP4 (1 ~2 mΩ) ERJMP4 (3~50 mΩ) ERJMS4 ERJM1W • Chip Resi Part No. EXBS8V EXBE EXBA • Current S	6432 6432 istor Array / C Size mm (inch) 5022 4021 6431 sed Carri Gensing Resist	hip Resistor A 2.80±0.20 2.50±0.20 3.50±0.20 er Tapi ors, Metal	r Networks B 5.70±0.20 4.40±0.20 6.80±0.20 ng (8 Plate Type B	0.30 W 12.00± 0.30	F 5.50±0.20	E 1.75 ±0.10	4.00 ±0.10	2.00 ±0.05	4.00 ±0.10	1.50 +0.10/0	1.20±0.20 1.60±0.20 1.80±0.20 (Uni T 1.6 max. 1.10±0.20	1.5 min t:mm) ØD ₁ 1.5 min



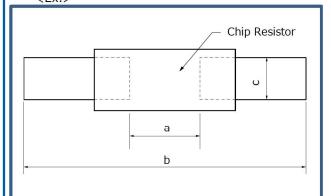
Taping Reel



Tano width(M)	Dimensions (mm)									
Tape width(W)	øΑ	øN	øС	W_1	W_2					
4 mm width	180.0±3.0			4.5±0.5	7.0±0.5					
8 mm width	190 0 0/ 1 5	60.0+1.0/0	13.0±0.2	9.0+1.0/0	11.4±1.0					
12 mm width	180.0 0/-1.5		13.0±0.2	13.0+1.0/0	15.4±1.0					
24 mm width	380.0±2.0	80.0±1.0		25.4±1.0	29.4±1.0					

Recommended Land Pattern

 \bullet An example of a land pattern for the Rectangular Type is shown below.

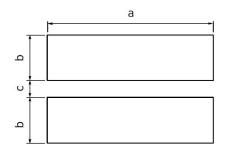


Part No.	Size mm	Dim	ensions(r	nm)
rait No.	inch	a	b	С
ERJ2LW/2BW	1005 0402	0.52	1.4 to 1.6	0.4 to 0.6
ERJ3LW/3BW	1608 0603	0.5 to 0.8	2.5 to 2.7	0.9 to 1.1
ERJ6LW		0.6 to 0.8	3.2 to 3.8	1.1 to 1.4
ERJ6BW	2012 0805	0.9	3.2 to 3.8	1.1 to 1.4
ERJ6CW (10 to 13 mΩ)		0.7 to 0.9	3.2 to 3.8	1.1 to 1.4
ERJ6CW (15 to 30 mΩ)		0.9 to 1.1	3.2 to 3.8	1.1 to 1.4
ERJ8BW				
ERJ8CW (10 to 16 mΩ)	3216 1206	1.2	1.1 to 5.0	1.3 to 1.8
ERJ8CW (18 to 50 mΩ)		2.0 to 2.6	4.4 to 5.0	1.2 to 1.8

Size	Dimensions(mm)			
mm/inch	a	b	С	
0402/01005	0.15 to 0.20	0.5 to 0.7	0.20 to 0.25	
0603/0201	0.3 to 0.4	0.8 to 0.9	0.25 to 0.35	
1005/0402	0.5 to 0.6	1.4 to 1.6	0.4 to 0.6	
1608/0603	0.7 to 0.9	2.0 to 2.2	0.8 to 1.0	
2012/0805	1.0 to 1.4	3.2 to 3.8	0.9 to 1.4	
3216/1206	2.0 to 2.4	4.4 to 5.0	1.2 to 1.8	
3225/1210	2.0 to 2.4	4.4 to 5.0	1.8 to 2.8	
4532/1812	3.3 to 3.7	5.7 to 6.5	2.3 to 3.5	
5025/2010	3.6 to 4.0	6.2 to 7.0	1.8 to 2.8	
6432/2512	5.0 to 5.4	7.6 to 8.6	2.3 to 3.5	
6432/2512*	3.6 to 4.0	7.6 to 8.6	2.3 to 3.5	

^{*} ERJL1W

An example of a land pattern for High Power Chip Resistors / Wide Terminal Type is shown below.

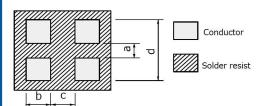


Part No.	Dimensions(mm)			
rait No.	a	b	С	
ERJA1	6.4	1.70	0.60	
ERJB1				
ERJC1 ⁽¹⁾	5.0	1.30	0.75	
ERJD1 ⁽²⁾				
ERJB2	3.2	0.95	0.70	
ERJD2 ⁽²⁾	3.2	0.93	0.70	
ERJB3	2.0	0.80	0.60	

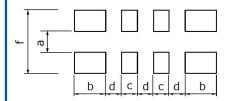
- (1) Anti-Sulfurated High Power Chip Resistors/Wide Terminal Type
- (2) Low TCR High Power Chip Resistors/Wide Terminal Type

Recommended Land Pattern

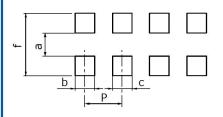
• An example of a land pattern for Chip Resistor Array, Anti-Sulfurated Chip Resistor Array and Chip Attenuator is shown below.



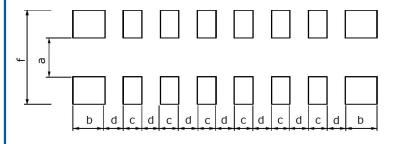
Part No.	Dimensions(mm)			
Part No.	a	b	С	d
EXB14V	0.30	0.30	0.30	0.80 to 0.90
EXB14A	0.30	0.30	0.30	0.80 to 0.90
EXB24V				
EXBU24	0.5	0.35 to 0.40	0.30	1.4 to 1.5
EXB24A				



Part No.		Dimensions(mm)			
rait No.	a	b	С	d	f
EXB28V EXBU28	0.40	0.525	0.25	0.25	1.40
EXBN8V	0.45 to 0.50	0.35 to 0.38	0.25	0.25	1.40 to 2.00



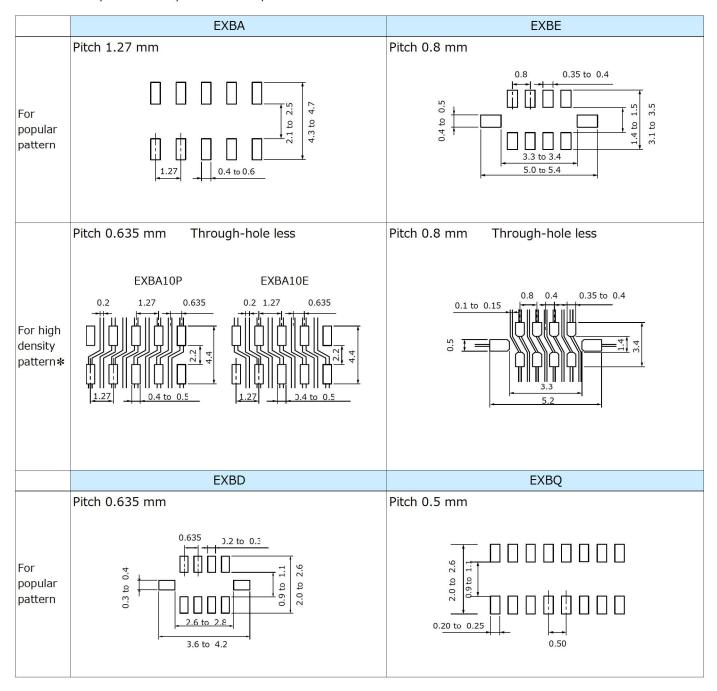
Part No.	Dimensions(mm)				
Part No.	a	b	С	f	Р
EXB18V	0.20 to 0.30	0.15 to 0.20	0.15 to 0.20	0.80 to 0.90	0.40
EXBV4V EXBV8V	0.7 to 0.9	0.4 to 0.45	0.4 to 0.45	2 to 2.4	0.80
EXB34V EXB38V EXBU34 EXBU38	0.7 to 0.9	0.4 to 0.5	0.4 to 0.5	2.2 to 2.6	0.80
EXBS8V	1 to 1.2	0.5 to 0.75	0.5 to 0.75	3.2 to 3.8	1.27



Part No.	Dimensions(mm)				
rait No.	a	b	С	d	f
EXB2HV	1.00	0.425	0.25	0.25	2.00
EXBU2H	1.00	0.425	0.25	0.23	2.00

Recommended Land Pattern

• An example of a land pattern for Chip Resistor Networks is shown below.



* When designing high density land patterns, examine the reliability of isolation among the lines and adopt the chip resistor networks.



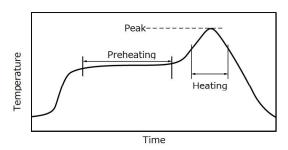
Recommended Soldering Conditions

Recommendations and precautions are described below.

Rectagular Type

Recommended soldering conditions for reflow

- Reflow soldering shall be performed a maximum of two times
- •Please contact us for additional information when used in conditions other than those specified.
- •Please measure the temperature of the terminals and study every kind of solder and printed circuit board for solderability be fore actual use.



For soldering (Example: Sn/Pb)

	Temperature	Time
Preheating	140 ℃ to 160 ℃	60 s to 120 s
Main heating	Above 200 ℃	30 s to 40 s
Peak	235 ± 5 ℃	max. 10 s

For lead-free soldering (Example: Sn/Ag/Cu)

	(=:::::::::::::::::::::::::::::::::::::				
	Temperature	Time			
Preheating	150 ℃ to180 ℃	60 s to 120 s			
Main heating	Above 230 ℃	30 s to 40 s			
Peak	max. 260 ℃	max. 10 s			

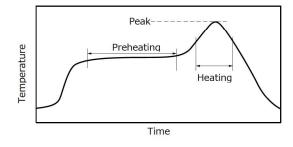
Recommended soldering conditions for flow

	For soldering		For lead-free soldering	
	Temperature Time		Temperature	Time
Preheating	140 ℃ to 160 ℃	60 s to 120 s	150 ℃ to 180 ℃	60 s to 120 s
Soldering	245 ± 5 ℃	20 s to 30 s	max. 260 ℃	max. 10 s

Chip Resistor Array, Chip Resistor Networks and Chip Attenuator

Recommended soldering conditions for reflow

- Reflow soldering shall be performed a maximum of two times.
- •Please contact us for additional information when used in conditions other than those specified.
- •Please measure the temperature of the terminals and study every kind of solder and printed circuit board for solderability be fore actual use.



For soldering (Example: Sn/Pb)

	Temperature	Time
Preheating	140 ℃ to 160 ℃	60 s to 120 s
Main heating	Above 200 ℃	30 s to 40 s
Peak	235 ± 5 ℃	max. 10 s

For lead-free soldering (Example: Sn/Ag/Cu)

3 (1 , 3, ,								
	Temperature	Time						
Preheating	150 ℃ to180 ℃	60 s to 120 s						
Main heating	Above 230 ℃	30 s to 40 s						
Peak	max. 260 ℃	max. 10 s						

Flow soldering

We do not recommend flow soldering, because a solder bridge may form. Please contact us regarding flow sol der ing of EXBA series.



Standard for Resistance Value and Resistance Tolerance

Basis Standard

IEC Publication 60062: Marking codes for resistors and capacitors.

IEC Publication 60063: Preferred number series for resistors and capacitors.

JIS C 5062: Marking codes for resistors and capacitors.

JIS C 5063: Preferred number series for resistors and capacitors.

Resistance Values

The resistance values are notched by "Ratio" below in each series.

Series	Resistance Tolerance (Standard)	Ratio	Remarks
E6	±20 %	⁶ √10=1.46	
E12	±10 %	¹²√10=1.21	
E24	± 5 %	24√10=1.10	Please refer to standard resistance values shown on this catalog.
E48	± 2 %	⁴⁸ √10=1.05	
E96	± 1 %	⁹⁶ √10=1.02	

How to express the resistance value with a Panasonic part number

The resistance value expressed in ohms is iden tified by a three digit number or a four digit number.

The last digit specifies the number of zeroes to follow.

The letter "R" shall be used as the decimal point for less than 10 Ω .

The examples of a three digit number

The examples of a times digit number								
Resistance Code	Value in ohms (Ω)							
R56	0.56							
5R6	5.6							
100	10							
271	270							
102	1 k							
273	27 k							
104	100 k							
275	2.7 M							
106	10 M							
107	100 M							

	1	-		•	1	Company of the same of the sam
The examp	OC.	\cap t	2	tour	digit	numhar
THE Examp	103	OI.	а	loui	ululu	Hullibel

Resistance Code	Value in ohms (Ω)
R562	0.562
5R62	5.62
56R2	56.2
1000	100
2711	2.71 k
1002	10 k
2713	271 k
1004	1 M
2751	2.71 M
1006	100 M

How to express the resistance tolerance with a Panasonic part number

The resistance tolerance is identified by a single letter in accordance with the following table and the code is placed just before the resistance code in the following examples.

Tolerance Code	Tolerance (%)	Examples
W	±0.05	W1001: 1000 Ω±0.05 %
В	±0.1	B1001 : 1000 Ω±0.1 %
С	±0.25	C1001 : 1000 Ω±0.25 %
D	±0.5	D1001 : 1000 Ω±0.5 %
F	±1	F1001 : 1000 Ω±1 %
G	±2	G1001 : 1000 Ω±2 %
J	±5	J101 : 100 Ω±5 %
K	±10	K101 : 100 Ω±10 %
М	±20	M101 : 100 Ω±20 %



Standard Resistance Values

E6	E12	E24	E48	E96	E6	E12	E24	E48	E96	E6	E12	E24	E48	E96
10	10	10	100	100				215	215				464	464
				102	22	22	22		221	47	47	47	,	475
			105	105				226	226				487	487
				107					232				3	499
	5	11	110	110			24	237	237			51	511	511
				113					243				3	523
			115	115				249	249				536	536
•	12	12		118					255				,	549
	12	12	121	121				261	261		56	56	562	562
				124		27	27		267				1	576
			127	127		27	27	274	274				590	590
		13		130					280				8	604
			133	133				287	287			62	619	619
				137					294				9	634
			140	140			30	301	301				649	649
				143					309					665
			147	147				316	316	68	68	68	681	681
15	15	15		150	33	33	33		324					698
			154	154				332	332				715	715
		16		158					340					732
			162	162				348	348			75	750	750
				165			36		357					768
			169	169				365	365				787	787
				174					374		82	82	,	806
	18	18	178	178		39	39	383	383		52	52	825	825
	10	10		182		33	3.5		392					845
			187	187				402	402				866	866
				191					412					887
			196	196			43	422	422			91	909	909
		20		200			- 15		432					931
			205	205				442	442				953	953
				210					453					976

CAUTION AND WARNING

- 1. The electronic components contained in this catalog are designed and produced for use in home electric appliances, office equipment, information equipment, communications equipment, and other general purpose electronic devices. Before use of any of these components for equipment that requires a high degree of safety, such as medical instruments, aerospace equipment, disaster-prevention equipment, security equipment, vehicles (automobile, train, vessel), please be sure to contact our sales representative corporation.
- 2. When applying one of these components for equipment requiring a high degree of safety, no matter what sort of application it might be, be sure to install a protective circuit or redundancy arrangement to enhance the safety of your equipment. In addition, please carry out the safety test on your own responsibility.
- 3. When using our products, no matter what sort of equipment they might be used for, be sure to make a written agreement on the specifications with us in advance.
- 4. Technical information contained in this catalog is intended to convey examples of typical performances and or applications and is not intended to make any warranty with respect to the intellectual property rights or any other related rights of our company or any third parties nor grant any license under such rights.
- 5. In order to export products in this catalog, the exporter may be subject to the export license requirement under the Foreign Exchange and Foreign Trade Law of Japan.
- 6. No ozone-depleting substances (ODSs) under the Montreal Protocol are used in the manufacturing processes of Automotive & Industrial Systems Company, Panasonic Corporation.

 Please contact ——— 			

Factory

Device Solutions Business Division Industrial Solutions Company

Panasonic

1006 Kadoma, Kadoma City, Osaka 571-8506, JAPAN